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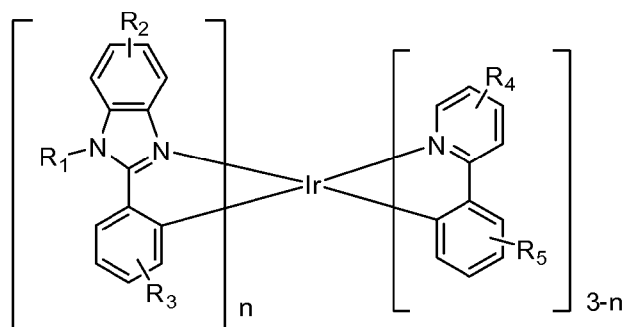
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(54) Title: PHOSPHORESCENT EMITTERS

**FIGURE 6**

(57) Abstract: Heteroleptic compounds containing phenylpyridine and phenylbenzimidazole are provided. The compounds may be used in organic light emitting devices, particularly as emissive dopants in the emissive layer of such devices.

PHOSPHORESCENT EMITTERS

[0001] This application claims priority to U.S. Provisional Application No. 61/113,257, filed November 11, 2008, the disclosure of which is herein expressly incorporated by reference in its entirety.

[0002] The claimed invention was made by, on behalf of, and/or in connection with one or more of the following parties to a joint university corporation research agreement: Regents of the University of Michigan, Princeton University, The University of Southern California, and the Universal Display Corporation. The agreement was in effect on and before the date the claimed invention was made, and the claimed invention was made as a result of activities undertaken within the scope of the agreement.

FIELD OF THE INVENTION

[0003] The present invention relates to novel heteroleptic complexes. In particular, the heteroleptic compounds contain phenylpyridine and phenylbenzimidazole. The compounds may be useful in organic light emitting devices (OLEDs).

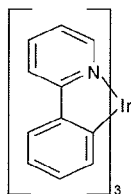
BACKGROUND

[0004] Opto-electronic devices that make use of organic materials are becoming increasingly desirable for a number of reasons. Many of the materials used to make such devices are relatively inexpensive, so organic opto-electronic devices have the potential for cost advantages over inorganic devices. In addition, the inherent properties of organic materials, such as their flexibility, may make them well suited for particular applications such as fabrication on a flexible substrate. Examples of organic opto-electronic devices include organic light emitting devices (OLEDs), organic phototransistors, organic photovoltaic cells, and organic photodetectors. For OLEDs, the organic materials may have performance advantages over conventional materials. For example, the wavelength at which an organic emissive layer emits light may generally be readily tuned with appropriate dopants.

[0005] OLEDs make use of thin organic films that emit light when voltage is applied across the device. OLEDs are becoming an increasingly interesting technology for use in applications such as flat panel displays, illumination, and backlighting. Several OLED materials and configurations are described in U.S. Pat. Nos. 5,844,363, 6,303,238, and 5,707,745, which are incorporated herein by reference in their entirety.

[0006] One application for phosphorescent emissive molecules is a full color display. Industry standards for such a display call for pixels adapted to emit particular colors, referred to as "saturated" colors. In particular, these standards call for saturated red, green, and blue pixels. Color may be measured using CIE coordinates, which are well known to the art.

[0007] One example of a green emissive molecule is tris(2-phenylpyridine) iridium, denoted Ir(ppy)₃, which has the structure of Formula I:



[0008] In this, and later figures herein, we depict the dative bond from nitrogen to metal (here, Ir) as a straight line.

[0009] As used herein, the term "organic" includes polymeric materials as well as small molecule organic materials that may be used to fabricate organic opto-electronic devices. "Small molecule" refers to any organic material that is not a polymer, and "small molecules" may actually be quite large. Small molecules may include repeat units in some circumstances. For example, using a long chain alkyl group as a substituent does not remove a molecule from the "small molecule" class. Small molecules may also be incorporated into polymers, for example as a pendent group on a polymer backbone or as a part of the backbone. Small molecules may also serve as the core moiety of a dendrimer, which consists of a series of chemical shells built on the core moiety. The core moiety of a dendrimer may be a fluorescent or phosphorescent small molecule emitter. A dendrimer may be a "small molecule," and it is believed that all dendrimers currently used in the field of OLEDs are small molecules.

[0010] As used herein, "top" means furthest away from the substrate, while "bottom" means closest to the substrate. Where a first layer is described as "disposed over" a second layer, the first layer is disposed further away from substrate. There may be other layers between the first and second layer, unless it is specified that the first layer is "in contact with" the second layer. For example, a cathode may be described as "disposed over" an anode, even though there are various organic layers in between.

[0011] As used herein, "solution processible" means capable of being dissolved, dispersed, or transported in and/or deposited from a liquid medium, either in solution or suspension form.

[0012] A ligand may be referred to as "photoactive" when it is believed that the ligand directly contributes to the photoactive properties of an emissive material. A ligand may be referred to as "ancillary" when it is believed that the ligand does not contribute to the photoactive properties of an emissive material, although an ancillary ligand may alter the properties of a photoactive ligand. More than one type of "photoactive" ligand may be present in a complex. The different photoactive ligands may each contribute to the properties of the emissive material.

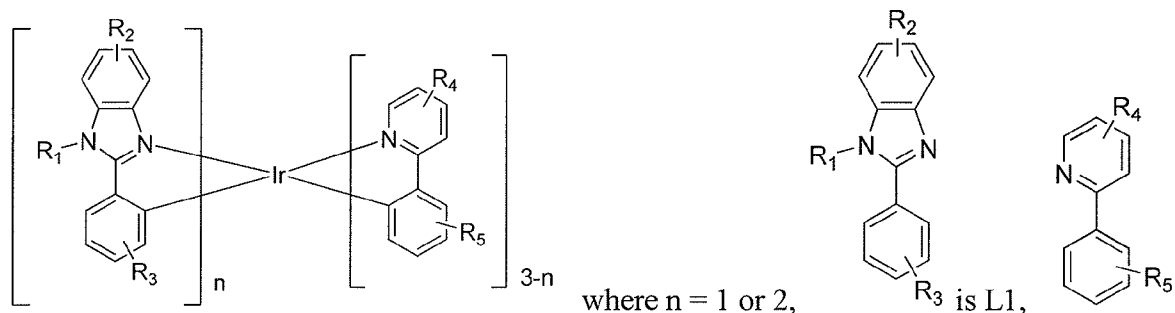
[0013] As used herein, and as would be generally understood by one skilled in the art, a first "Highest Occupied Molecular Orbital" (HOMO) or "Lowest Unoccupied Molecular Orbital" (LUMO) energy level is "greater than" or "higher than" a second HOMO or LUMO energy level if the first energy level is closer to the vacuum energy level. Since ionization potentials (IP) are measured as a negative energy relative to a vacuum level, a higher HOMO energy level corresponds to an IP having a smaller absolute value (an IP that is less negative). Similarly, a higher LUMO energy level corresponds to an electron affinity (EA) having a smaller absolute value (an EA that is less negative). On a conventional energy level diagram, with the vacuum level at the top, the LUMO energy level of a material is higher than the HOMO energy level of the same material. A "higher" HOMO or LUMO energy level appears closer to the top of such a diagram than a "lower" HOMO or LUMO energy level.

[0014] As used herein, and as would be generally understood by one skilled in the art, a first work function is "greater than" or "higher than" a second work function if the first work function has a higher absolute value. Because work functions are generally measured as negative numbers relative to vacuum level, this means that a "higher" work function is more negative. On a conventional energy level diagram, with the vacuum level at the top, a "higher" work function is illustrated as further away from the vacuum level in the downward direction. Thus, the definitions of HOMO and LUMO energy levels follow a different convention than work functions.

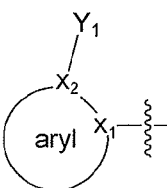
[0015] More details on OLEDs, and the definitions described above, can be found in US Pat. No. 7,279,704, which is incorporated herein by reference in its entirety.

SUMMARY OF THE INVENTION

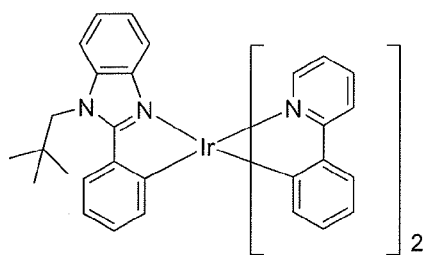
[0016] Heteroleptic compounds $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$ are provided. The heteroleptic compounds have the formula:



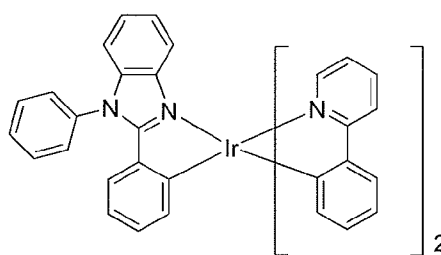
$\text{R}_1, \text{R}_2, \text{R}_3, \text{R}_4$, and R_5 may represent mono, di, tri, or tetra substitutions, and $\text{R}_1, \text{R}_2, \text{R}_3, \text{R}_4$, and R_5 are each independently selected from the group consisting of hydrogen, alkyl, heteroalkyl, aryl, substituted aryl, heteroaryl, and substituted heteroaryl. Preferably, n is 1. In one aspect, R_1 is selected from the group consisting of alkyl, heteroalkyl, substituted aryl, and substituted heteroaryl, where R_1 does not form a conjugated system with L1 . Preferably,

R_1 is  where X_1 and X_2 are independently selected from C and N. Y_1 is not hydrogen. Y_1 may be joined to other substituents on the aryl ring. The heteroleptic compound may have a narrower full width at half maximum (FWHM) of emission and/or a lower sublimation temperature than the corresponding homoleptic compounds.

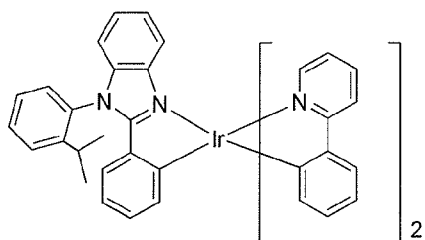
[0017] Specific examples of heteroleptic compounds having particular L1 and L2 ligands are provided. Preferably, the heteroleptic compounds are selected from the group consisting of:



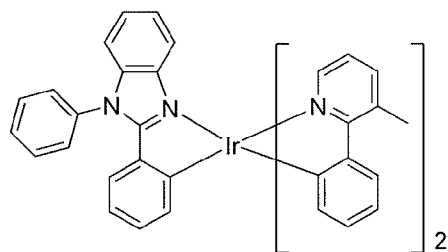
Compound 1



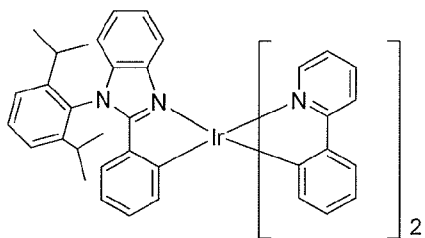
Compound 2



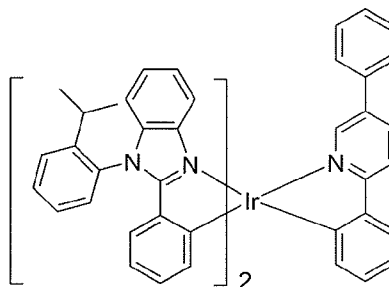
Compound 3



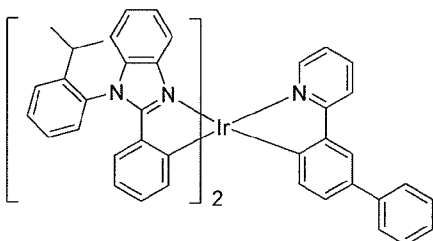
Compound 4



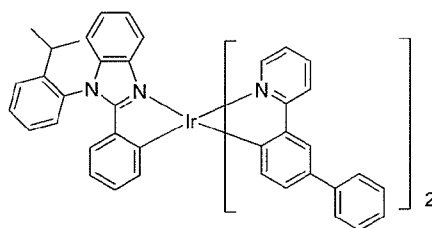
Compound 5



Compound 6

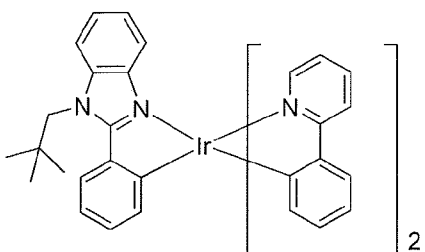


Compound 7

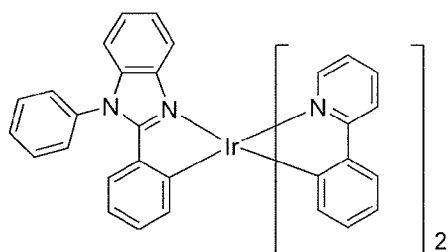


Compound 8

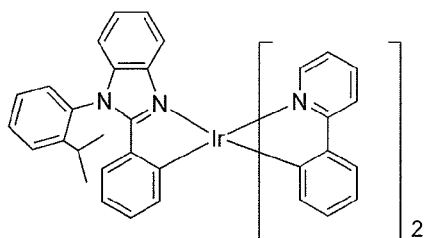
[0018] In another aspect, preferably the heteroleptic compound is selected from the group consisting of:



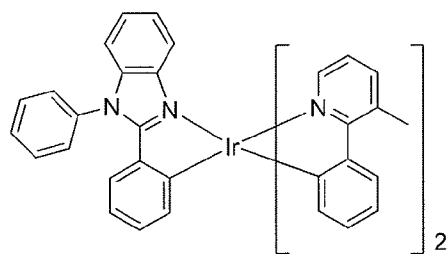
Compound 1



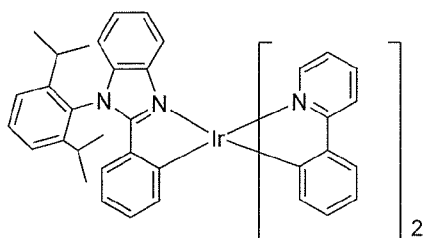
Compound 2



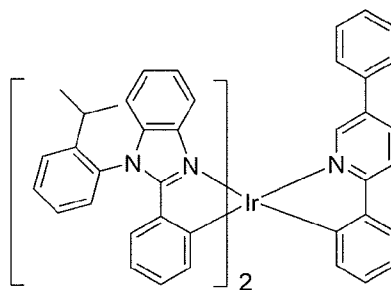
Compound 3



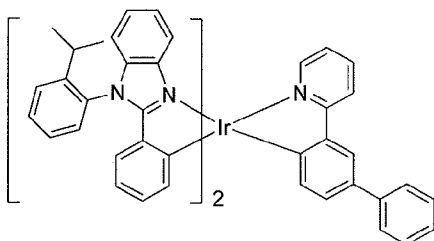
Compound 4



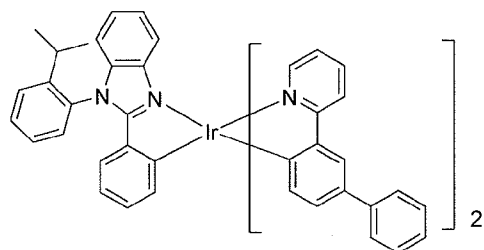
Compound 5



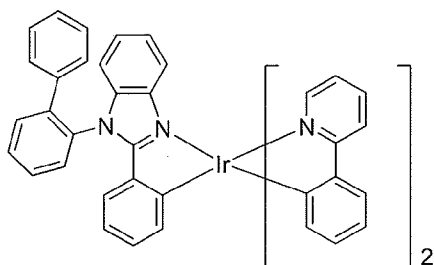
Compound 6



Compound 7



Compound 8



Compound 9

[0019] An organic light emitting device is also provided. The device has an anode, a cathode, an and an organic layer disposed between the anode and the cathode. The organic layer further comprises a heteroleptic compound $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$, as described above.

Preferably the organic layer is an emissive layer having a host and an emissive dopant, and the heteroleptic compound is the emissive dopant.

[0020] A consumer product is also provided. The product contains a device that has an anode, a cathode, and an emissive layer disposed between the anode and the cathode, where the organic layer further comprises a heteroleptic compound $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$, as described above.

BRIEF DESCRIPTION OF THE DRAWINGS

[0021] FIG. 1 shows an organic light emitting device.

[0022] FIG. 2 shows an inverted organic light emitting device that does not have a separate electron transport layer.

[0023] FIG. 3 shows solution photoluminescence spectra of homoleptic and heteroleptic compounds.

[0024] FIG. 4 shows a phosphorescent organic light emitting device structure.

[0025] FIG. 5 shows a phosphorescent organic light emitting device containing the inventive compounds.

[0026] FIG. 6 shows a heteroleptic compound.

DETAILED DESCRIPTION

[0027] Generally, an OLED comprises at least one organic layer disposed between and electrically connected to an anode and a cathode. When a current is applied, the anode injects holes and the cathode injects electrons into the organic layer(s). The injected holes and electrons each migrate toward the oppositely charged electrode. When an electron and hole localize on the same molecule, an "exciton," which is a localized electron-hole pair having an excited energy state, is formed. Light is emitted when the exciton relaxes via a photoemissive mechanism. In some cases, the exciton may be localized on an excimer or an exciplex. Non-radiative mechanisms, such as thermal relaxation, may also occur, but are generally considered undesirable.

[0028] The initial OLEDs used emissive molecules that emitted light from their singlet states ("fluorescence") as disclosed, for example, in U.S. Pat. No. 4,769,292, which is incorporated by reference in its entirety. Fluorescent emission generally occurs in a time frame of less than 10 nanoseconds.

[0029] More recently, OLEDs having emissive materials that emit light from triplet states ("phosphorescence") have been demonstrated. Baldo et al., "Highly Efficient Phosphorescent

Emission from Organic Electroluminescent Devices," *Nature*, vol. 395, 151-154, 1998; ("Baldo-I") and Baldo et al., "Very high-efficiency green organic light-emitting devices based on electrophosphorescence," *Appl. Phys. Lett.*, vol. 75, No. 3, 4-6 (1999) ("Baldo-II"), which are incorporated by reference in their entireties. Phosphorescence is described in more detail in US Pat. No. 7,279,704 at cols. 5-6, which are incorporated by reference.

[0030] FIG. 1 shows an organic light emitting device 100. The figures are not necessarily drawn to scale. Device 100 may include a substrate 110, an anode 115, a hole injection layer 120, a hole transport layer 125, an electron blocking layer 130, an emissive layer 135, a hole blocking layer 140, an electron transport layer 145, an electron injection layer 150, a protective layer 155, and a cathode 160. Cathode 160 is a compound cathode having a first conductive layer 162 and a second conductive layer 164. Device 100 may be fabricated by depositing the layers described, in order. The properties and functions of these various layers, as well as example materials, are described in more detail in US 7,279,704 at cols. 6-10, which are incorporated by reference.

[0031] More examples for each of these layers are available. For example, a flexible and transparent substrate-anode combination is disclosed in U.S. Pat. No. 5,844,363, which is incorporated by reference in its entirety. An example of a p-doped hole transport layer is m-MTDATA doped with F.sub.4-TCNQ at a molar ratio of 50:1, as disclosed in U.S. Patent Application Publication No. 2003/0230980, which is incorporated by reference in its entirety. Examples of emissive and host materials are disclosed in U.S. Pat. No. 6,303,238 to Thompson et al., which is incorporated by reference in its entirety. An example of an n-doped electron transport layer is BPhen doped with Li at a molar ratio of 1:1, as disclosed in U.S. Patent Application Publication No. 2003/0230980, which is incorporated by reference in its entirety. U.S. Pat. Nos. 5,703,436 and 5,707,745, which are incorporated by reference in their entireties, disclose examples of cathodes including compound cathodes having a thin layer of metal such as Mg:Ag with an overlying transparent, electrically-conductive, sputter-deposited ITO layer. The theory and use of blocking layers is described in more detail in U.S. Pat. No. 6,097,147 and U.S. Patent Application Publication No. 2003/0230980, which are incorporated by reference in their entireties. Examples of injection layers are provided in U.S. Patent Application Publication No. 2004/0174116, which is incorporated by reference in its entirety. A description of protective layers may be found in U.S. Patent Application Publication No. 2004/0174116, which is incorporated by reference in its entirety.

[0032] FIG. 2 shows an inverted OLED 200. The device includes a substrate 210, a cathode 215, an emissive layer 220, a hole transport layer 225, and an anode 230. Device 200 may be fabricated by depositing the layers described, in order. Because the most common OLED configuration has a cathode disposed over the anode, and device 200 has cathode 215 disposed under anode 230, device 200 may be referred to as an "inverted" OLED. Materials similar to those described with respect to device 100 may be used in the corresponding layers of device 200. FIG. 2 provides one example of how some layers may be omitted from the structure of device 100.

[0033] The simple layered structure illustrated in FIGS. 1 and 2 is provided by way of non-limiting example, and it is understood that embodiments of the invention may be used in connection with a wide variety of other structures. The specific materials and structures described are exemplary in nature, and other materials and structures may be used. Functional OLEDs may be achieved by combining the various layers described in different ways, or layers may be omitted entirely, based on design, performance, and cost factors. Other layers not specifically described may also be included. Materials other than those specifically described may be used. Although many of the examples provided herein describe various layers as comprising a single material, it is understood that combinations of materials, such as a mixture of host and dopant, or more generally a mixture, may be used. Also, the layers may have various sublayers. The names given to the various layers herein are not intended to be strictly limiting. For example, in device 200, hole transport layer 225 transports holes and injects holes into emissive layer 220, and may be described as a hole transport layer or a hole injection layer. In one embodiment, an OLED may be described as having an "organic layer" disposed between a cathode and an anode. This organic layer may comprise a single layer, or may further comprise multiple layers of different organic materials as described, for example, with respect to FIGS. 1 and 2.

[0034] Structures and materials not specifically described may also be used, such as OLEDs comprised of polymeric materials (PLEDs) such as disclosed in U.S. Pat. No. 5,247,190 to Friend et al., which is incorporated by reference in its entirety. By way of further example, OLEDs having a single organic layer may be used. OLEDs may be stacked, for example as described in U.S. Pat. No. 5,707,745 to Forrest et al, which is incorporated by reference in its entirety. The OLED structure may deviate from the simple layered structure illustrated in FIGS. 1 and 2. For example, the substrate may include an angled reflective surface to improve out-coupling, such as a mesa structure as described in U.S. Pat. No.

6,091,195 to Forrest et al., and/or a pit structure as described in U.S. Pat. No. 5,834,893 to Bulovic et al., which are incorporated by reference in their entireties.

[0035] Unless otherwise specified, any of the layers of the various embodiments may be deposited by any suitable method. For the organic layers, preferred methods include thermal evaporation, ink-jet, such as described in U.S. Pat. Nos. 6,013,982 and 6,087,196, which are incorporated by reference in their entireties, organic vapor phase deposition (OVPD), such as described in U.S. Pat. No. 6,337,102 to Forrest et al., which is incorporated by reference in its entirety, and deposition by organic vapor jet printing (OVJP), such as described in U.S. patent application Ser. No. 10/233,470, which is incorporated by reference in its entirety. Other suitable deposition methods include spin coating and other solution based processes. Solution based processes are preferably carried out in nitrogen or an inert atmosphere. For the other layers, preferred methods include thermal evaporation. Preferred patterning methods include deposition through a mask, cold welding such as described in U.S. Pat. Nos. 6,294,398 and 6,468,819, which are incorporated by reference in their entireties, and patterning associated with some of the deposition methods such as ink-jet and OVJD. Other methods may also be used. The materials to be deposited may be modified to make them compatible with a particular deposition method. For example, substituents such as alkyl and aryl groups, branched or unbranched, and preferably containing at least 3 carbons, may be used in small molecules to enhance their ability to undergo solution processing. Substituents having 20 carbons or more may be used, and 3-20 carbons is a preferred range. Materials with asymmetric structures may have better solution processibility than those having symmetric structures, because asymmetric materials may have a lower tendency to recrystallize. Dendrimer substituents may be used to enhance the ability of small molecules to undergo solution processing.

[0036] Devices fabricated in accordance with embodiments of the invention may be incorporated into a wide variety of consumer products, including flat panel displays, computer monitors, televisions, billboards, lights for interior or exterior illumination and/or signaling, heads up displays, fully transparent displays, flexible displays, laser printers, telephones, cell phones, personal digital assistants (PDAs), laptop computers, digital cameras, camcorders, viewfinders, micro-displays, vehicles, a large area wall, theater or stadium screen, or a sign. Various control mechanisms may be used to control devices fabricated in accordance with the present invention, including passive matrix and active matrix. Many of

the devices are intended for use in a temperature range comfortable to humans, such as 18 degrees C. to 30 degrees C., and more preferably at room temperature (20-25 degrees C.).

[0037] The materials and structures described herein may have applications in devices other than OLEDs. For example, other optoelectronic devices such as organic solar cells and organic photodetectors may employ the materials and structures. More generally, organic devices, such as organic transistors, may employ the materials and structures.

[0038] The terms halo, halogen, alkyl, cycloalkyl, alkenyl, alkynyl, arylkyl, heterocyclic group, aryl, aromatic group, and heteroaryl are known to the art, and are defined in US 7,279,704 at cols. 31-32, which are incorporated herein by reference.

[0039] 2-phenylbenzimidazole (herein called "phenylbenzimidazole") and phenylpyridine-containing materials are provided, which can be used in phosphorescent organic light emitting devices giving high efficiency, high stability, long operational lifetimes, and improved color. The materials may be used as phosphorescent emissive dopants in green devices.

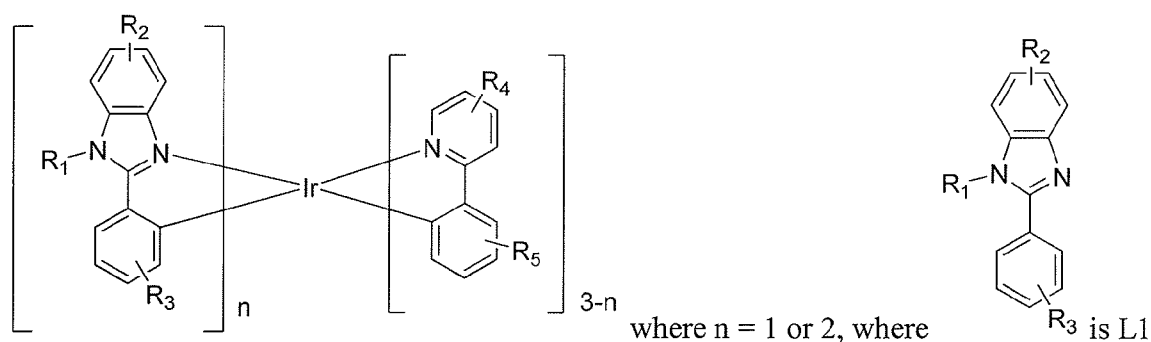
[0040] Phenylpyridine and phenylbenzimidazole-containing heteroleptic compounds are provided. Heteroleptic compounds provide highly tunable phosphorescent emitting materials and thus these compounds are desirable in order to achieve a broad range of colors and highly saturated colors. The emission of the metal complex can be tuned by carefully choosing different ligands, depending on the triplet energy and HOMO/LUMO levels of different ligands. While phenylbenzimidazoles provide devices with good lifetime performance, they generally have a higher sublimation temperature and may have a vibronic emission spectrum (see FIG.3). A heteroleptic complex containing both a phenylbenzimidazole ligand and phenylpyridine ligand may provide a lower sublimation temperature while maintaining the beneficial properties of the phenylbenzimidazole (i.e., long lifetime and high stability).

[0041] It is generally accepted that the sublimation temperature of a complex can be determined from the molecular structure of the complex. High molecular weight usually results in higher sublimation temperature. So then, a heteroleptic compound may be expected to have a sublimation temperature between that of the corresponding homoleptic compounds because the molecular weight of the heteroleptic compound is between the molecular weights of each of the corresponding homoleptic compounds. However, some of the heteroleptic compounds containing phenylpyridine and phenylbenzimidazole, as disclosed herein, have a sublimation temperature that is lower than both corresponding homoleptic compounds (i.e.,

phenylpyridine homoleptic compound and phenylbenzimidazole homoleptic compound). The reduction in the sublimation temperature of the heteroleptic complex may provide improved device manufacturing.

[0042] In addition, these heteroleptic compounds may also provide a more narrow emission spectrum. Without being bound by theory, it is noted that both ligands (i.e., phenylpyridine and phenylbenzimidazole) are green emitters that are close in energy level, thus both ligands could directly contribute to the emission of the compound. The observed emission spectra of the heteroleptic compounds disclosed herein are unexpectedly narrow (see FIG. 3). The emission spectrum of the compound is expected to be similar to phenylbenzimidazole emission because the electrochemical gap of benzimidazole is smaller than phenylpyridine (i.e., benzimidazole has a shallower HOMO and a deeper LUMO than phenylpyridine). However, the observed emission of the heteroleptic compound is closer to the emission profile of phenylpyridine than benzimidazole (e.g., no vibronic structure). It is believed that the observed emission spectra of the compounds may be a result of unexpected interactions between the phenylpyridine and phenylbenzimidazole ligands when both ligands are included in the same complex. Therefore, a complex containing phenylpyridine and phenylbenzimidazole ligands may be advantageously used as an emissive material for PHOLEDs having long lifetimes, high stability, and improved manufacturing as well as improved color.

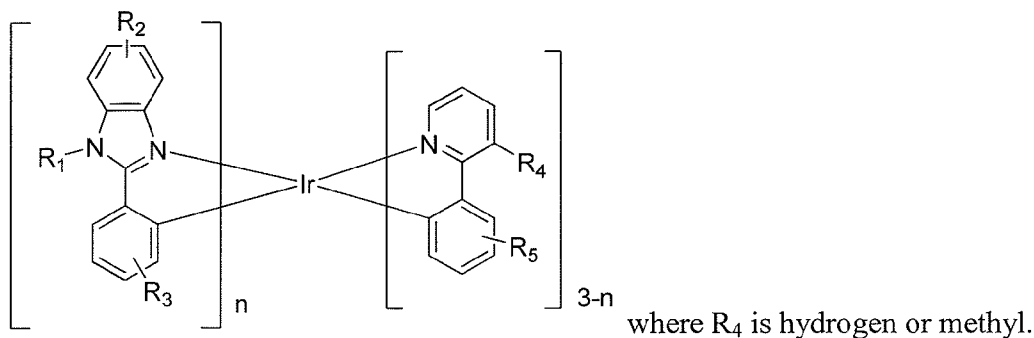
[0043] Heteroleptic compounds $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$ are provided, which may be advantageously used in OLEDs, having the formula:



and is L2. Each of R_1 , R_2 , R_3 , R_4 , and R_5 may represent mono, di, tri, or tetra

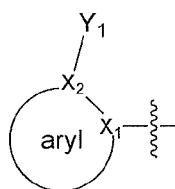
substitutions. Each of R_1 , R_2 , R_3 , R_4 , and R_5 are independently selected from the group consisting of hydrogen, alkyl, heteroalkyl, aryl, substituted aryl, heteroaryl, and substituted heteroaryl. Preferably, n is 1.

[0044] In one aspect, the compound has the formula:

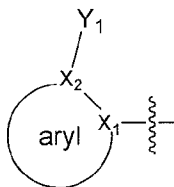


[0045] In another aspect, R_1 is selected from the group consisting of alkyl, heteroalkyl, aryl, heteroaryl, substituted aryl, and substituted heteroaryl, and where R_1 does not form a conjugated system with L1. The phenylbenzimidazole moiety is important in order to achieve the beneficial properties of these heteroleptic compounds. Therefore, in order to maintain the beneficial features, the R_1 substituent is a chemical group having minimal conjugation. Further, conjugation between the phenyl and the benzimidazole portions of L1 will likely result in a reduced LUMO level and a loss of the saturated green emission. Thus, the substituents (e.g., R_1 and R_2) are not fused as to form an extended conjugated system.

[0046] Preferably, the R_1 substituent is a branched alkyl or a twisted aryl (e.g., isopropyl and isobutyl). “Twisted aryl” as used herein refers to a structure having the formula



where X_1 and X_2 are independently selected from C and N, Y_1 is not hydrogen, and Y_1 may be joined to other substituents on the aryl ring. Branched alkyl and twisted aryl substituents may provide reduced solid state packing and a lower sublimation temperature.

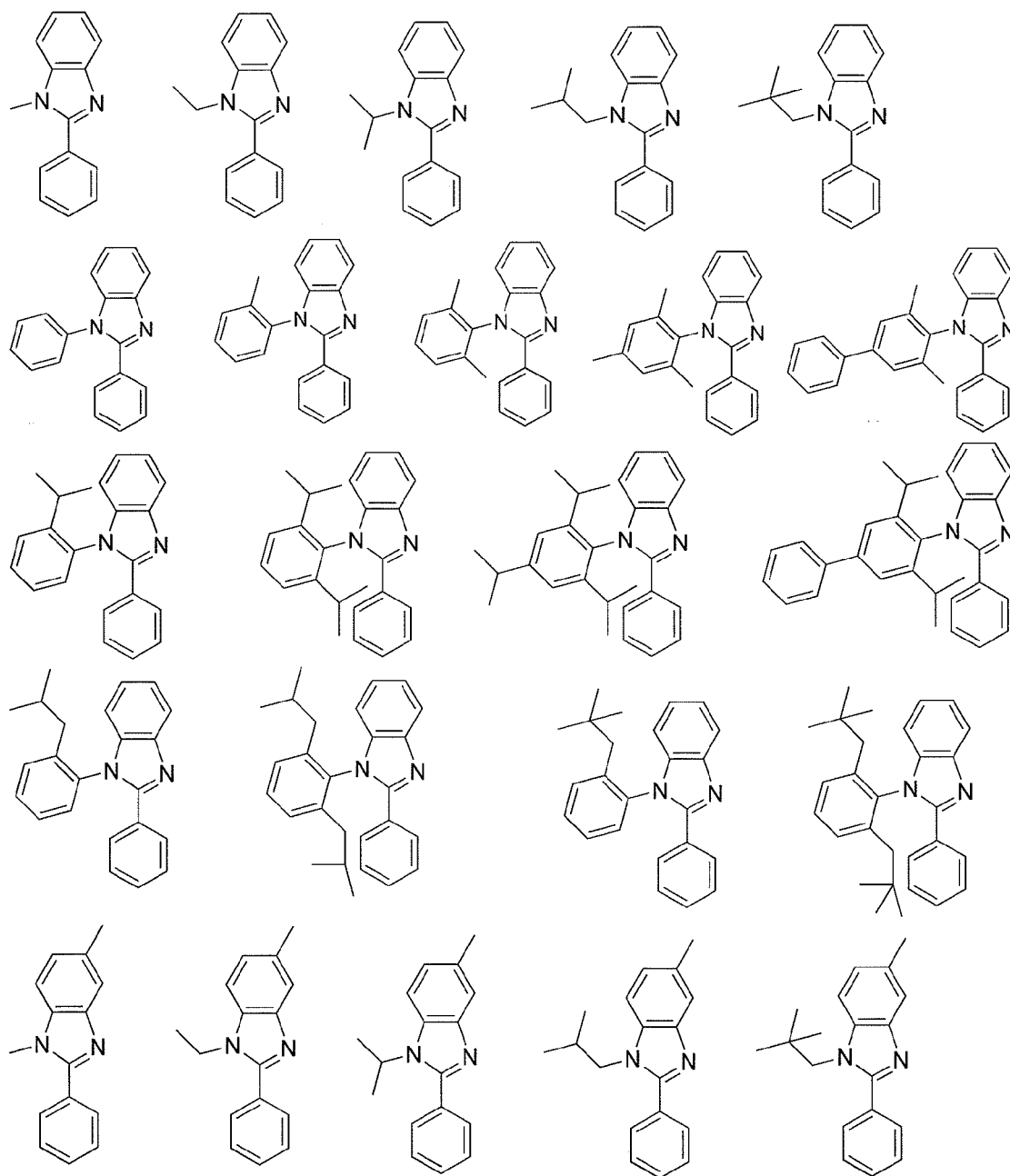


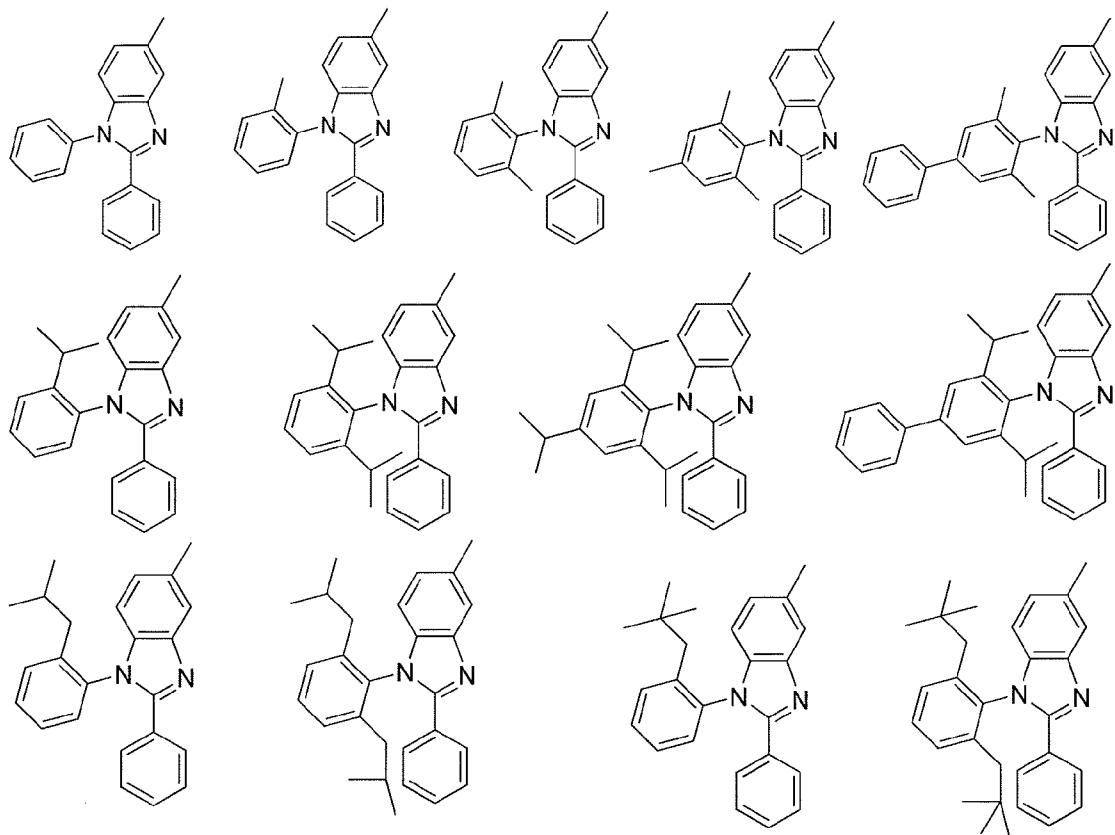
[0047] More preferably, R_1 is where X_1 and X_2 are independently selected from C and N. Y_1 is not hydrogen. Y_1 may be joined to other substituents on the aryl ring. It

is thought that a non-planar conformation contributes to the beneficial properties of the compound. For example, a heteroleptic compound having this R₁ substituent may have better color and a lower sublimation temperature. In addition, this R₁ substituent may be less likely to lower the triplet energy of the compound.

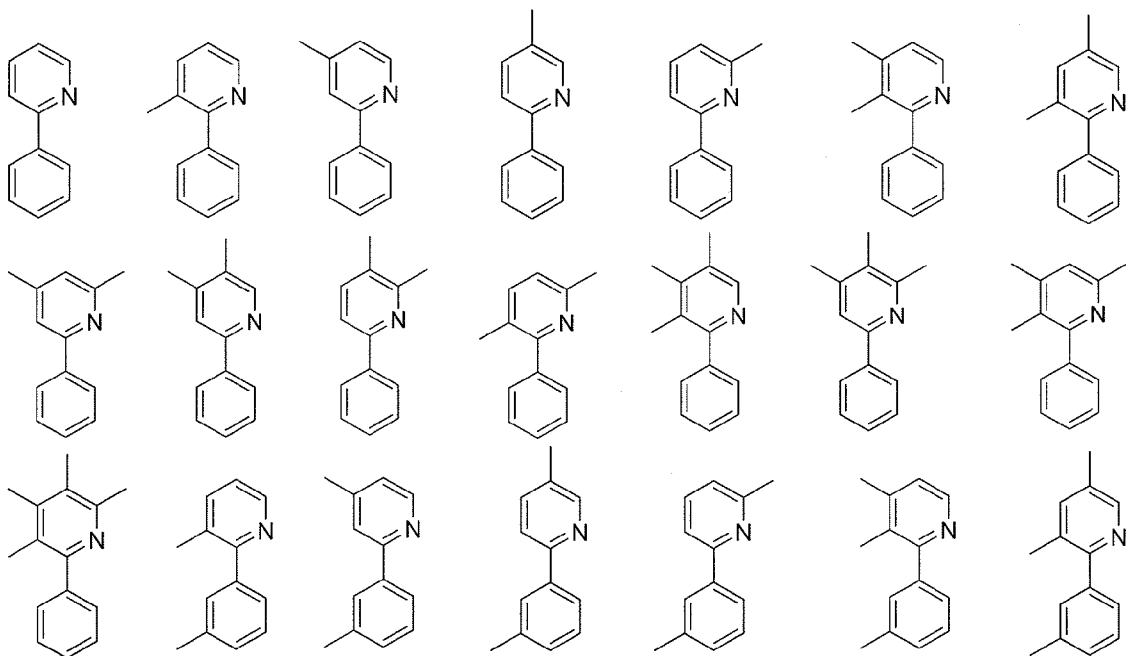
[0048] In another aspect, each of R₂, R₃, and R₅ are hydrogen.

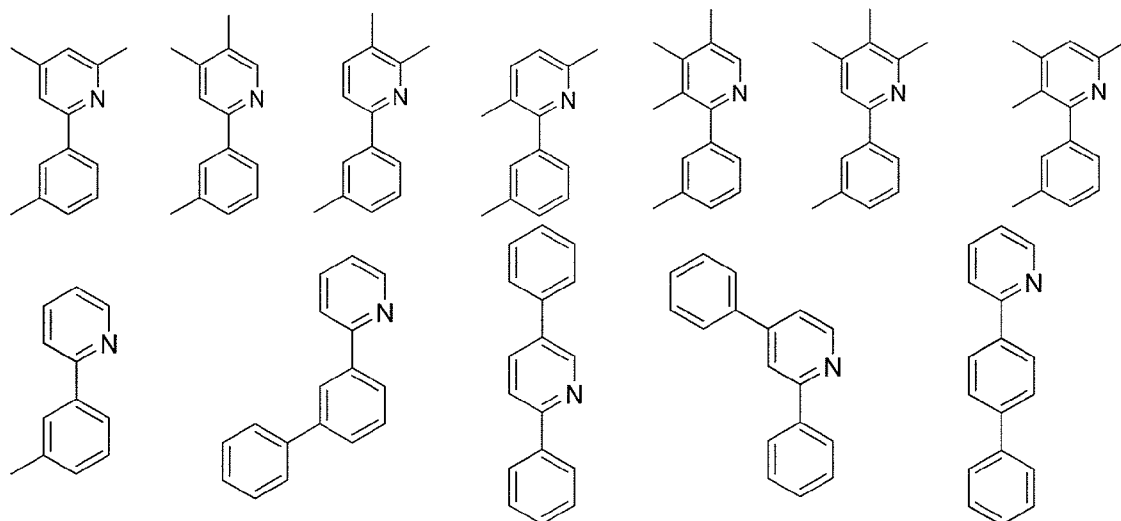
[0049] Specific examples of heteroleptic compounds include compounds containing L1 selected from the group consisting of:





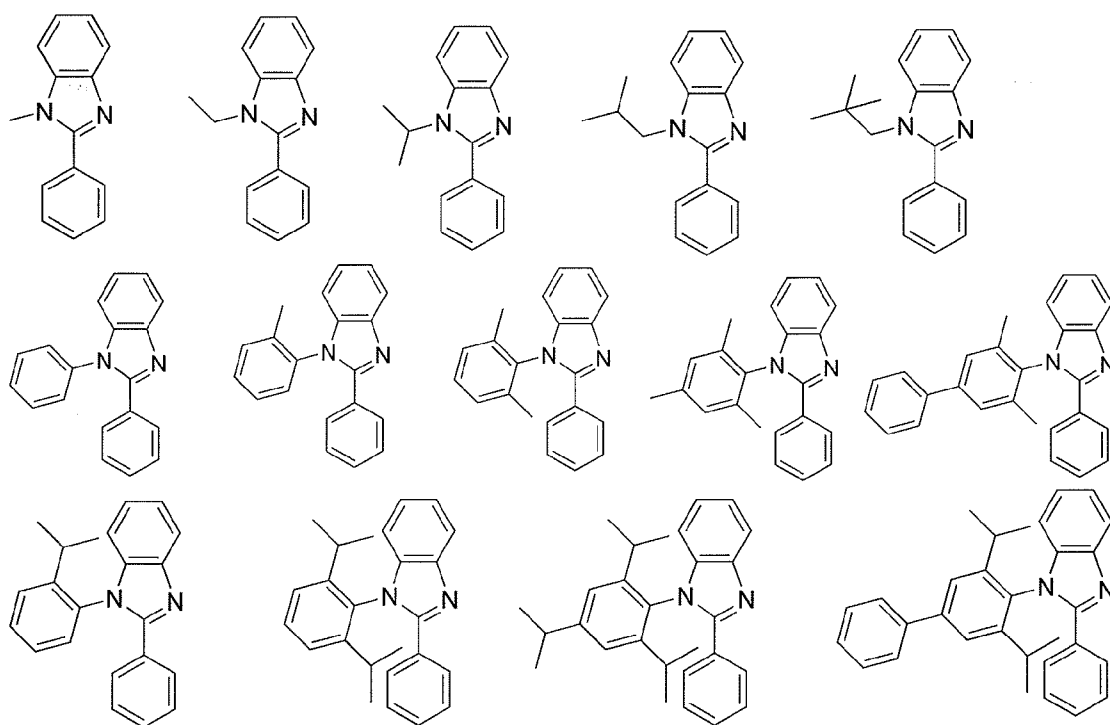
[0050] Further specific examples of heteroleptic compounds include compounds containing L2 selected from the group consisting of:

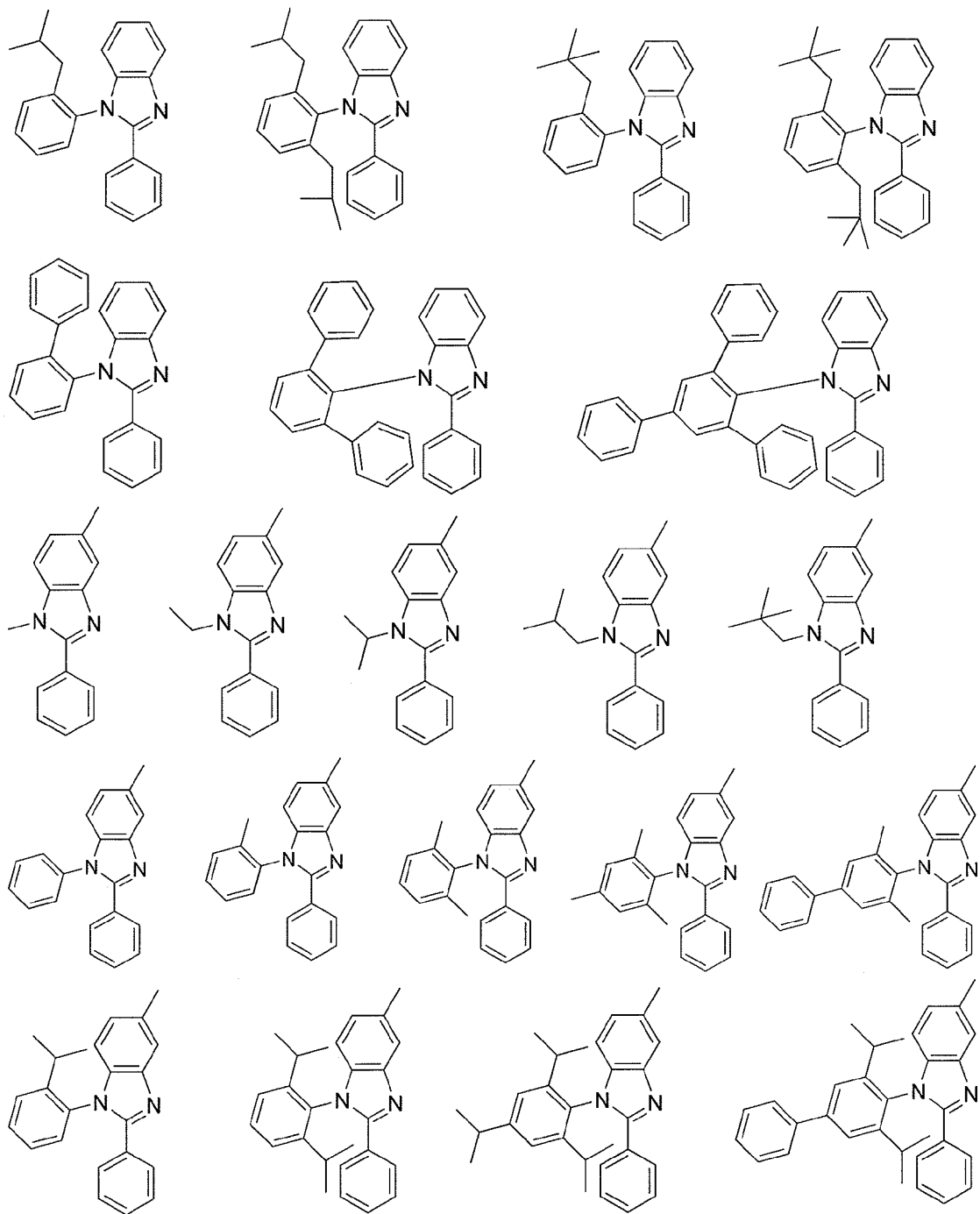


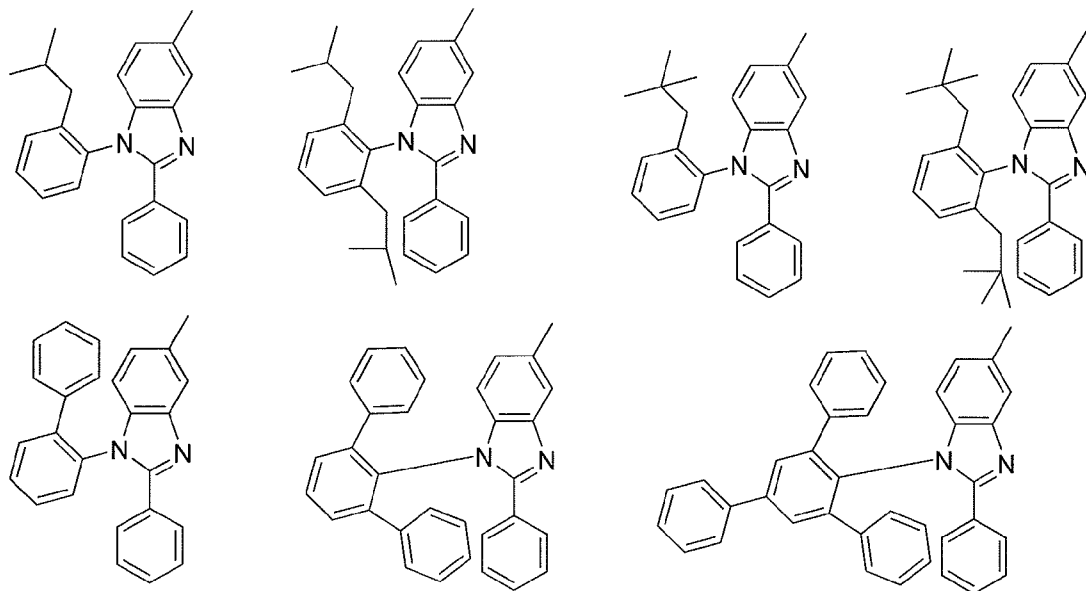


[0051] In one aspect, the heteroleptic compound includes both an L1 and an L2 selected from the groups provided above.

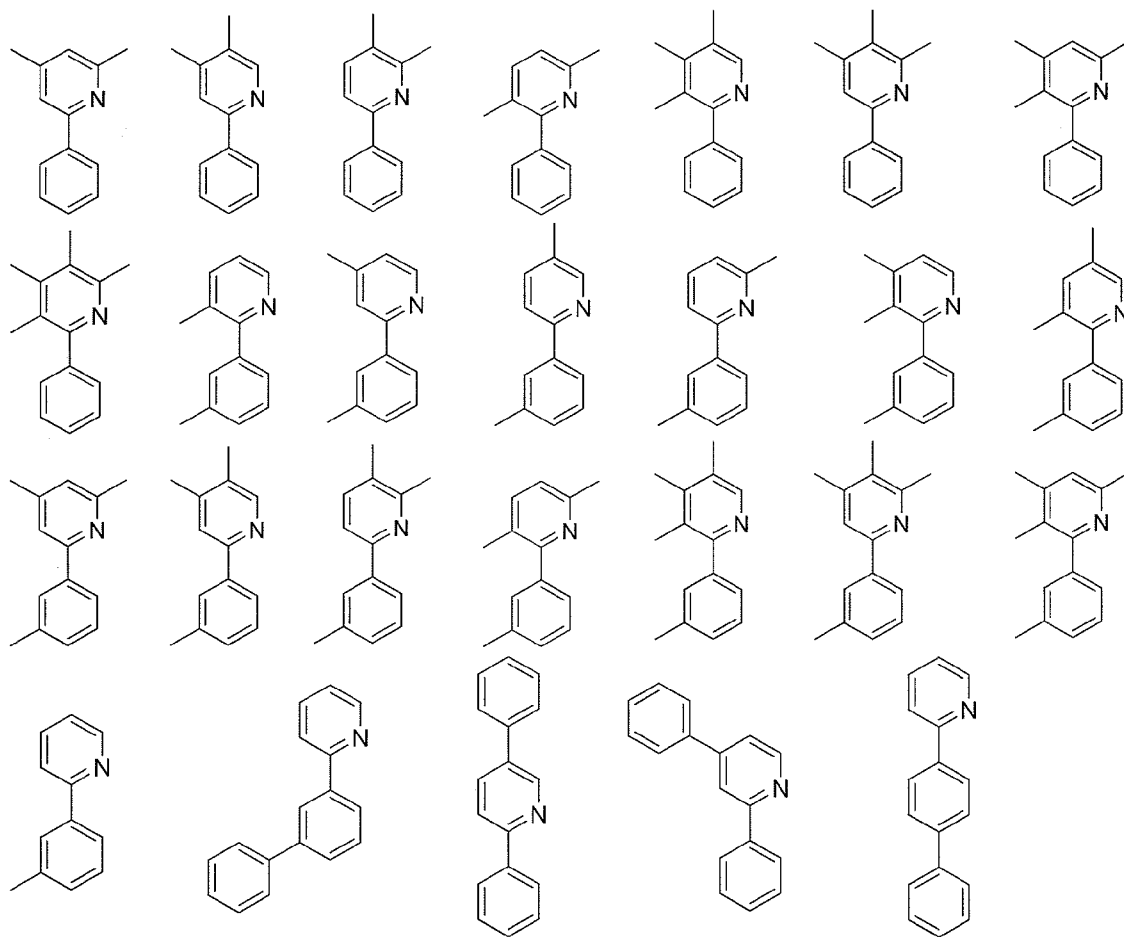
[0052] Further examples of specific heteroleptic compounds include compounds containing L1 selected from the group consisting of:

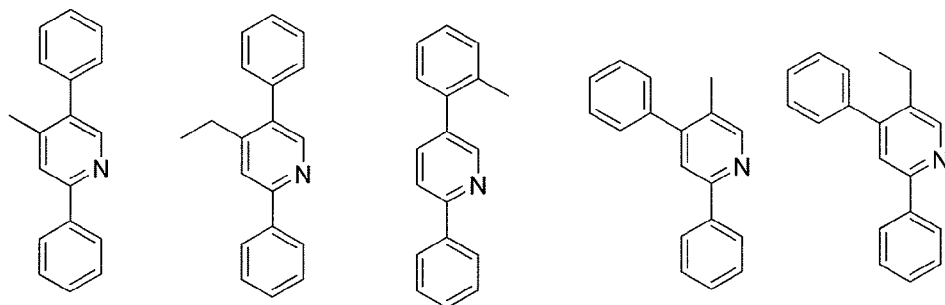






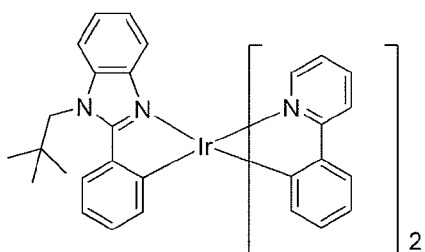
[0053] Additional specific examples of heteroleptic compounds include compounds containing L2 selected from the group consisting of:



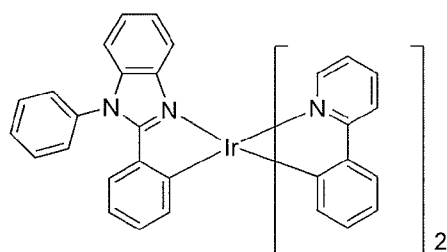


[0054] In another aspect, the heteroleptic compound includes both an L1 and an L2 from the two immediately preceding groups.

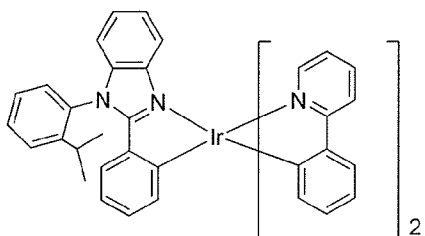
[0055] Preferably, the heteroleptic compound is selected from the group consisting of:



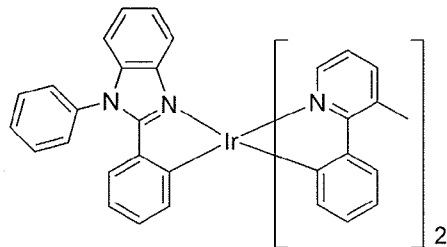
Compound 1



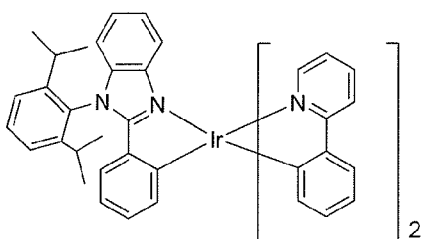
Compound 2



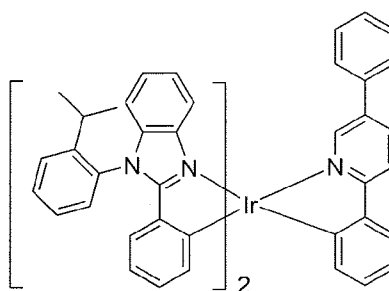
Compound 3



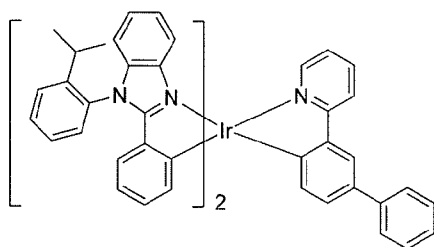
Compound 4



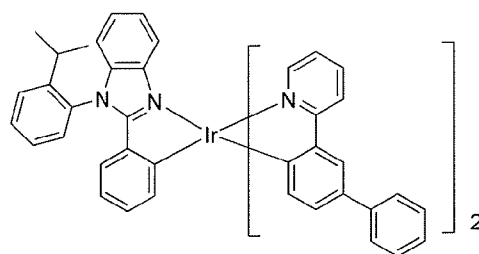
Compound 5



Compound 6



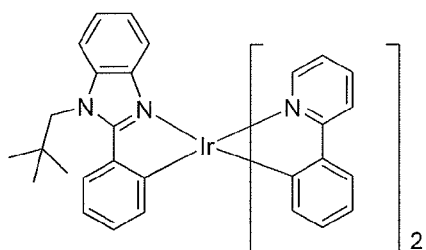
Compound 7



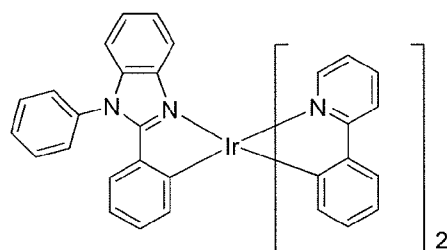
Compound 8

[0056] More preferably, the heteroleptic compound is selected from Compounds 1, 3, 5-8.

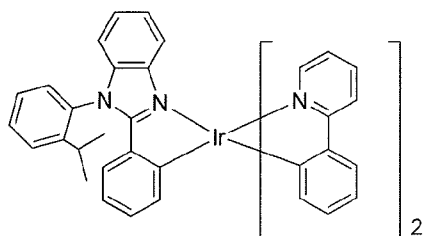
[0057] In another aspect, preferably the heteroleptic compound is selected from the group consisting of:



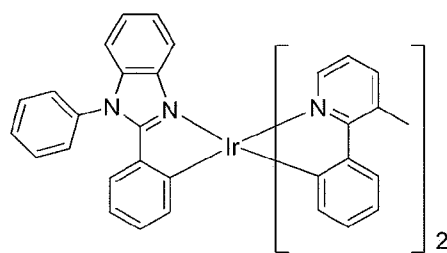
Compound 1



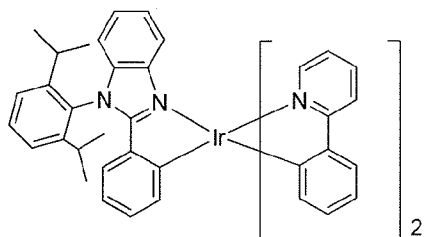
Compound 2



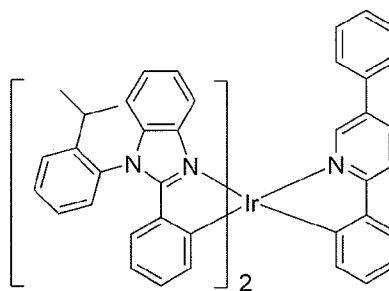
Compound 3



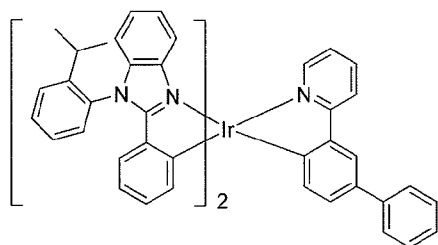
Compound 4



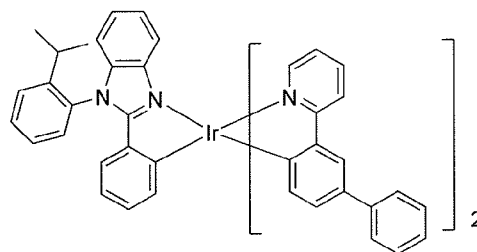
Compound 5



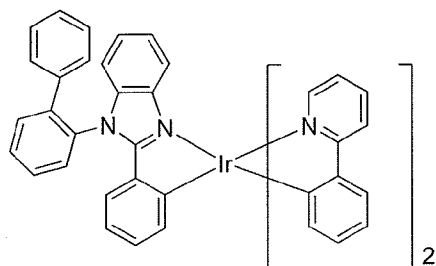
Compound 6



Compound 7

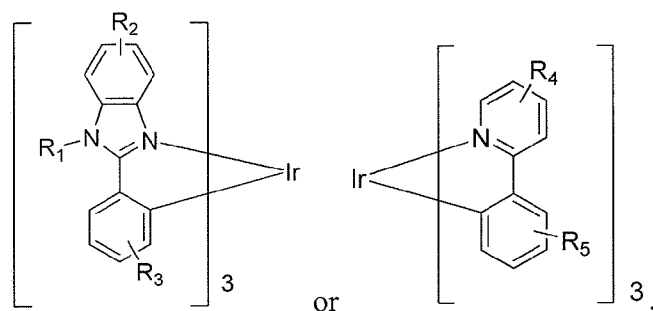
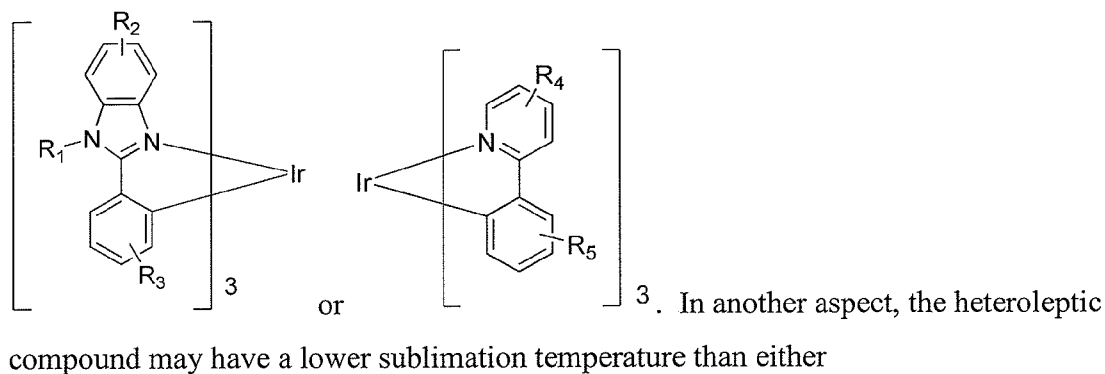


Compound 8



Compound 9

[0058] In one aspect, the heteroleptic compound has an emission spectrum with a narrower full width at half maximum (FWHM) than either

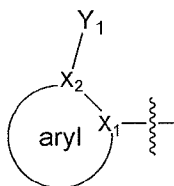


[0059] Additionally, an organic light emitting device is also provided. The device comprises an anode, a cathode, and an organic layer, disposed between the anode and the cathode. The organic layer further comprises a heteroleptic compound $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$, as described above. Preferably, the organic layer contains a heteroleptic compound selected

from the group consisting of Compound 1-Compound 8. More preferably, the organic layer contains a heteroleptic compound selected from the group consisting of Compounds 1, 3, and 5-8.

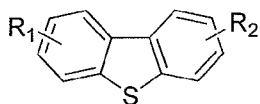
[0060] Further, an organic light emitting device comprising an anode, a cathode, and an organic layer that is disposed between the anode and the cathode, itself further comprising a heteroleptic compound selected from the group consisting of Compound 1-Compound 9 is also provided.

[0061] The organic layer of the device may comprise a heteroleptic compound wherein R_1 is selected from the group consisting of alkyl, heteroalkyl, aryl, heteroaryl, substituted aryl, and substituted heteroaryl, and where R_1 does not form a conjugated system with L1.



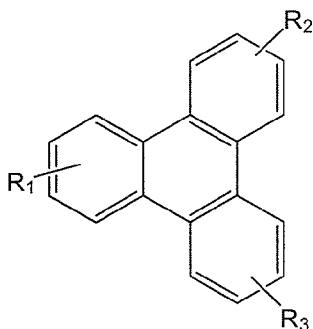
Preferably, R_1 is R_1 is where X_1 and X_2 are independently selected from C and N. Y_1 is not hydrogen. Y_1 may be joined to other substituents on the aryl ring.

[0062] In one aspect, the emissive layer further comprises a host. Preferably, the host has the formula:



where R_1 and R_2 represent, independently, mono, di, tri or tetra substitutions selected from alkyl, alkoxy, amino, alkenyl, alkynyl, arylkyl, aryl and heteroaryl, or no substitution; and where at least one of R_1 and R_2 includes a triphenylene group.

[0063] In another aspect, the host has the formula:



where each of R_1 , R_2 , and R_3 is independently a hydrogen, a non-fused aryl group, or a non-fused heteroaryl group having one or more meta-substituents,

wherein at least one of R_1 , R_2 , and R_3 is not hydrogen. Each meta-substituent is a non-fused aryl or heteroaryl group optionally substituted with further substituents selected from the group consisting of non-fused aryl groups, non-fused heteroaryl groups, and alkyl groups.

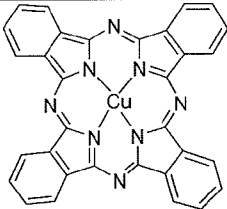
[0064] The materials described herein as useful for a particular layer in an organic light emitting device may be used in combination with a wide variety of other materials present in the device. For example, emissive dopants disclosed herein may be used in conjunction with a wide variety of hosts, transport layers, blocking layers, injection layers, electrodes and other layers that may be present. The materials described or referred to below are non-limiting examples of materials that may be useful in combination with the compounds disclosed herein, and one of skill in the art can readily consult the literature to identify other materials that may be useful in combination.

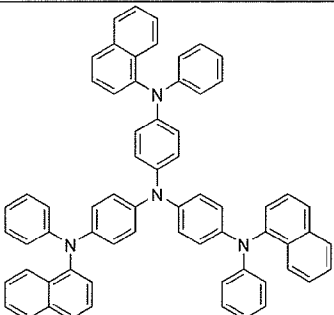
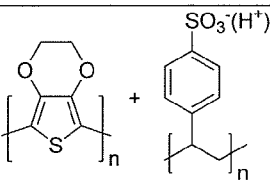
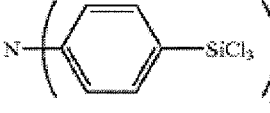
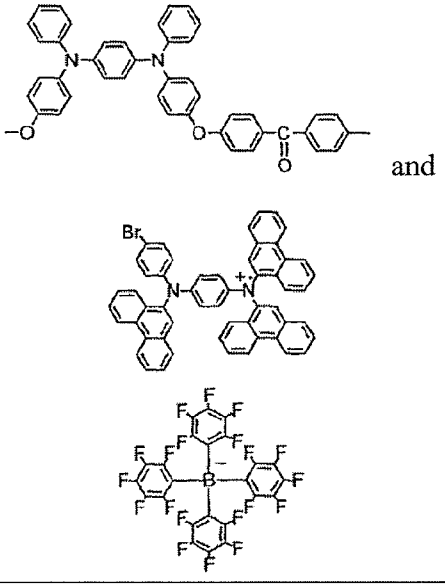
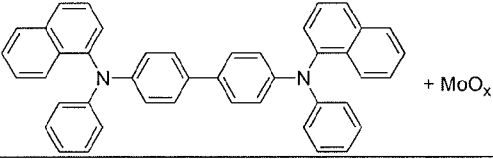
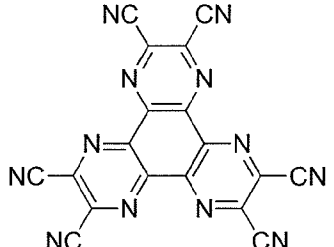
[0065] A consumer product comprising a device is also provided, wherein the device further comprises an anode, a cathode and an organic layer. The organic layer further comprises a phenylpyridine and phenylbenzimidazole-containing complex as described.

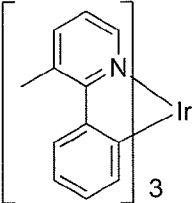
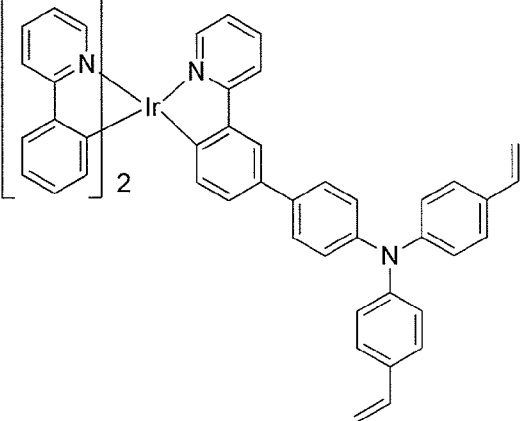
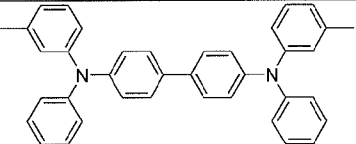
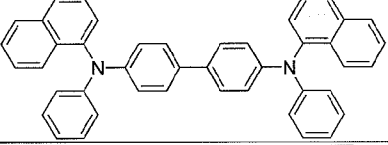
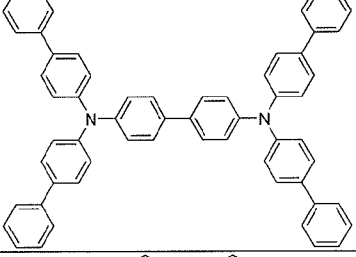
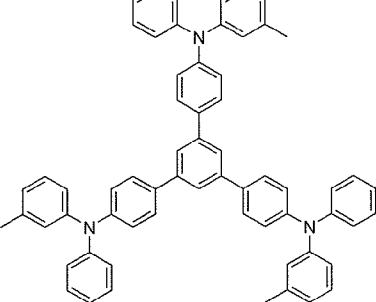
[0066] In particular, a consumer product containing a device, in which the organic layer of the device contains a heteroleptic compound selected from the group consisting of Compounds 1-9, is provided.

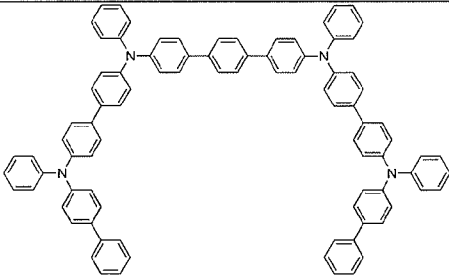
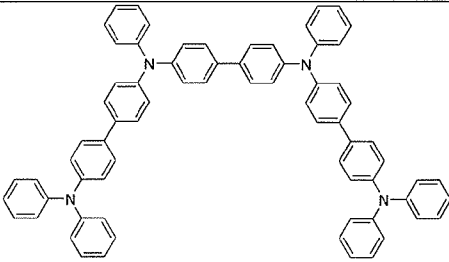
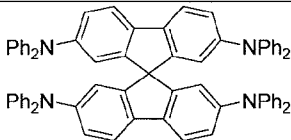
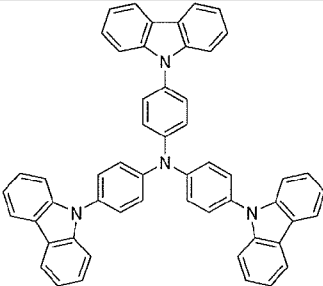
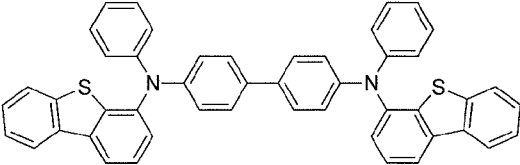
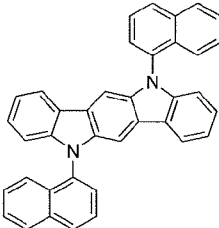
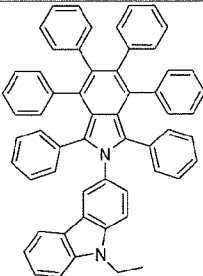
[0067] In addition to and / or in combination with the materials disclosed herein, many hole injection materials, hole transporting materials, host materials, dopant materials, exciton/hole blocking layer materials, electron transporting and electron injecting materials may be used in an OLED. Non-limiting examples of the materials that may be used in an OLED in combination with materials disclosed herein are listed in Table 1 below. Table 1 lists non-limiting classes of materials, non-limiting examples of compounds for each class, and references that disclose the materials.

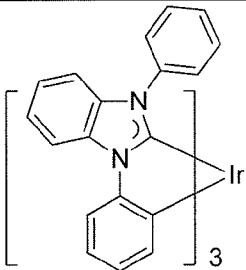
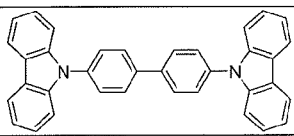
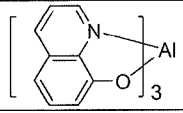
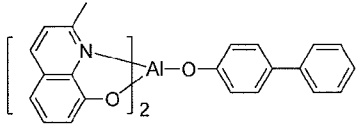
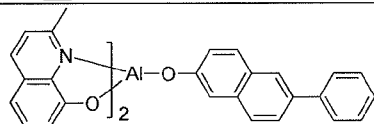
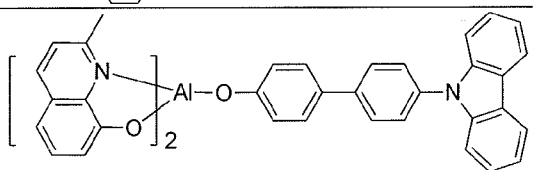
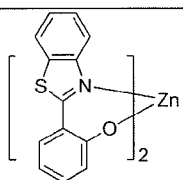
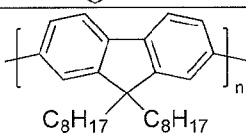
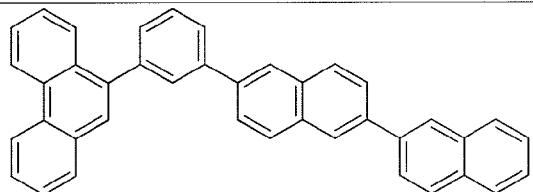
Table 1.

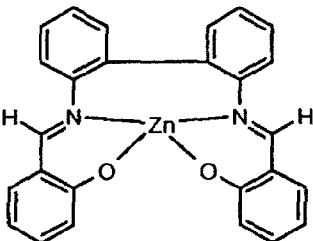
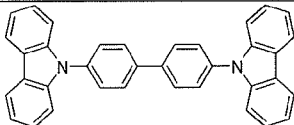
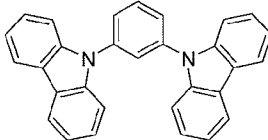
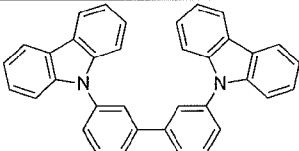
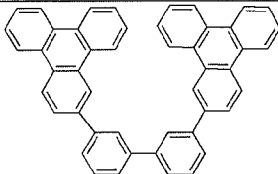
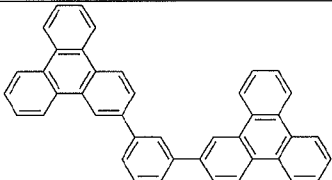
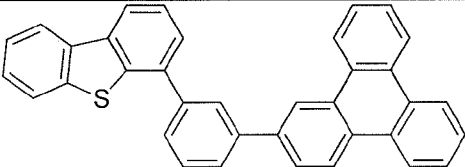
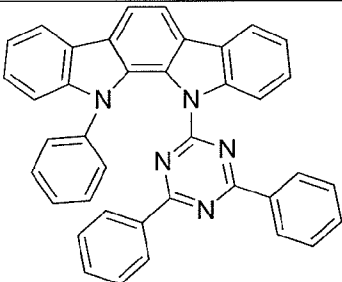
MATERIAL	EXAMPLES OF MATERIAL	PUBLICATIONS
Hole injection materials		
Phthalocyanine and porphyrin compounds		Appl. Phys. Lett. 69, 2160 (1996)

Starburst triarylamines		J. Lumin. 72-74, 985 (1997)
CF _x Fluorohydrocarbon polymer	$\left[\text{CH}_x\text{F}_y \right]_n$	Appl. Phys. Lett. 78, 673 (2001)
Conducting polymers (e.g., PEDOT:PSS, polyaniline, polythiophene)		Synth. Met. 87, 171 (1997) WO2007002683
Phosphonic acid and silane SAMs		US20030162053
Triaryamine or polythiophene polymers with conductivity dopants		EA01725079A1
Arylamines complexed with metal oxides such as molybdenum and tungsten oxides		SID Symposium Digest, 37, 923 (2006) WO2009018009
p-type semiconducting organic complexes		US20020158242

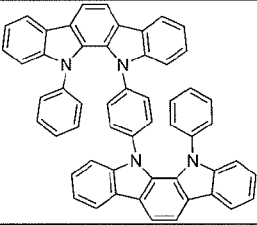
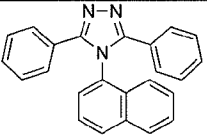
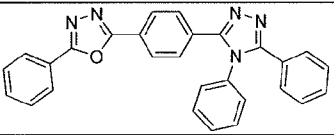
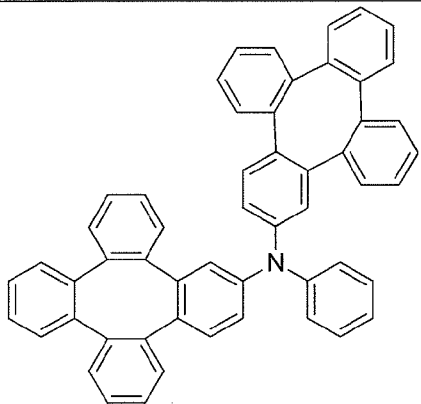
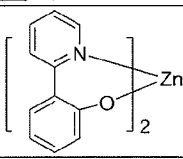
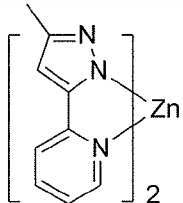
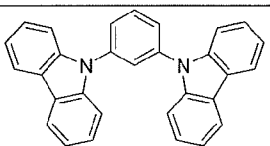
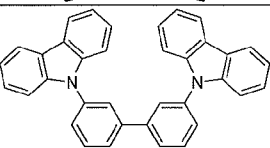
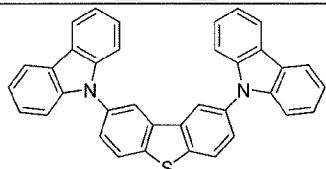
Metal organometallic complexes		US20060240279
Cross-linkable compounds		US20080220265
Hole transporting materials		
Triarylamines (e.g., TPD, α -NPD)		Appl. Phys. Lett. 51, 913 (1987)
		US5061569
		EP650955
		J. Mater. Chem. 3, 319 (1993)

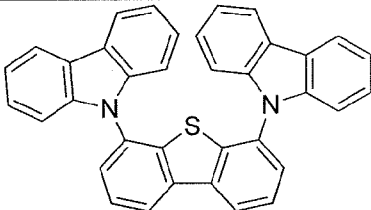
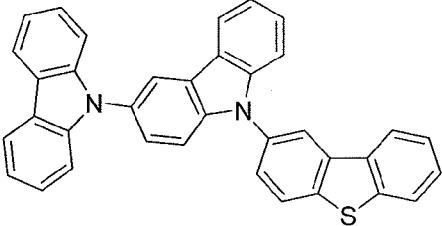
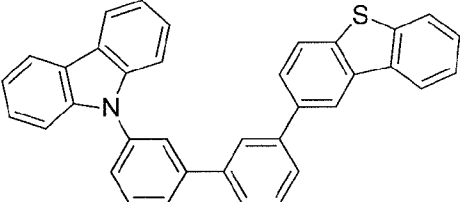
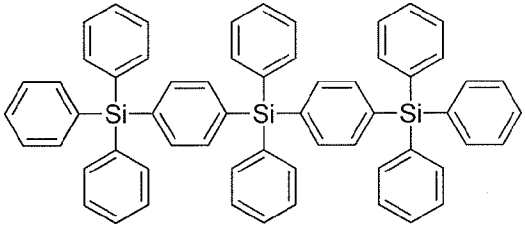
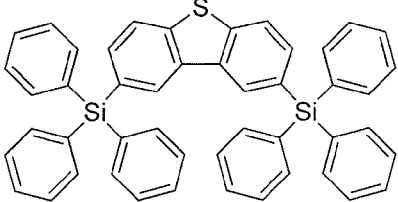
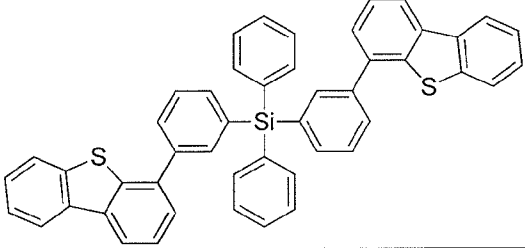
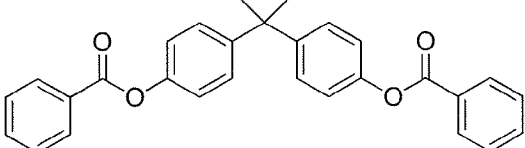
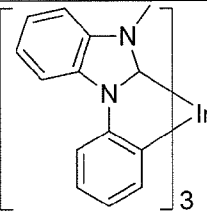
		Appl. Phys. Lett. 90, 183503 (2007)
		Appl. Phys. Lett. 90, 183503 (2007)
Triarylamine on spirofluorene core		Synth. Met. 91, 209 (1997)
Arylamine carbazole compounds		Adv. Mater. 6, 677 (1994), US20080124572
Triarylamine with (di)benzothiophene/(di)benzofuran		US20070278938, US20080106190
Indolocarbazoles		Synth. Met. 111, 421 (2000)
Isoindole compounds		Chem. Mater. 15, 3148 (2003)

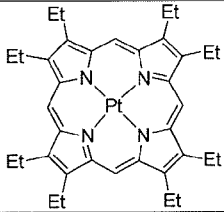
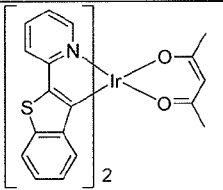
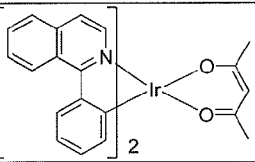
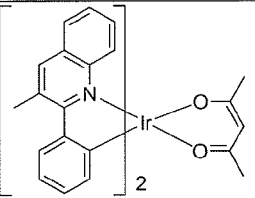
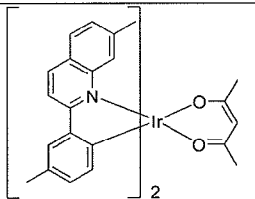
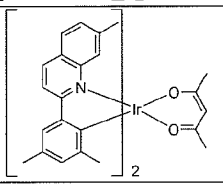
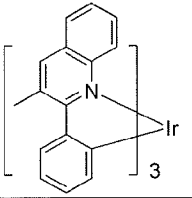
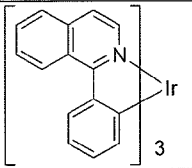
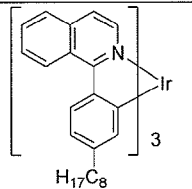
Metal carbene complexes		US20080018221
Phosphorescent OLED host materials		
Red hosts		
Arylcarbazoles		Appl. Phys. Lett. 78, 1622 (2001)
Metal 8-hydroxyquinolates (e.g., Alq ₃ , BAlq)		Nature 395, 151 (1998)
		US20060202194
		WO2005014551
		WO2006072002
Metal phenoxybenzothiazole compounds		Appl. Phys. Lett. 90, 123509 (2007)
Conjugated oligomers and polymers (e.g., polyfluorene)		Org. Electron. 1, 15 (2000)
Aromatic fused rings		WO2009066779, WO2009066778, WO2009063833, US20090045731, US20090045730, WO2009008311, US20090008605, US20090009065

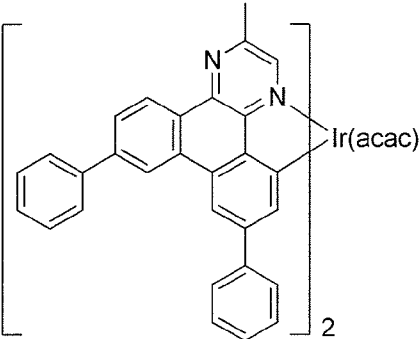
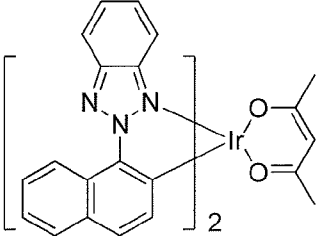
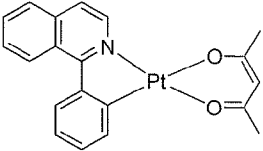
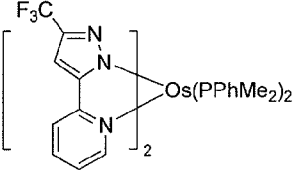
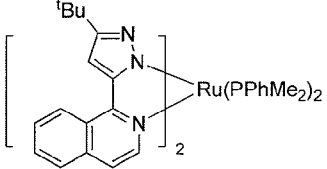
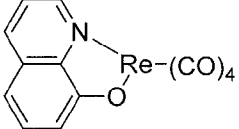
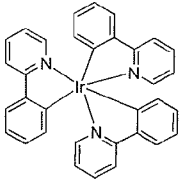
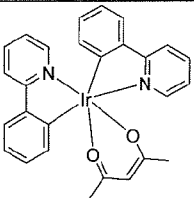
Zinc complexes		WO2009062578
Green hosts		
Arylcarbazoles		Appl. Phys. Lett. 78, 1622 (2001)
		US20030175553
		WO2001039234
Aryltriphenylene compounds		US20060280965
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		WO2009021126
Donor acceptor type molecules		WO2008056746

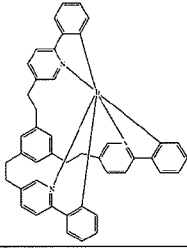
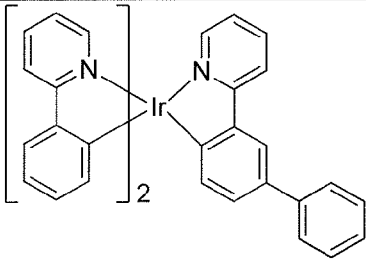
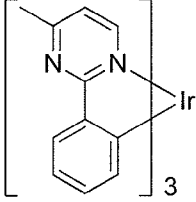
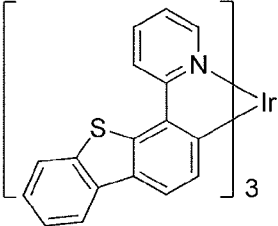
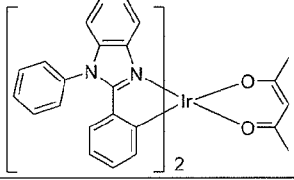
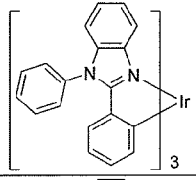
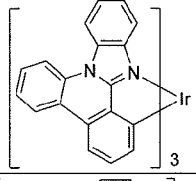
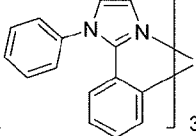
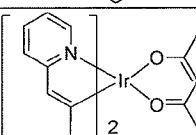
Aza-carbazole/DBT/DBF		JP2008074939
Polymers (e.g., PVK)		Appl. Phys. Lett. 77, 2280 (2000)
Spirofluorene compounds		WO2004093207
Metal phenoxybenzooxazole compounds		WO2005089025
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		JP200511610
Spirofluorene-carbazole compounds		JP2007254297
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Indolocabazoles		WO2007063796

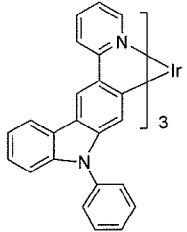
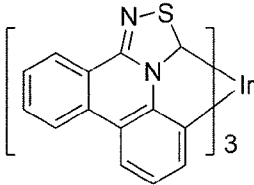
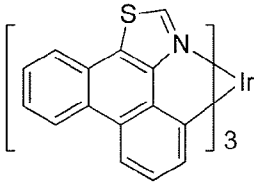
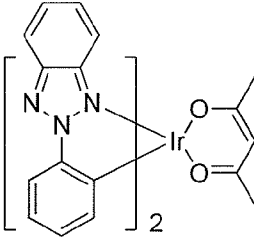
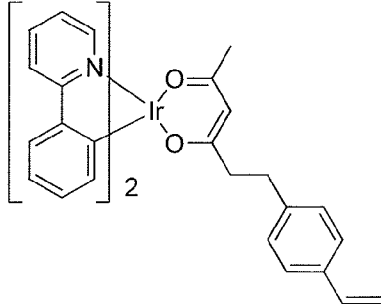
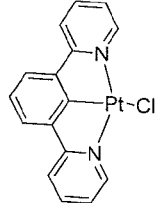
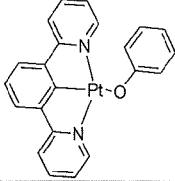
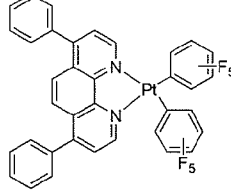
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5-member ring electron deficient heterocycles (e.g., triazole, oxadiazole)		J. Appl. Phys. 90, 5048 (2001)
		WO2004107822
Tetraphenylene complexes		US20050112407
Metal phenoxypyridine compounds		WO2005030900
Metal coordination complexes (e.g., Zn, Al with N^N ligands)		US20040137268, US20040137267
Blue hosts		
Arylcarbazoles		Appl. Phys. Lett, 82, 2422 (2003)
		US20070190359
Dibenzothiophene/Dibenz ofuran-carbazole compounds		WO2006114966, US20090167162

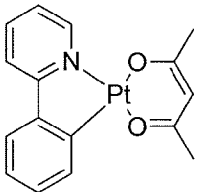
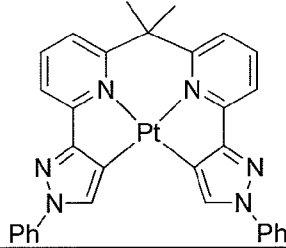
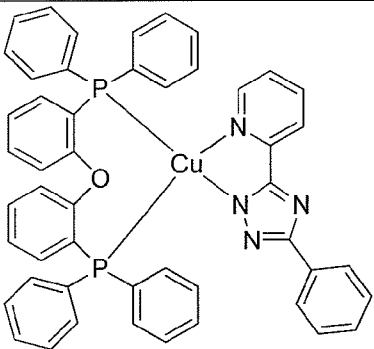
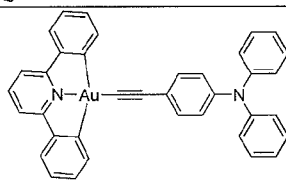
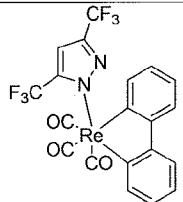
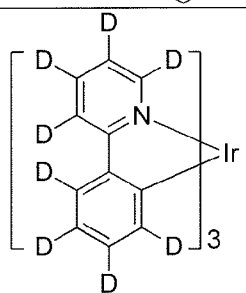
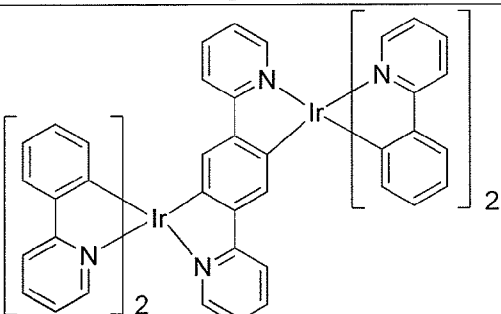
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		WO2009086028
		US20090030202, US20090017330
Silicon aryl compounds		US20050238919
		WO2009003898
Silicon/Germanium aryl compounds		EP2034538A
Aryl benzoyl ester		WO2006100298
High triplet metal organometallic complex		US7154114
Phosphorescent dopants		

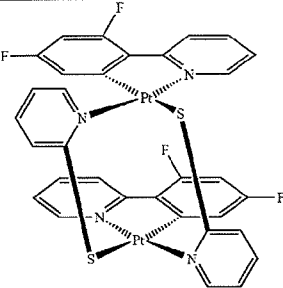
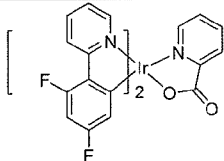
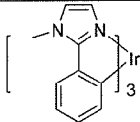
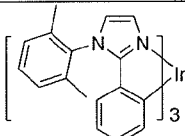
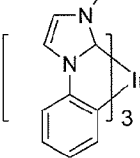
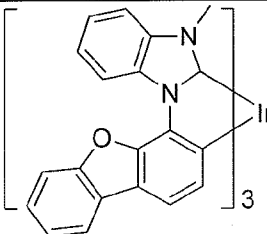
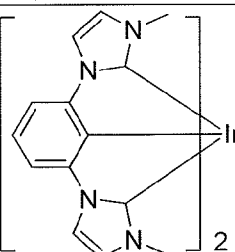
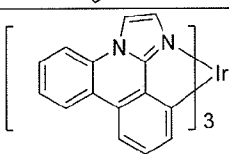
Red dopants		
Heavy metal porphyrins (e.g., PtOEP)		Nature 395, 151 (1998)
Iridium(III) organometallic complexes		Appl. Phys. Lett. 78, 1622 (2001)
		US2006835469
		US2006835469
		US20060202194
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	 H ₁₇ C ₈	Adv. Mater. 19, 739 (2007)

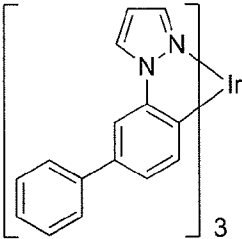
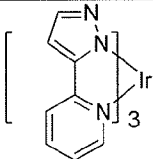
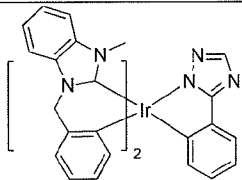
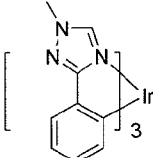
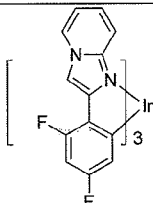
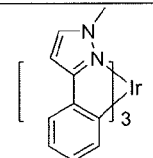
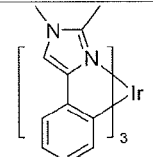
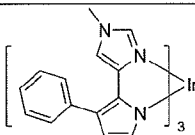
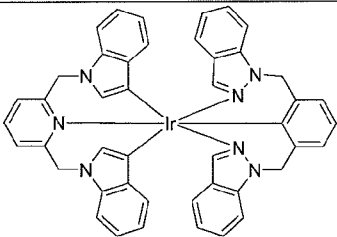
		WO2009100991
		WO2008101842
Platinum(II) organometallic complexes		WO2003040257
Osmium(III) complexes		Chem. Mater. 17, 3532 (2005)
Ruthenium(II) complexes		Adv. Mater. 17, 1059 (2005)
Rhenium (I), (II), and (III) complexes		US20050244673
Green dopants		
Iridium(III) organometallic complexes	 and its derivatives	Inorg. Chem. 40, 1704 (2001)
		US20020034656

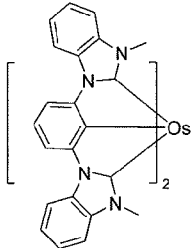
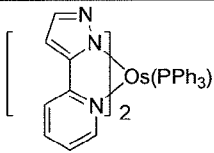
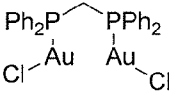
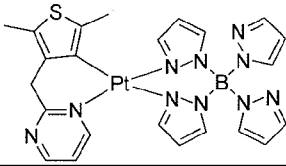
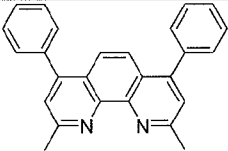
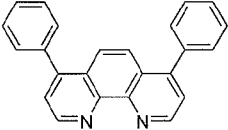
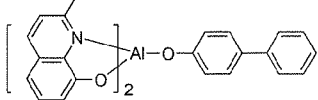
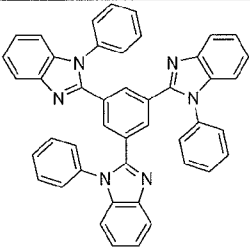
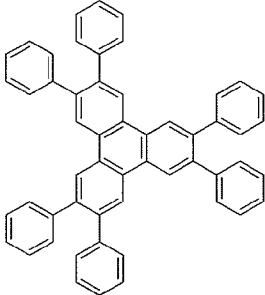
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		US20070190359
		US 20060008670 JP2007123392
		Adv. Mater. 16, 2003 (2004)

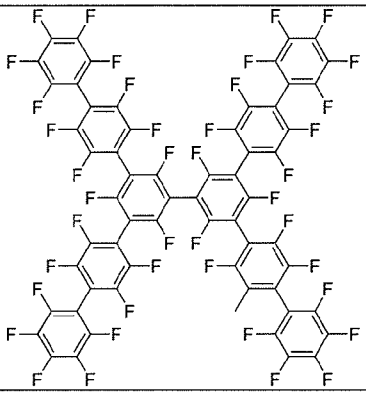
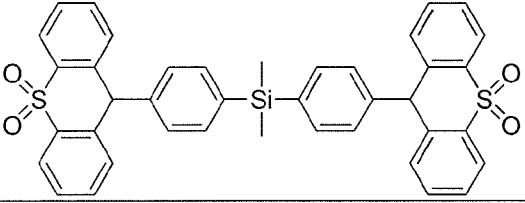
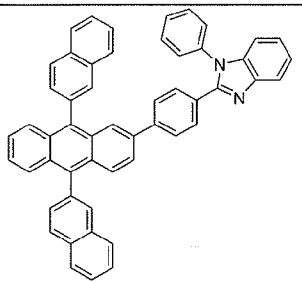
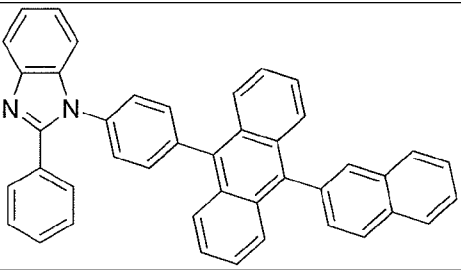
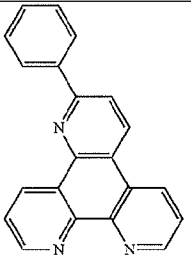
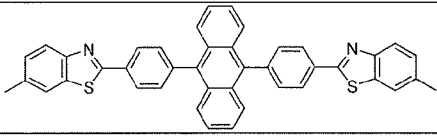
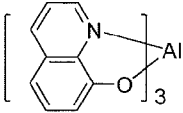
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Monomer for polymeric metal organometallic compounds		US7250226, US7396598
Pt(II) organometallic complexes, including polydentate ligands		Appl. Phys. Lett. 86, 153505 (2005)
		Appl. Phys. Lett. 86, 153505 (2005)
		Chem. Lett. 34, 592 (2005)

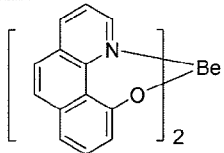
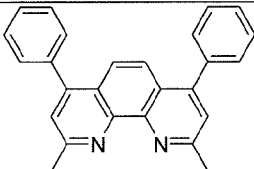
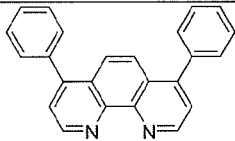
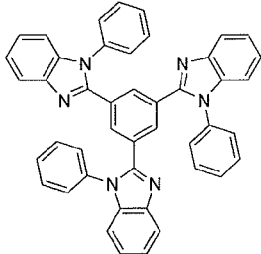
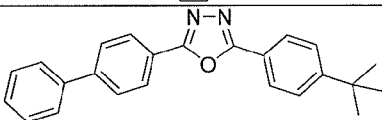
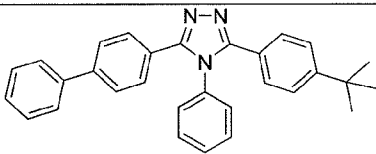
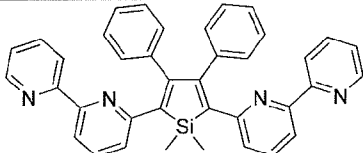
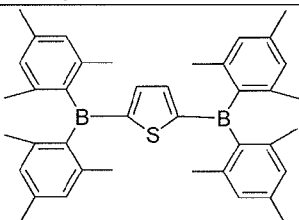
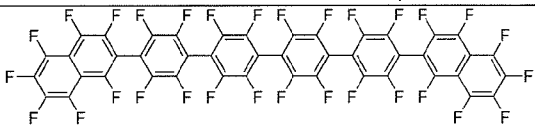
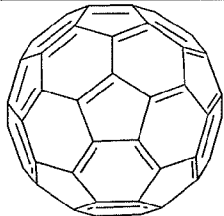
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Cu complexes		WO2009000673
Gold complexes		Chem. Commun. 2906 (2005)
Rhenium(III) complexes		Inorg. Chem. 42, 1248 (2003)
Deuterated organometallic complexes		US20030138657
Organometallic complexes with two or more metal centers		US20030152802

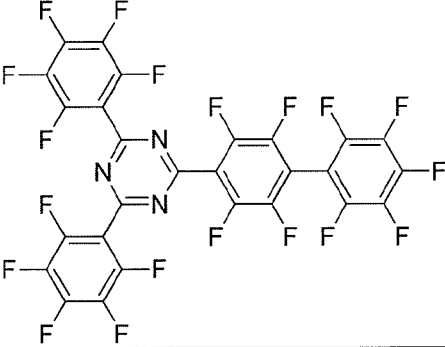
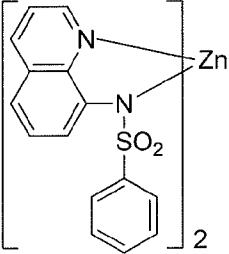
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		US20070190359, US20080297033

		US7338722
		US20020134984
		Angew. Chem. Int. Ed. 47, 1 (2008)
		Chem. Mater. 18, 5119 (2006)
		Inorg. Chem. 46, 4308 (2007)
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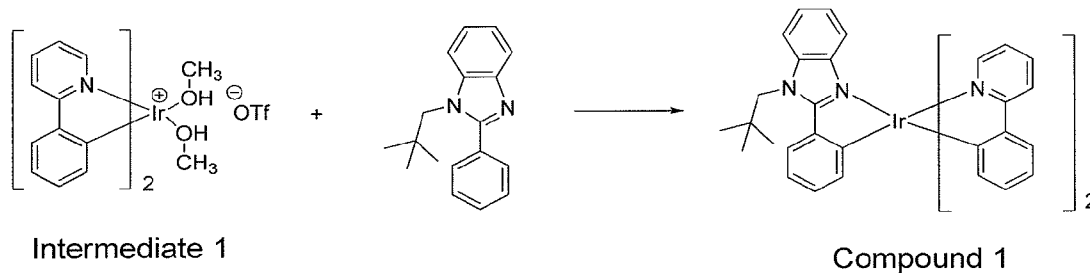
Osmium(II) complexes		US7279704
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Gold complexes		Appl. Phys. Lett. 74, 1361 (1999)
Platinum(II) complexes		WO2006098120, WO2006103874
Exciton/hole blocking layer materials		
Bathocuprine compounds (e.g., BCP, BPhen)		Appl. Phys. Lett. 75, 4 (1999)
		Appl. Phys. Lett. 79, 449 (2001)
Metal 8-hydroxyquinolates (e.g., BALq)		Appl. Phys. Lett. 81, 162 (2002)
5-member ring electron deficient heterocycles such as triazole, oxadiazole, imidazole, benzoimidazole		Appl. Phys. Lett. 81, 162 (2002)
Triphenylene compounds		US20050025993

Fluorinated aromatic compounds		Appl. Phys. Lett. 79, 156 (2001)
Phenothiazine-S-oxide		WO2008132085
Electron transporting materials		
Anthracene-benzimidazole compounds		WO2003060956
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Aza triphenylene derivatives		US20090115316
Anthracene-benzothiazole compounds		Appl. Phys. Lett. 89, 063504 (2006)
Metal 8-hydroxyquinolates (e.g., Alq ₃ , Zrq ₄)		Appl. Phys. Lett. 51, 913 (1987) US7230107

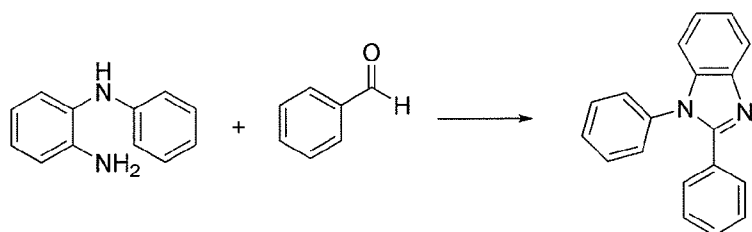
Metal hydroxybenoquinolates		Chem. Lett. 5, 905 (1993)
Bathocuprine compounds such as BCP, BPhen, etc		Appl. Phys. Lett. 91, 263503 (2007)
		Appl. Phys. Lett. 79, 449 (2001)
5-member ring electron deficient heterocycles (e.g., triazole, oxadiazole, imidazole, benzoimidazole)		Appl. Phys. Lett. 74, 865 (1999)
		Appl. Phys. Lett. 55, 1489 (1989)
		Jpn. J. Apply. Phys. 32, L917 (1993)
Silole compounds		Org. Electron. 4, 113 (2003)
Arylborane compounds		J. Am. Chem. Soc. 120, 9714 (1998)
Fluorinated aromatic compounds		J. Am. Chem. Soc. 122, 1832 (2000)
Fullerene (e.g., C60)		US20090101870

Triazine complexes		US20040036077
Zn (N^N) complexes		US6528187

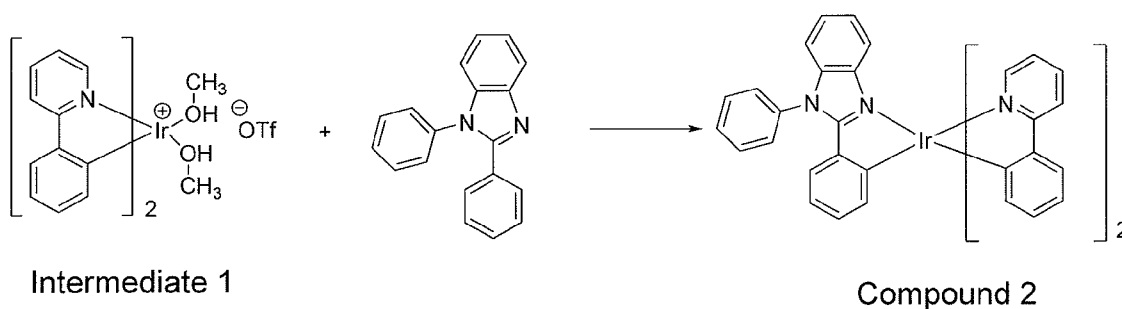
EXPERIMENTAL

Compound Examples*Synthesis of Compound 1*

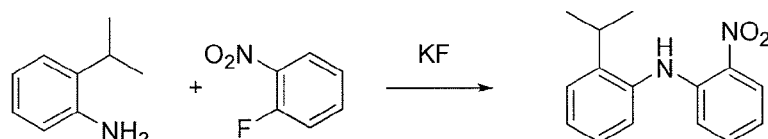
[0068] Synthesis of Compound 1. Intermediate 1 (1.4 g, 1.96 mmol) and 1-neopentyl-2-phenyl-1H-benzodimidazole (1.6 g, 5.9 mmol) were mixed with 30 mL of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:2 dichloromethane and hexanes as eluent. 0.3 g of desired product was obtained after purification.

Synthesis of Compound 2

[0069] Synthesis of 1,2-diphenyl-1H-benzo[d]imidazole. N¹-phenylbenzene-1,2-diamine (4.15 g, 22 mmol) and benzaldehyde (2.1 g, 20 mmol) were mixed with methoxyethanol (60 ml) in a three-neck flask. The mixture was heated up to reflux for 48 hours. After cooled to room temperature, the solvent was evaporated. The residue was purified by column chromatography using dichloromethane to 5% of ethyl acetate in dichloromethane as eluent. 2 g of desired product was obtained.

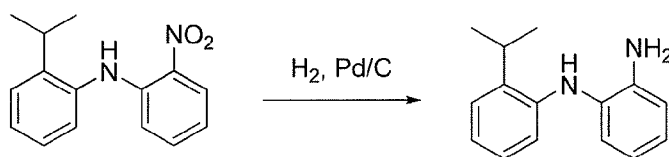


[0070] Synthesis of Compound 2. Intermediate 1 (1.32 g, 1.86 mmol) and 1,2-diphenyl-1H-benzo[d]imidazole (1.5 g, 5.5 mmol) were mixed with 40 mL of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:2 dichloromethane and hexanes as eluent. 0.3 g of desired product was obtained after purification.

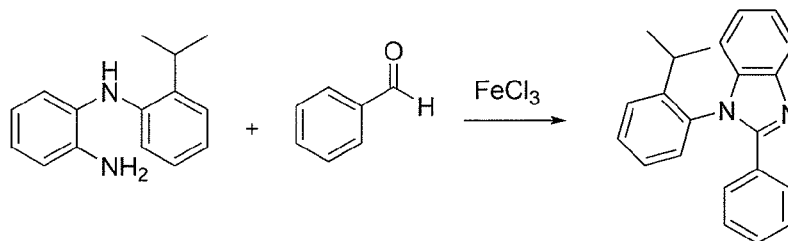
Synthesis of Compound 3

[0071] Synthesis of 2-isopropyl-N-(2-nitrophenyl)aniline. 2-isopropylaniline (27 g, 200 mmol), 2-fluoronitrobenzene (14 g, 100 mmol), and potassium fluoride (8.6 g, 150 mmol) were mixed in a one-neck flask. The mixture was heated up to 180 °C under nitrogen for 48

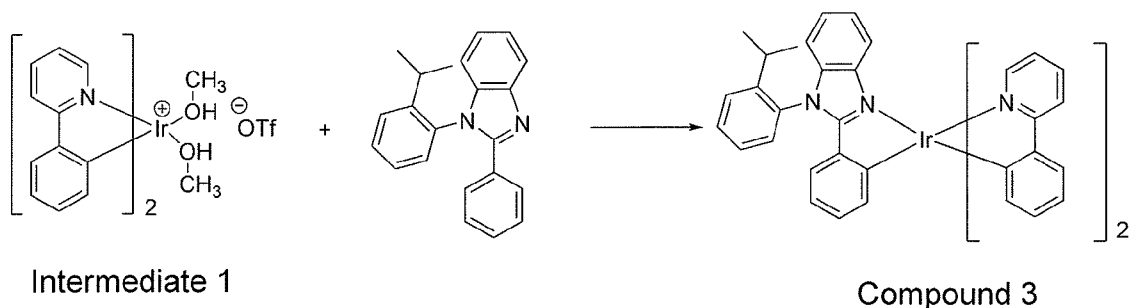
hours. After cooled to room temperature, water (200 mL) was added. The mixture was then extracted with dichloromethane (200 mL) for three times. The solvent was evaporated and the residue was purified by column chromatography using 20% of dichloromethane in hexanes. 22.5 g of desired product was obtained.



[0072] Synthesis of N¹-(2-isopropylphenyl)benzene-1,2-diamine. 2-isopropyl-N-(2-nitrophenyl)aniline (22.7 g, 89 mmol) and 10% palladium on carbon (0.6 g) were mixed with 150 mL of ethanol under nitrogen in a plastic coated hydrogenation vessel. The mixture was put on a par hydrogenator and reacted under 40 psi of hydrogen until there is no pressure drop. The catalyst was filtered off through a Celite bed. The solvent was evaporated. The product was used for the next step without further purification. 20 g of desired product was obtained.

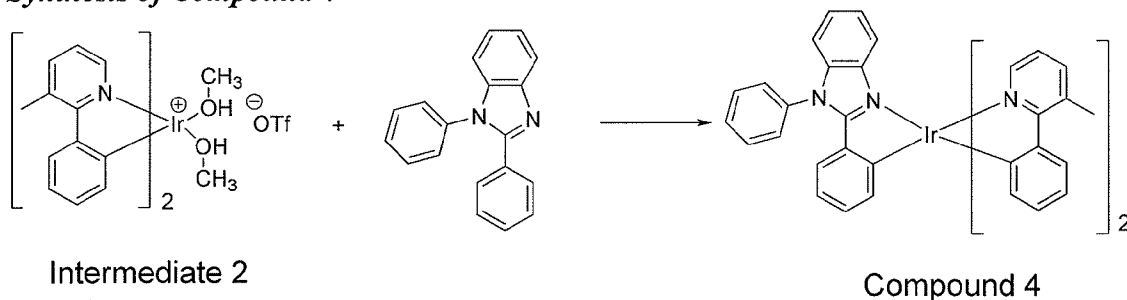


[0073] Synthesis of 1-(2-isopropylphenyl)-2-phenyl-1H-benzo[d]imidazole. N¹-(2-isopropylphenyl)benzene-1,2-diamine (20 g, 88 mmol) and benzaldehyde (8.5 g, 80 mmol) were reacted in acetonitrile (100 mL) under reflux for 3 hours. The reaction mixture was cooled to room temperature. Ferric chloride (0.13 g, 0.8 mmol) was added. The reaction mixture was heated up again to reflux overnight. Air was bubbled through the reaction while reflux. The solvent was evaporated. The residue was dissolved in dichloromethane (200 mL) and ran through a short silica gel plug. The crude product was purified by column chromatography using dichloromethane to 3% of ethyl acetate in dichloromethane. The product was further purified by recrystallizing from ethanol. 8 g of desired product was obtained.



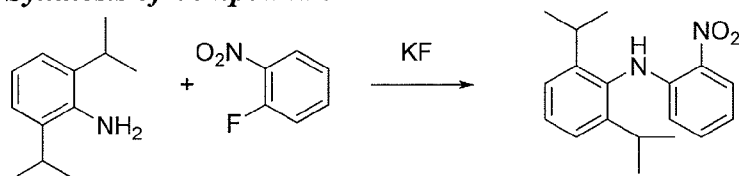
[0074] Synthesis of Compound 3. Intermediate 1 (1.5 g, 2.1 mmol) and 1-(2-isopropylphenyl)-2-phenyl-1H-benzo[d]imidazole (2 g, 6.4 mmol) were mixed with 30 ml of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:2 dichloromethane and hexanes as eluent. 0.7 g of desired product was obtained after purification.

Synthesis of Compound 4



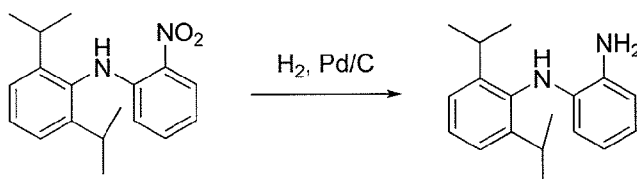
[0075] Synthesis of Compound 4. Intermediate 2 (7.4 g, 10 mmol) and 1,2-diphenyl-1H-benzo[d]imidazole (8.11 g, 30 mmol) were mixed with 200 ml of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:2 dichloromethane and hexanes as eluent. 1.4 g of desired product was obtained after purification.

Synthesis of Compound 5

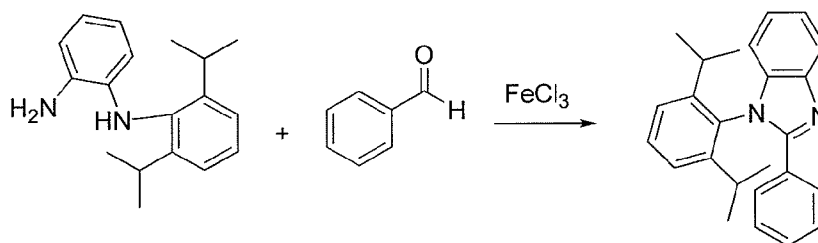


[0076] Synthesis of 2,6-diisopropyl-N-(2-nitrophenyl)aniline. 2,6-diisopropylaniline (25 g, 141 mmol), 2-fluoronitrobenzene (10 g, 70 mmol), and potassium fluoride (6.2 g, 106 mmol)

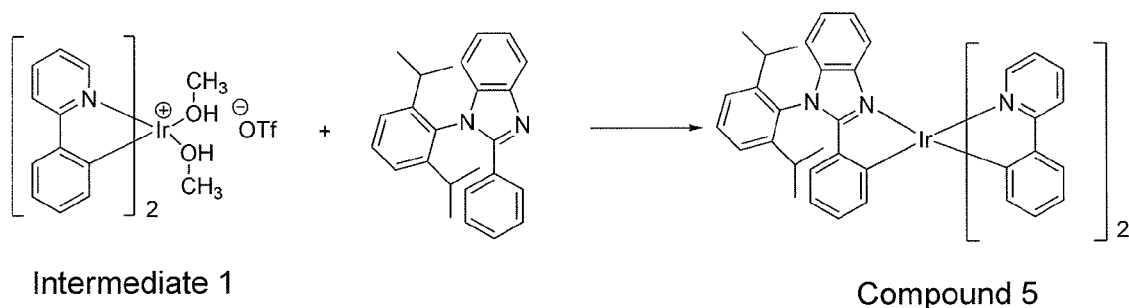
were mixed in a one-neck flask. The mixture was heated up to 180 °C under nitrogen for 48 hours. After cooled to room temperature, water (200 mL) was added. The mixture was then extracted with dichloromethane (200 mL) for three times. The solvent was evaporated and the residue was purified by column chromatography using 20% of dichloromethane in hexanes. 10 g of desired product was obtained.



[0077] Synthesis of N¹-(2,6-diisopropylphenyl)benzene-1,2-diamine. 2,6-diisopropyl-N-(2-nitrophenyl)aniline (9.5 g, 32 mmol) and 10% palladium on carbon (0.4 g) were mixed with 150 ml of ethanol under nitrogen in a plastic coated hydrogenation vessel. The mixture was put on a par hydrogenator and reacted under 40 psi of hydrogen until there is no pressure drop. The catalyst was filtered off through a Celite bed. The solvent was evaporated. The product was used for the next step without further purification. 8.5 g of desired product was obtained.

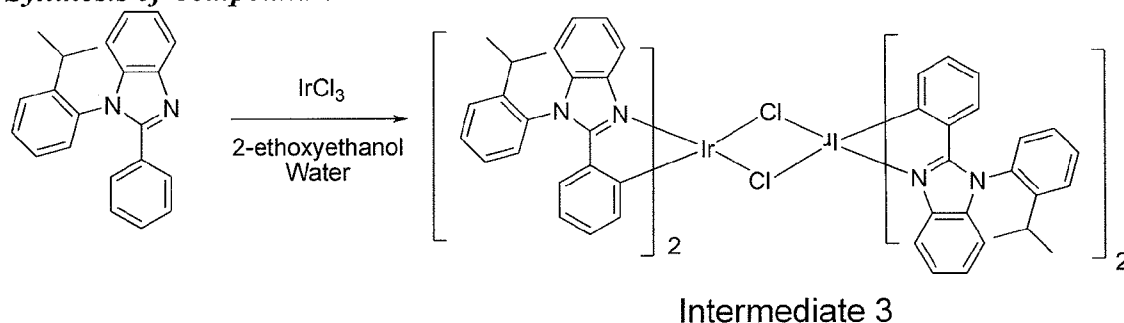


[0078] Synthesis of 1-(2,6-diisopropylphenyl)-2-phenyl-1H-benzo[d]imidazole. N¹-(2,6-diisopropylphenyl)benzene-1,2-diamine (8.5 g, 32 mmol) and benzaldehyde (3 g, 28.8 mmol) were reacted in acetonitrile (100 ml) under reflux for 3 hours. The reaction mixture was cooled to room temperature. Ferric chloride (0.05 g, 0.28 mmol) was added. The reaction mixture was heated up again to reflux overnight. Air was bubbled through the reaction while reflux. The solvent was evaporated. The residue was dissolved in dichloromethane (200 mL) and ran through a short silica gel plug. The crude product was purified by column chromatography using dichloromethane to 3% of ethyl acetate in dichloromethane. 3.4 g of desired product was obtained.

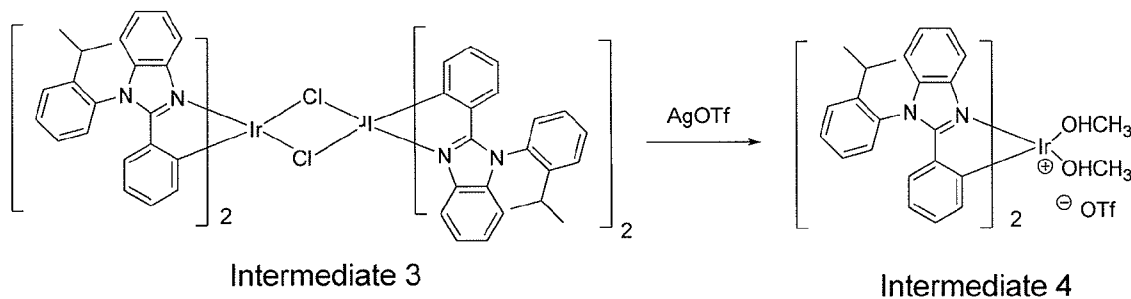


[0079] Synthesis of Compound 5. Intermediate 1 (2.1 g, 2.9 mmol) and 1-(2,6-diisopropylphenyl)-2-phenyl-1H-benzo[d]imidazole (3.1 g, 8.7 mmol) were mixed with 60 ml of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:2 dichloromethane and hexanes as eluent. 1.1 g of desired product was obtained after purification.

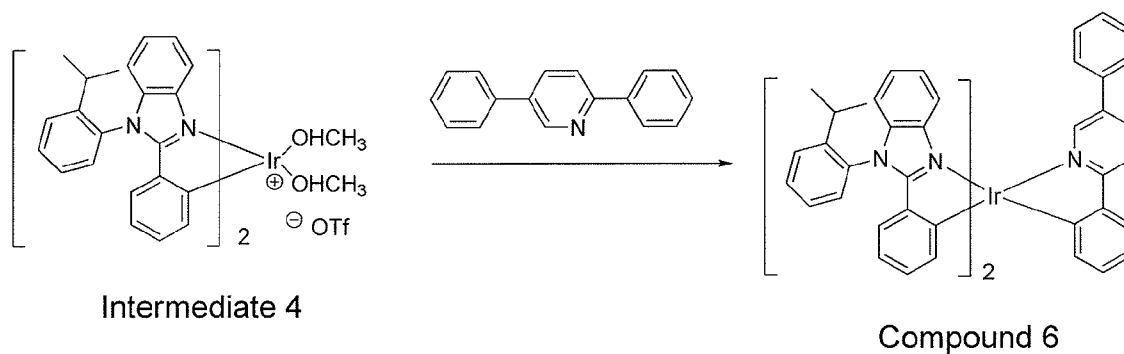
Synthesis of Compound 6



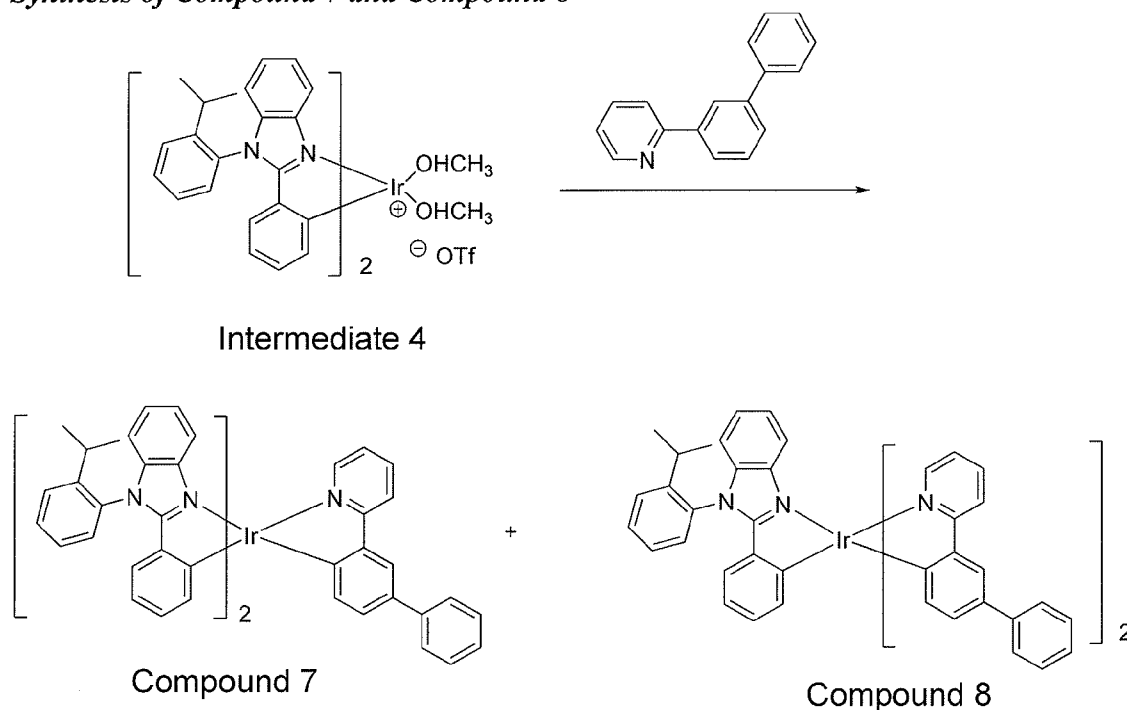
[0080] Synthesis of Intermediate 3. 1-(2-isopropylphenyl)-2-phenyl-1H-benzo[d]imidazole (3 g, 9.6 mmol) and iridium chloride (1.5 g, 4.36 mmol) were mixed with 60 mL of 2-ethoxyethanol and 20 ml of water in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The solid was thoroughly washed with methanol and hexanes and then dried under vacuum. 3.5 g of product was obtained.



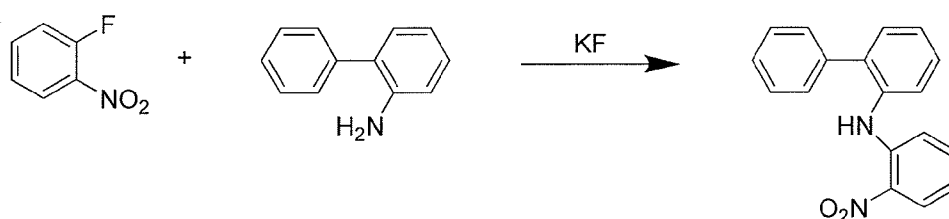
[0081] Synthesis of intermediate 4. Intermediate 3 (3.5 g, 2.06 mmol) and silver triflate (1.06 g, 4.12 mmol) were mixed with 300 ml of dichloromethane and 30 mL of methanol. The mixture was stirred at room temperature for 24 hours. The solid was filtered. The filtrate was evaporated to dryness. 4.2 g of product was obtained.



[0082] Synthesis of Compound 6. Intermediate 4 (2.0 g, 1.95 mmol) and 2,5-diphenylpyridine (1.4 g, 5.83 mmol) were mixed with 50 mL of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:1 dichloromethane and hexanes as eluent. 0.5 g of desired product was obtained after purification.

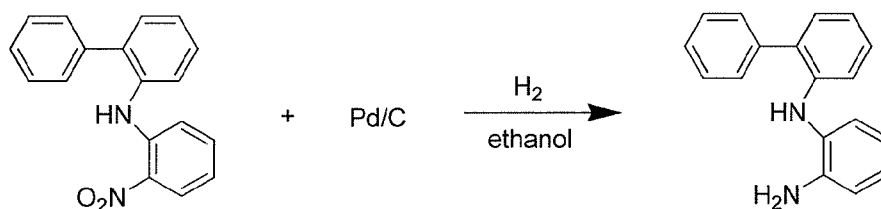
Synthesis of Compound 7 and Compound 8

[0083] Synthesis of Compound 7 and Compound 8. Intermediate 4 (2.0 g, 1.95 mmol) and 2-(biphenyl-3-yl)pyridine (1.5 g, 5.8 mmol) were mixed with 60 ml of ethanol in a three-neck flask under nitrogen. The mixture was heated up to reflux for 24 hours. After cooled to room temperature, the precipitate was collected by filtration. The product was purified by column chromatography using 1:1 dichloromethane and hexanes as eluent. 1.4 g of Compound 7 and 0.4 g of Compound 8 were collected.

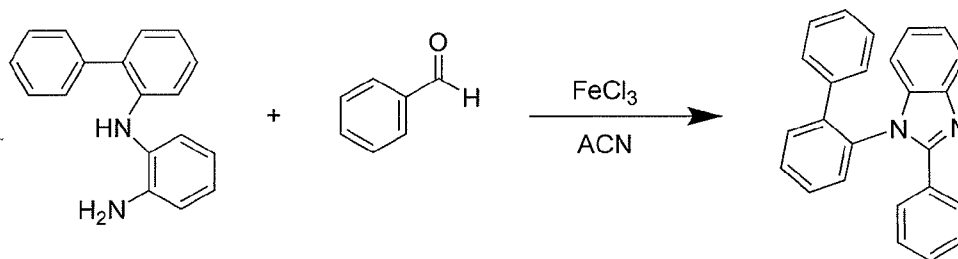
Synthesis of Compound 9

[0084] Synthesis of N-(2-nitrophenyl)biphenyl-2-amine. A mixture of 1-fluoro-2-nitrobenzene (13.06 g, 92.6 mmol), 2-aminobiphenyl (31.3 g, 185.2 mmol), and potassium fluoride (8.1 g, 138.9 mmol) was prepared in a 100 mL round bottom flask. The flask was evacuated and replaced with nitrogen. The mixture was heated to 200 °C overnight. The reaction mixture was cooled and ethyl acetate and water were added. The layers were separated and the aqueous layer was extracted with ethyl acetate. The organic layers were dried over magnesium sulfate, filtered, and evaporated. The residue was preabsorbed onto

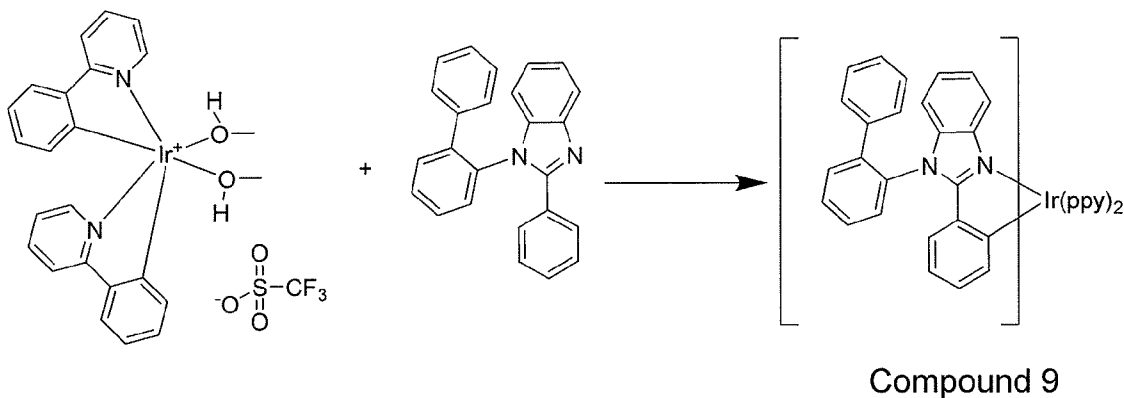
Celite and purified by column chromatography eluting with 0, 2, and 5% ethyl acetate/hexanes. 24.5 g (91%) of product was obtained.



[0085] Synthesis of N¹-(biphenyl-2-yl)benzene-1,2-diamine. N-(2-nitrophenyl)biphenyl-2-amine (19.69 g, 67.8 mmol), 10% palladium on carbon (0.29 g, 0.27 mmol), and 150 mL of ethanol was added to a Parr hydrogenator bottle. The mixture was hydrogenated on a Parr hydrogenator until no more hydrogen was taken up by the solution. The solution was filtered through Celite to remove the catalyst, Celite was washed with dichloromethane, the filtrate was evaporated to yield a brown oil, 14.8 g (84%). The product was used for the next step without further purification.



[0086] Synthesis of 1-(biphenyl-2-yl)-2-phenyl-1H-benzo[d]imidazole. N'-(biphenyl-2-yl)benzene-1,2-diamine (14.8 g, 56.85 mmol), benzaldehyde (5.2 mL, 51.68 mmol), and 200 mL of acetonitrile were added to a 500 mL 3-neck round bottom flask. The mixture was heated to reflux overnight under nitrogen. 80 mg (0.49 mmol) of iron (III) chloride was added and mixture was bubbled with air directly into cooled solution. After 3 hours the solvent was evaporated and the residue dissolved in dichloromethane and the solution passed through a silica gel plug eluting with 0 to 10% ethyl acetate/dichloromethane. 6.56 g (37%) product was obtained.



[0087] Synthesis of Compound 9. The triflate complex (2.06 g, 2.89 mmol), 1-(biphenyl-2-yl)-2-phenyl-1*H*-benzo[d]imidazole (4 g, 11.55 mmol), and 100 mL ethanol were added to a 250 mL round bottom flask. The mixture was heated to reflux overnight under nitrogen. The precipitate was collected by filtration and then purified by column. 0.75 g of product was obtained.

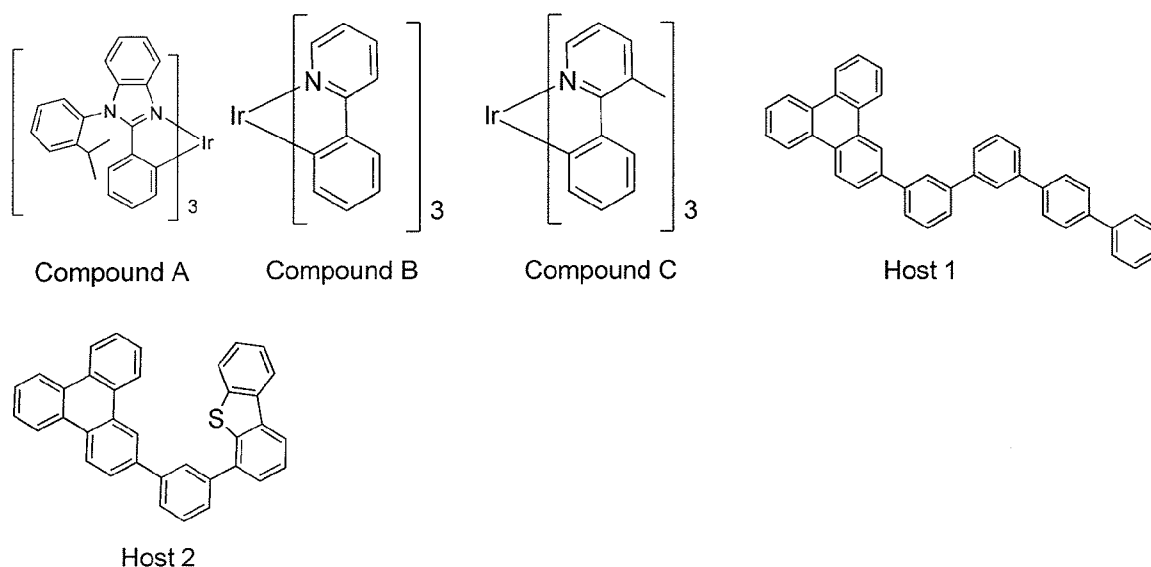
Device Examples

[0088] All example devices were fabricated by high vacuum ($<10^{-7}$ Torr) thermal evaporation. The anode electrode is ~ 800 Å, 1200 Å or 2000 Å of indium tin oxide (ITO) on glass, or 800 Å Sapphire/IZO. The cathode consists of 10 Å of LiF followed by 1000 Å of Al. All devices are encapsulated with a glass lid sealed with an epoxy resin in a nitrogen glove box (<1 ppm of H_2O and O_2) immediately after fabrication, and a moisture getter was incorporated inside the package.

[0089] The organic stack of Device Examples 1-10 consisted of sequentially, from the ITO surface (1200 Å), 100 Å of Compound C as the hole injection layer (HIL), 300 Å of 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl (α -NPD) as the hole transporting layer (HTL), 300 Å of Host-1 or Host-2 doped with 7-10% of the dopant emitter (invention Compounds 1-3) as the emissive layer (EML), 50 Å or 100 Å of Host 1 or Host 2 as the blocking layer (BL), and 400 Å or 450 Å of tris-8-hydroxyquinoline aluminum (Alq_3) as the ETL.

[0090] Comparative Examples 1-4 were fabricated similarly to the Device Examples except that Compound B or Compound C was used as the emissive dopant.

[0091] As used herein, the following compounds have the following structures:



[0092] Particular emissive dopants for the emissive layer of an OLED are provided which may lead to devices having particularly good properties. The materials for the emissive layer, and the materials and thicknesses for the BL and ETL of Device Examples 1-10 are shown in Table 2. The devices were tested, and the results measured are provided in Table 3. Devices having an emissive layer using Compounds 1-3 as the emissive dopant show improved device efficiency and lifetime as well as more saturated color indicating that these heteroleptic compounds may be beneficial.

Table 2.

Device Example	HIL	HTL	Host	A %	BL	ETL
Example 1	Compound C 100Å	NPD 300Å	Host-1	Compound 1 7%	Host-1 50Å	Alq 450Å
Example 2	Compound C 100Å	NPD 300Å	Host-1	Compound 1 10%	Host-1 50Å	Alq 450Å
Example 3	Compound C 100Å	NPD 300Å	Host-1	Compound 2 7%	Host-1 50Å	Alq 450Å
Example 4	Compound C 100Å	NPD 300Å	Host-1	Compound 2 10%	Host-1 50Å	Alq 450Å
Example 5	Compound C 100Å	NPD 300Å	Host-2	Compound 3 7%	Host-2 100Å	Alq 400Å
Example 6	Compound C 100Å	NPD 300Å	Host-2	Compound 3 10%	Host-2 100Å	Alq 400Å
Example 7	Compound C 100Å	NPD 300Å	Host-2	Compound 4 7%	Host-2 100Å	Alq 400Å
Example 8	Compound C 100Å	NPD 300Å	Host-2	Compound 4 10%	Host-2 100Å	Alq 400Å
Example 9	Compound C 100Å	NPD 300Å	Host-2	Compound 5 7%	Host-2 100Å	Alq 400Å
Example 10	Compound C 100Å	NPD 300Å	Host-2	Compound 5 10%	Host-2 100Å	Alq 400Å
Comparative Example 1	Compound C 100Å	NPD 300Å	Host-2	Compound B 7%	Host-2 100Å	Alq 400Å

Comparative Example 2	Compound C 100Å	NPD 300Å	Host-2	Compound B 10%	Host-2 100Å	Alq 400Å
Comparative Example 3	Compound C 100Å	NPD 300Å	Host-1	Compound C 10%	Host-1 50Å	Alq 450Å
Comparative Example 4	Compound C 100Å	NPD 300Å	Host-2	Compound C 7%	Host-2 100Å	Alq 400Å

Table 3.

Device Example	λ max, (nm)	FWHM (nm)	CIE		At L = 1000 cd/m ²				At J = 40mA/cm ²	
			X	Y	V (V)	LE (cd/A)	EQE (%)	PE lm/W	Lo, (cd/m ²)	RT 80% (hr)
Example 1	521	74	0.331	0.615	7	45	12.5	20.2	10,883	87
Example 2	523	75	0.338	0.614	6.3	51.5	14.3	25.9	14,139	99
Example 3	522	80	0.347	0.607	6	57	16.1	29.6	16,045	127
Example 4	526	86	0.363	0.598	6.6	52.6	15	24.9	16,197	149
Example 5	519	73	0.325	0.618	6.3	51	14.2	25.5	13,159	200
Example 6	520	72	0.324	0.622	5.6	55.1	15.3	31.1	15,610	280
Example 7	527	78	0.360	0.603	6	59.9	16.7	31.2	15,345	150
Example 8	528	88	0.366	0.600	5.4	67.7	19	39.2	19,894	150
Example 9	519	71	0.320	0.622	6.1	50.4	14	26.1	13,610	200
Example 10	519	72	0.325	0.620	5.7	50.5	14	27.6	14,262	270
Comparative Example 1	519	74	0.321	0.621	6	45.1	12.6	23.6	13,835	196
Comparative Example 2	521	76	0.325	0.618	6	44	12.3	22.9	13,469	200
Comparative Example 3	529	79	0.361	0.604	5.9	46.7	12.9	24.7	14,575	97
Comparative Example 4	527	74	0.348	0.613	6	56.4	15.4	29.7	16,108	290

[0093] From Device Examples 1-10, it can be seen that the invention compounds as emissive dopants in green phosphorescent OLEDs give high device efficiency, long operational lifetime and more saturated color. Compound 1 and 2 showed better efficiency, more saturated color, and longer lifetime than Compound C as can be seen from Device Examples 1-4 and Comparative Example 3. Compound 3 has longer lifetime and higher efficiency than Compound B as can be seen from Device Examples 5 and 6 and Comparative Examples 1 and 2. Notably, devices containing Compound 3 as an emissive dopant also showed more saturated color and a narrower emission spectrum than Compound C as shown in Comparative Example 4.

[0094] These data show that phenylpyridine and phenylbenzimidazole containing heteroleptic compounds are excellent emissive dopants for phosphorescent OLEDs providing better color, longer lifetime, and higher efficiency.

[0095] Particular emissive dopants for use in the emissive layer of an OLED are provided. These dopants may provide devices having particularly good properties. The materials for

the emissive layer, and the materials and thicknesses for the BL and ETL of Device Examples 1-16 are shown in Table 4. The devices were tested, and the results measured are provided in Table 5. Devices having an emissive layer using Compounds 1-6, 8 and 9 as the emissive dopant show improved device efficiency and lifetime as well as more saturated color indicating that these heteroleptic compounds may be beneficial.

Table 4.

Device Example	HIL	HTL	Host	A %	BL	ETL
Example 1	Compound C 100Å	NPD 300Å	Host-1	Compound 1 7%	Host-1 50Å	Alq 450Å
Example 2	Compound C 100Å	NPD 300Å	Host-1	Compound 1 10%	Host-1 50Å	Alq 450Å
Example 3	Compound C 100Å	NPD 300Å	Host-1	Compound 2 7%	Host-1 50Å	Alq 450Å
Example 4	Compound C 100Å	NPD 300Å	Host-1	Compound 2 10%	Host-1 50Å	Alq 450Å
Example 5	Compound C 100Å	NPD 300Å	Host-2	Compound 3 7%	Host-2 100Å	Alq 400Å
Example 6	Compound C 100Å	NPD 300Å	Host-2	Compound 3 10%	Host-2 100Å	Alq 400Å
Example 7	Compound C 100Å	NPD 300Å	Host-2	Compound 4 7%	Host-2 100Å	Alq 400Å
Example 8	Compound C 100Å	NPD 300Å	Host-2	Compound 4 10%	Host-2 100Å	Alq 400Å
Example 9	Compound C 100Å	NPD 300Å	Host-2	Compound 5 7%	Host-2 100Å	Alq 400Å
Example 10	Compound C 100Å	NPD 300Å	Host-2	Compound 5 10%	Host-2 100Å	Alq 400Å
Example 11	Compound C 100Å	NPD 300Å	Host-2	Compound 6 7%	Host-2 100Å	Alq 400Å
Example 12	Compound C 100Å	NPD 300Å	Host-2	Compound 6 10%	Host-2 100Å	Alq 400Å
Example 13	Compound C 100Å	NPD 300Å	Host-2	Compound 8 7%	Host-2 100Å	Alq 400Å
Example 14	Compound C 100Å	NPD 300Å	Host-2	Compound 8 10%	Host-2 100Å	Alq 400Å
Example 15	Compound C 100Å	NPD 300Å	Host-2	Compound 9 7%	Host-2 100Å	Alq 400Å
Example 16	Compound C 100Å	NPD 300Å	Host-2	Compound 9 10%	Host-2 100Å	Alq 400Å
Comparative Example 1	Compound C 100Å	NPD 300Å	Host-2	Compound B 7%	Host-2 100Å	Alq 400Å
Comparative Example 2	Compound C 100Å	NPD 300Å	Host-2	Compound B 10%	Host-2 100Å	Alq 400Å
Comparative Example 3	Compound C 100Å	NPD 300Å	Host-1	Compound C 10%	Host-1 50Å	Alq 450Å
Comparative Example 4	Compound C 100Å	NPD 300Å	Host-2	Compound C 7%	Host-2 100Å	Alq 400Å

Table 5.

Device Example	λ max, (nm)	FWHM (nm)	CIE		At L = 1000 cd/m ²				At J = 40mA/cm ²	
			X	Y	V (V)	LE (cd/A)	EQE (%)	PE lm/W	Lo, (cd/m ²)	RT _{80%} (hr)
Example 1	521	74	0.331	0.615	7	45	12.5	20.2	10,883	87
Example 2	523	75	0.338	0.614	6.3	51.5	14.3	25.9	14,139	99
Example 3	522	80	0.347	0.607	6	57	16.1	29.6	16,045	127
Example 4	526	86	0.363	0.598	6.6	52.6	15	24.9	16,197	149
Example 5	519	73	0.325	0.618	6.3	51	14.2	25.5	13,159	200
Example 6	520	72	0.324	0.622	5.6	55.1	15.3	31.1	15,610	280
Example 7	527	78	0.360	0.603	6	59.9	16.7	31.2	15,345	150
Example 8	528	88	0.366	0.600	5.4	67.7	19	39.2	19,894	150
Example 9	519	71	0.320	0.622	6.1	50.4	14	26.1	13,610	200
Example 10	519	72	0.325	0.620	5.7	50.5	14	27.6	14,262	270
Example 11	547	70	0.426	0.561	5.7	70.3	19.7	38.5	18,699	280
Example 12	549	69	0.432	0.557	5.4	74.7	21	43.6	21,276	420
Example 13	527	68	0.342	0.620	6	54.5	14.7	28.4	16,098	360
Example 14	527	68	0.339	0.623	5.5	53.2	14.3	30.2	16,462	425
Example 15	520	70	0.325	0.620	6.1	55.3	15.3	28.5	14,113	240
Example 16	520	70	0.325	0.622	5.7	57.3	15.8	31.6	16,065	280
Comparative Example 1	519	74	0.321	0.621	6	45.1	12.6	23.6	13,835	196
Comparative Example 2	521	76	0.325	0.618	6	44	12.3	22.9	13,469	200
Comparative Example 3	529	79	0.361	0.604	5.9	46.7	12.9	24.7	14,575	97
Comparative Example 4	527	74	0.348	0.613	6	56.4	15.4	29.7	16,108	290

[0096] From Device Examples 1-16, it can be seen that green OLEDs which comprise an invention compound as an emitting dopant provide excellent properties. Compounds 6, 8, and 9 showed more saturated color, better efficiency, and longer lifetime than Compounds B and C, as can be seen from Device Examples 11-14 and Comparative Examples 1-4. Devices containing Compound 6 showed improved lifetime as compared to devices using Compound B or Compound C. Devices using Compound 8 or Compound 9 showed more saturated color, improved efficiency and a longer lifetime than devices using Compound B or Compound C.

[0097] This data shows that heteroleptic compound containing phenylpyridine and phenylbenzimidazole are great emitting dopants for phosphorescent OLEDs. These compounds provide devices having improved efficiency, improved color, and longer lifetime.

[0098] FIG. 3 shows the solution photoluminescence (PL) spectra of Compound 3, Compound A, and Compound B. The homoleptic complex Compound A showed vibronic

structures. The heteroleptic complex Compound 3 has a similar shape as Compound B. However, the emission of Compound 3 is narrower than Compound B, which indicates that both ligands may contribute to the emission. In addition, Compound 3 can be evaporated at less than 220 °C under high vacuum, which is about 20 degrees lower than Compound B and about 60 degrees lower than Compound A.

[0099] FIG. 4 shows a general phosphorescent organic light emitting device.

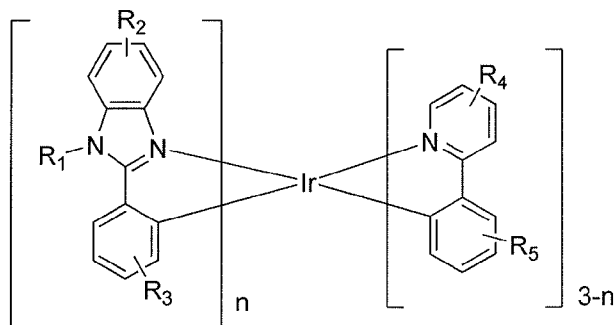
[0100] FIG. 5 shows a phosphorescent organic light emitting device having an emissive layer containing the inventive compound as an emissive dopant. The device of FIG. 5 includes a 100 Å thick hole injection layer of Compound C, a 300 Å thick hole transport layer of NPD, a 300 Å thick emissive layer of a host material doped with X % of the inventive compound, a 50 Å or 100 Å thick blocking layer of Host-1 or Host-2, and a 400 Å or 450 Å thick electron transport layer of Alq₃, and a LiF / Al cathode. X is either 7% or 10%.

[0101] FIG. 6 shows a heteroleptic compound containing phenylpyridine and phenylbenzimidazole.

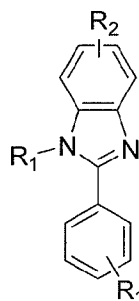
[0102] It is understood that the various embodiments described herein are by way of example only, and are not intended to limit the scope of the invention. For example, many of the materials and structures described herein may be substituted with other materials and structures without deviating from the spirit of the invention. The present invention as claimed may therefore includes variations from the particular examples and preferred embodiments described herein, as will be apparent to one of skill in the art. It is understood that various theories as to why the invention works are not intended to be limiting.

WHAT IS CLAIMED IS:

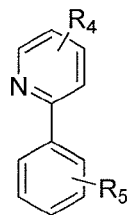
1. A heteroleptic iridium compound $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$ having the formula:



wherein $n = 1$ or 2 ;



wherein R_3 is L1 ;



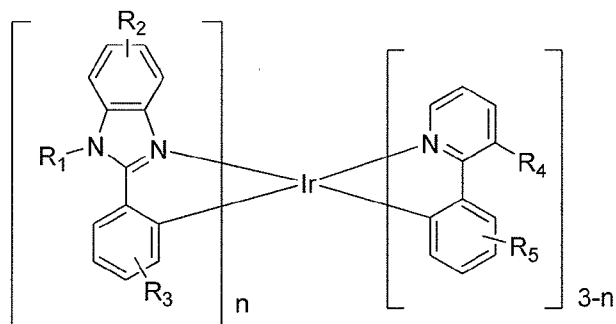
wherein R_5 is L2 ;

wherein R_1 , R_2 , R_3 , R_4 , and R_5 may represent mono, di, tri, or tetra

substitutions; and

wherein R_1 , R_2 , R_3 , R_4 , and R_5 are each independently selected from the group consisting of hydrogen, alkyl, heteroalkyl, aryl, substituted aryl, heteroaryl, and substituted heteroaryl.

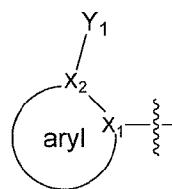
2. The compound of claim 1, wherein $n = 1$.
3. The compound of claim 1, wherein the compound has the formula:



wherein R_4 is hydrogen or methyl.

4. The compound of claim 1, wherein R_1 is selected from the group consisting of alkyl, heteroalkyl, aryl, heteroaryl, substituted aryl, and substituted heteroaryl; and

wherein R_1 does not form a conjugated system with L1.



5. The compound of claim 4, wherein R_1 is ;

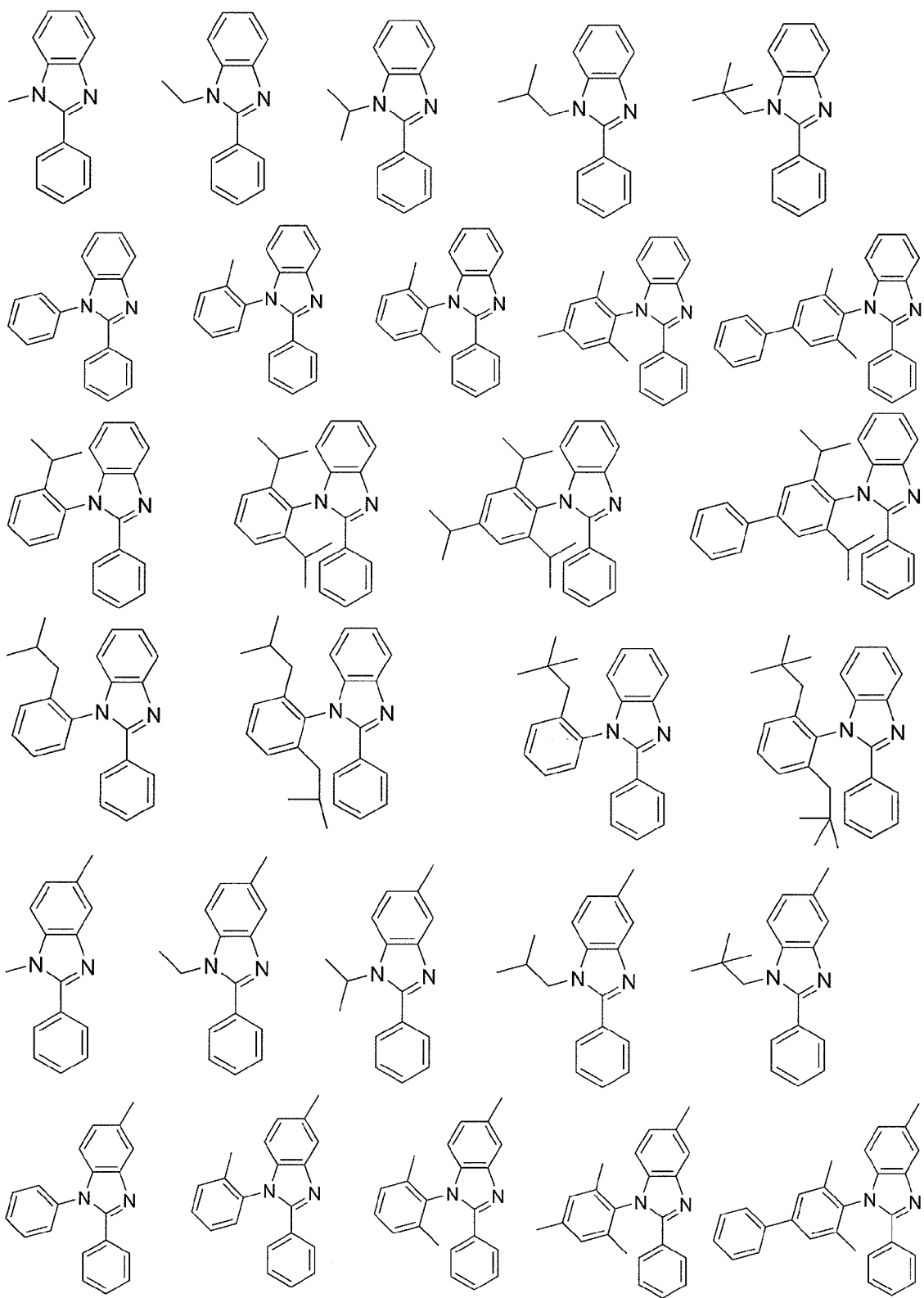
wherein X_1 and X_2 are independently selected from C and N;

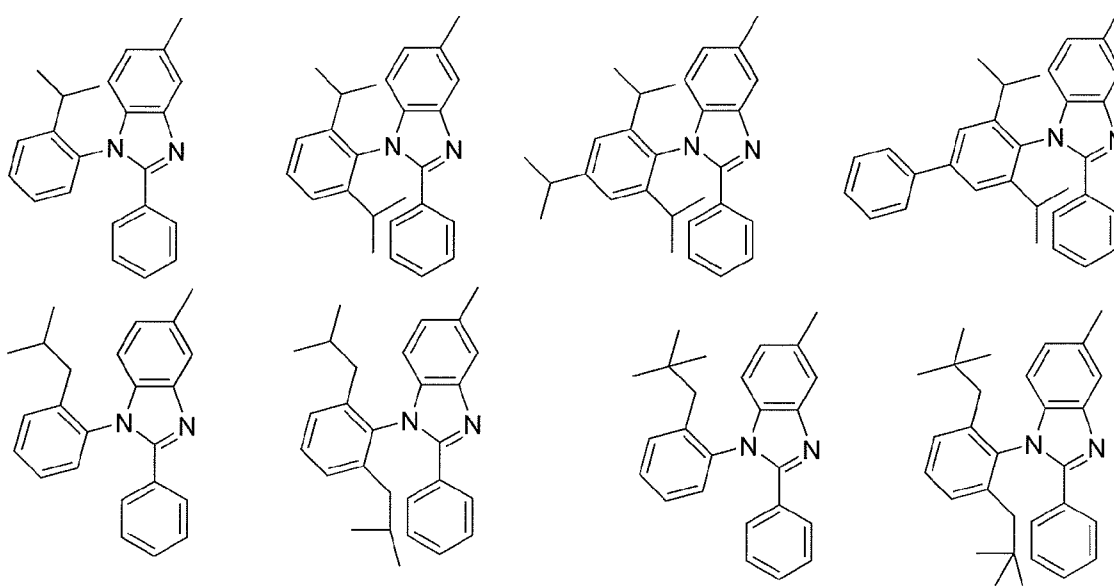
wherein Y_1 is not hydrogen; and

wherein Y_1 may be joined to other substituents on the aryl ring.

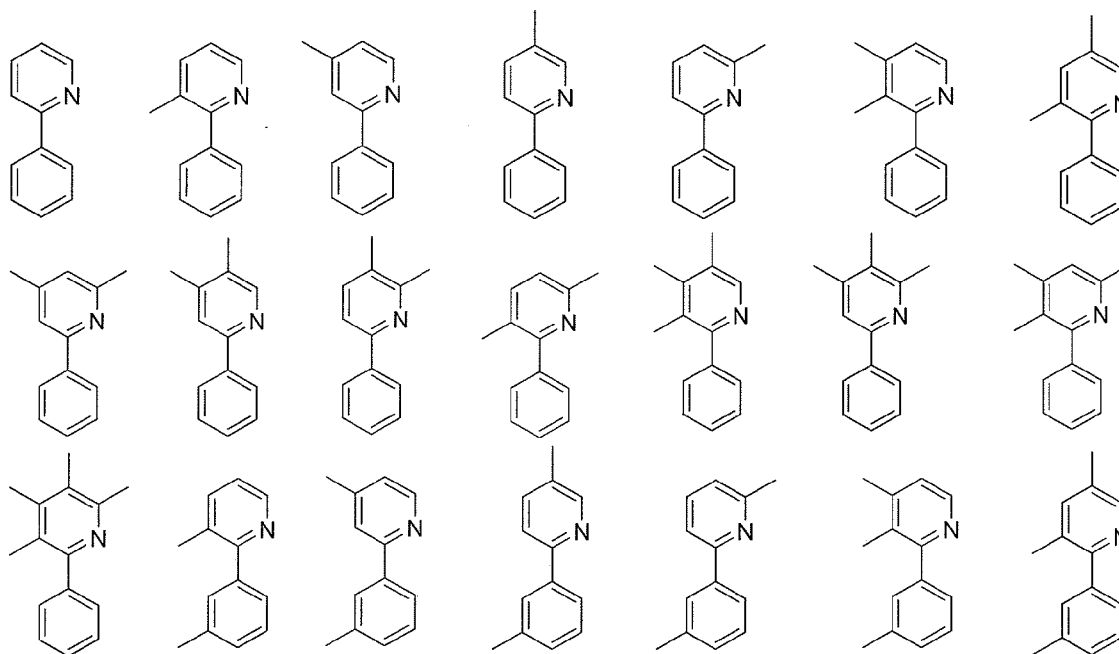
6. The compound of claim 1, wherein each of R_2 , R_3 , and R_5 are hydrogen.

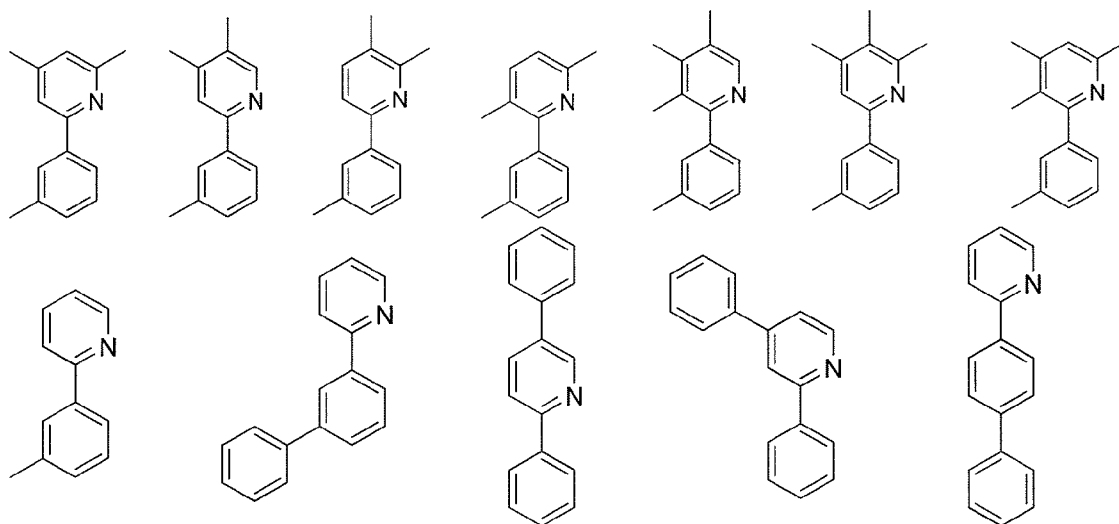
7. The compound of claim 1, wherein L1 is selected from the group consisting of:



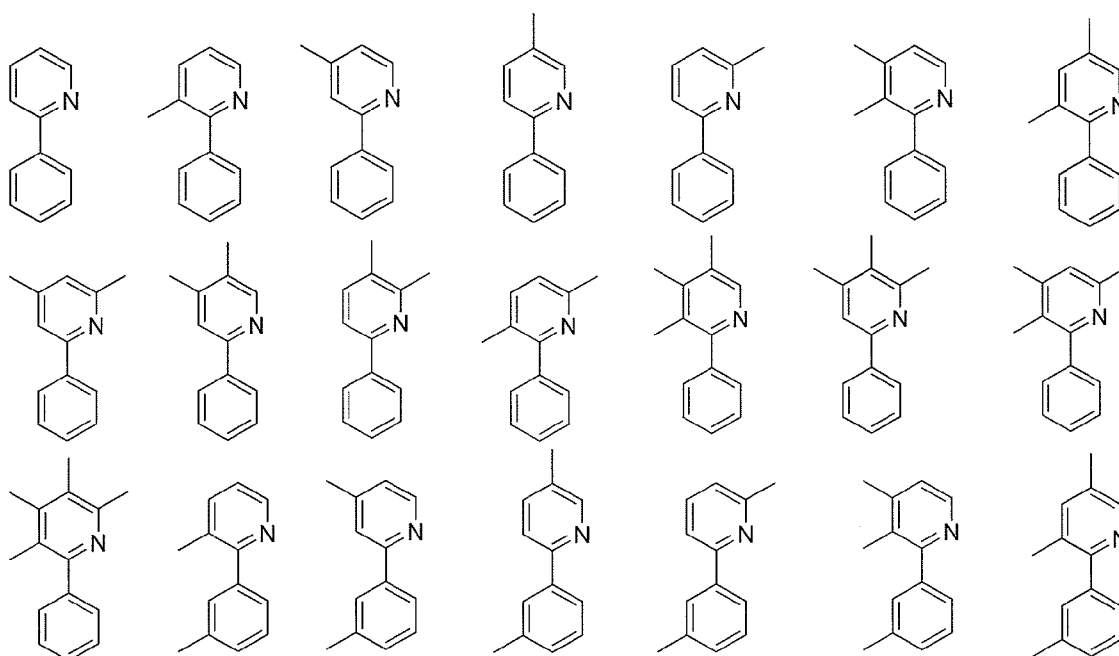


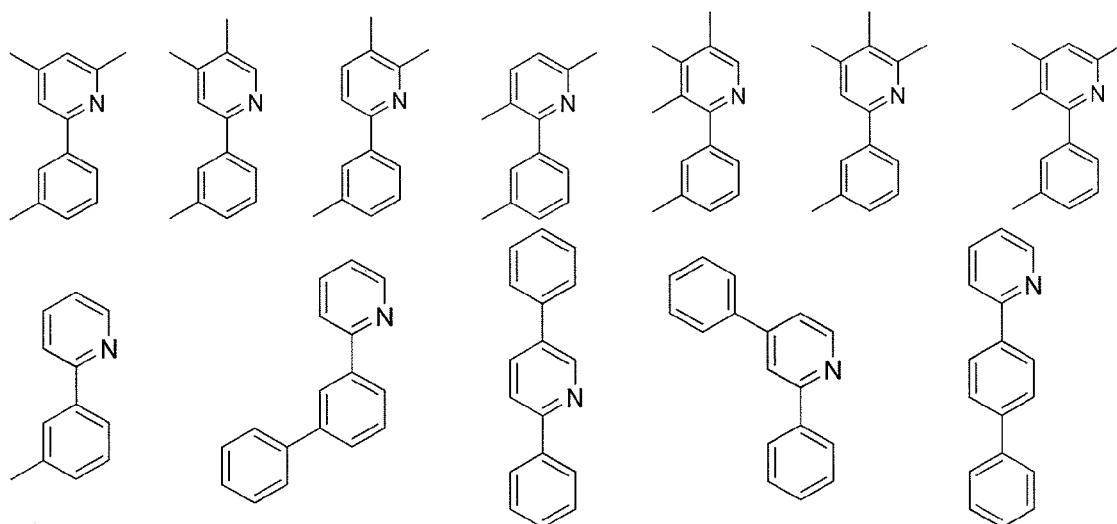
8. The compound of claim 1, wherein L2 is selected from the group consisting of:



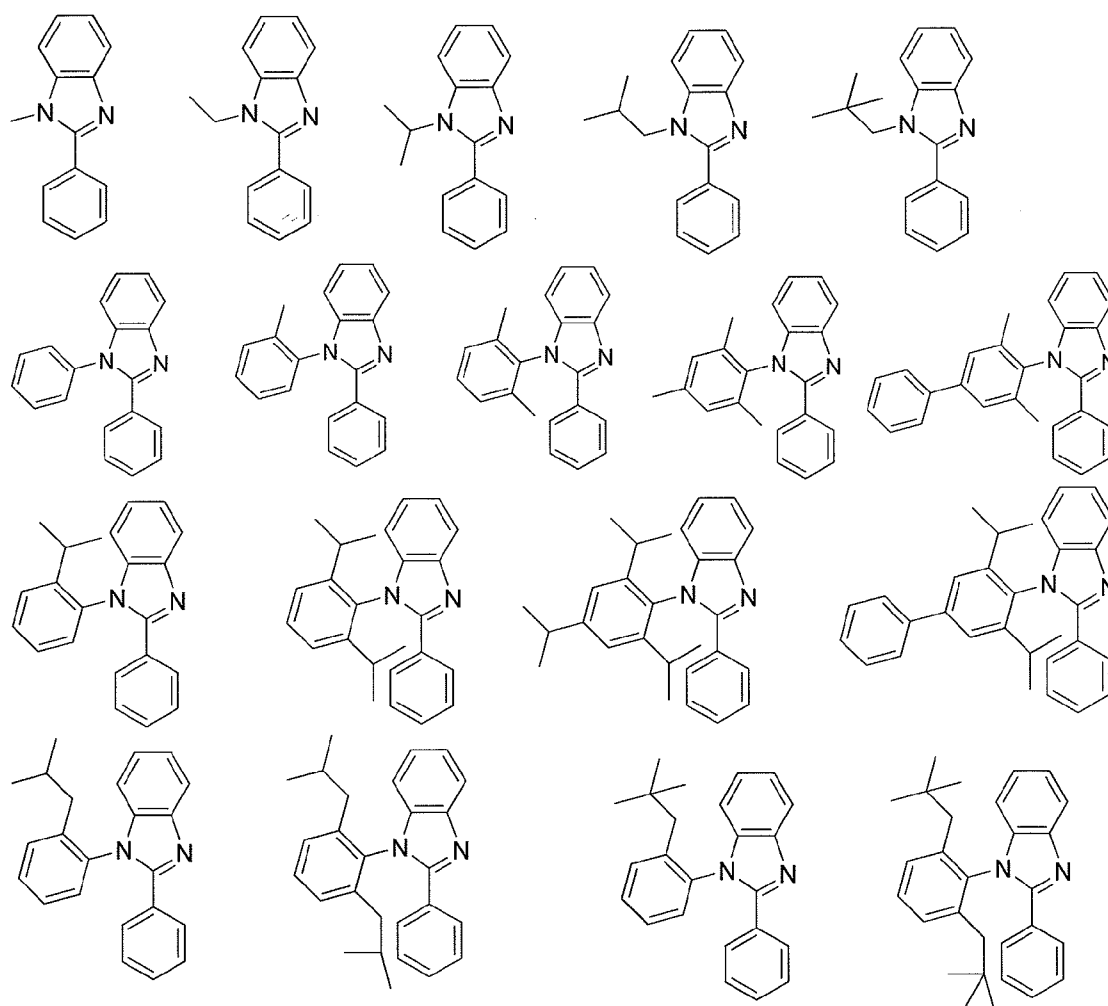


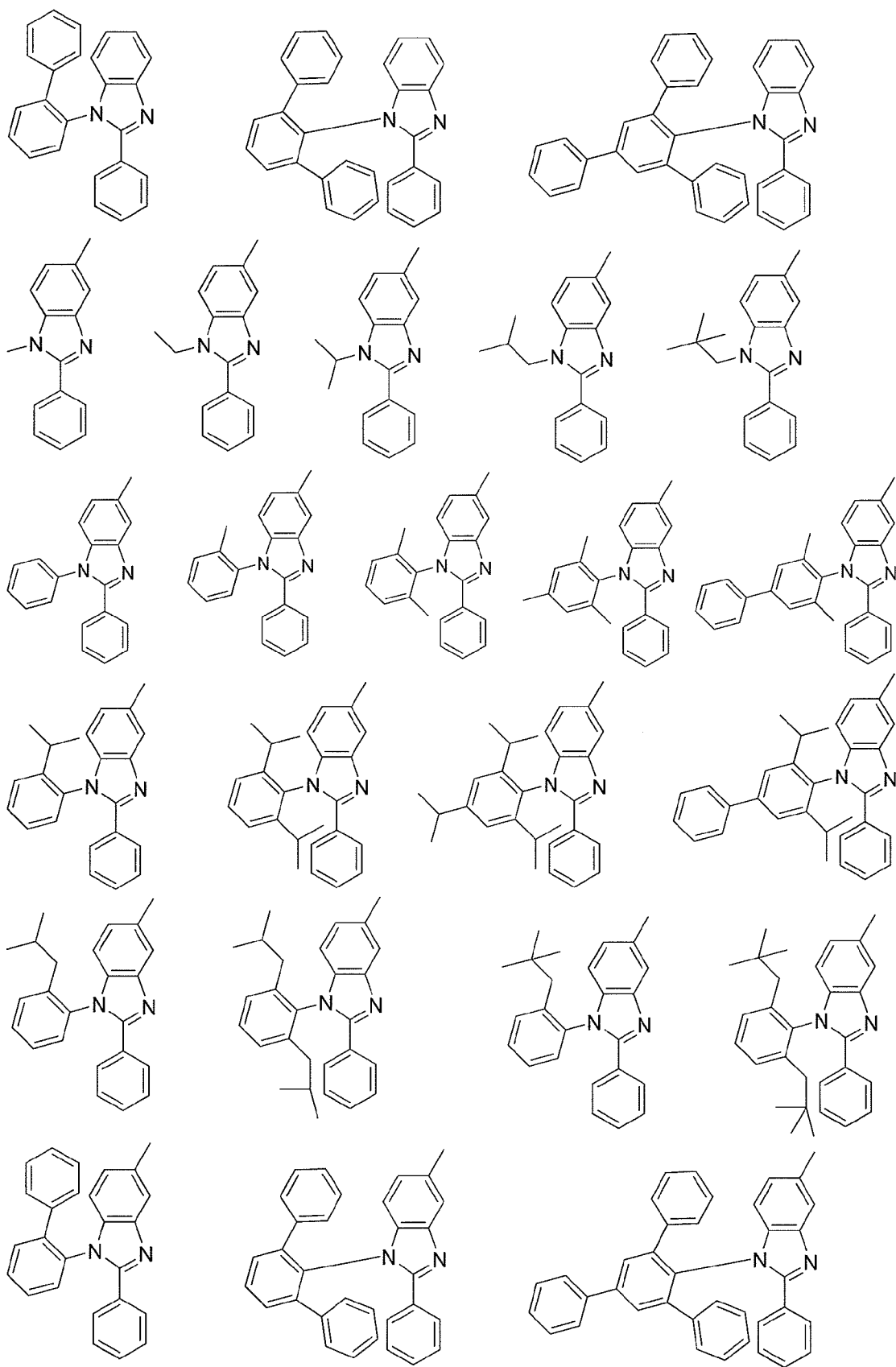
9. The compound of claim 7, wherein L2 is selected from the group consisting of:



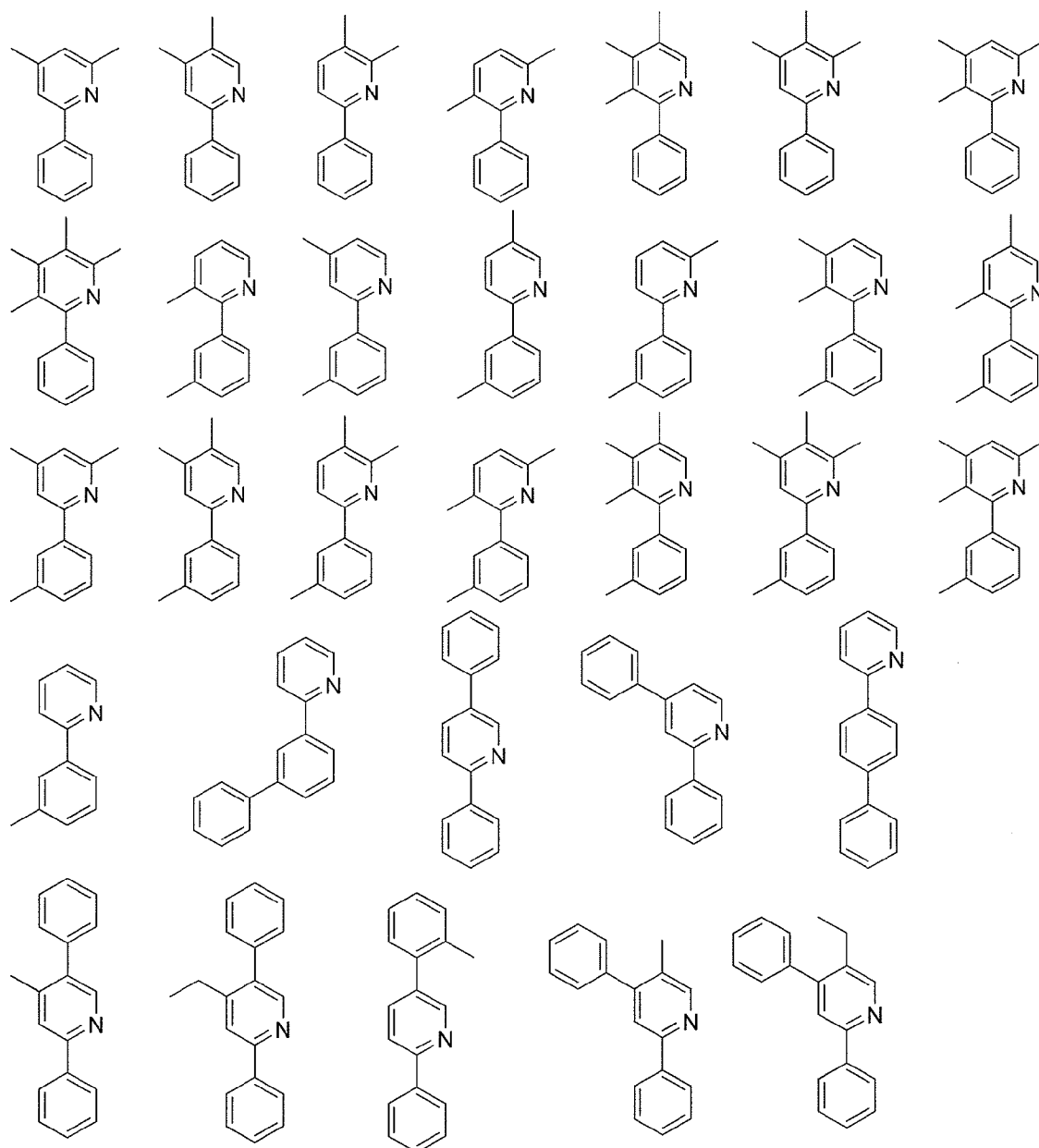


10. The compound of claim 1, wherein L1 is selected from the group consisting of:

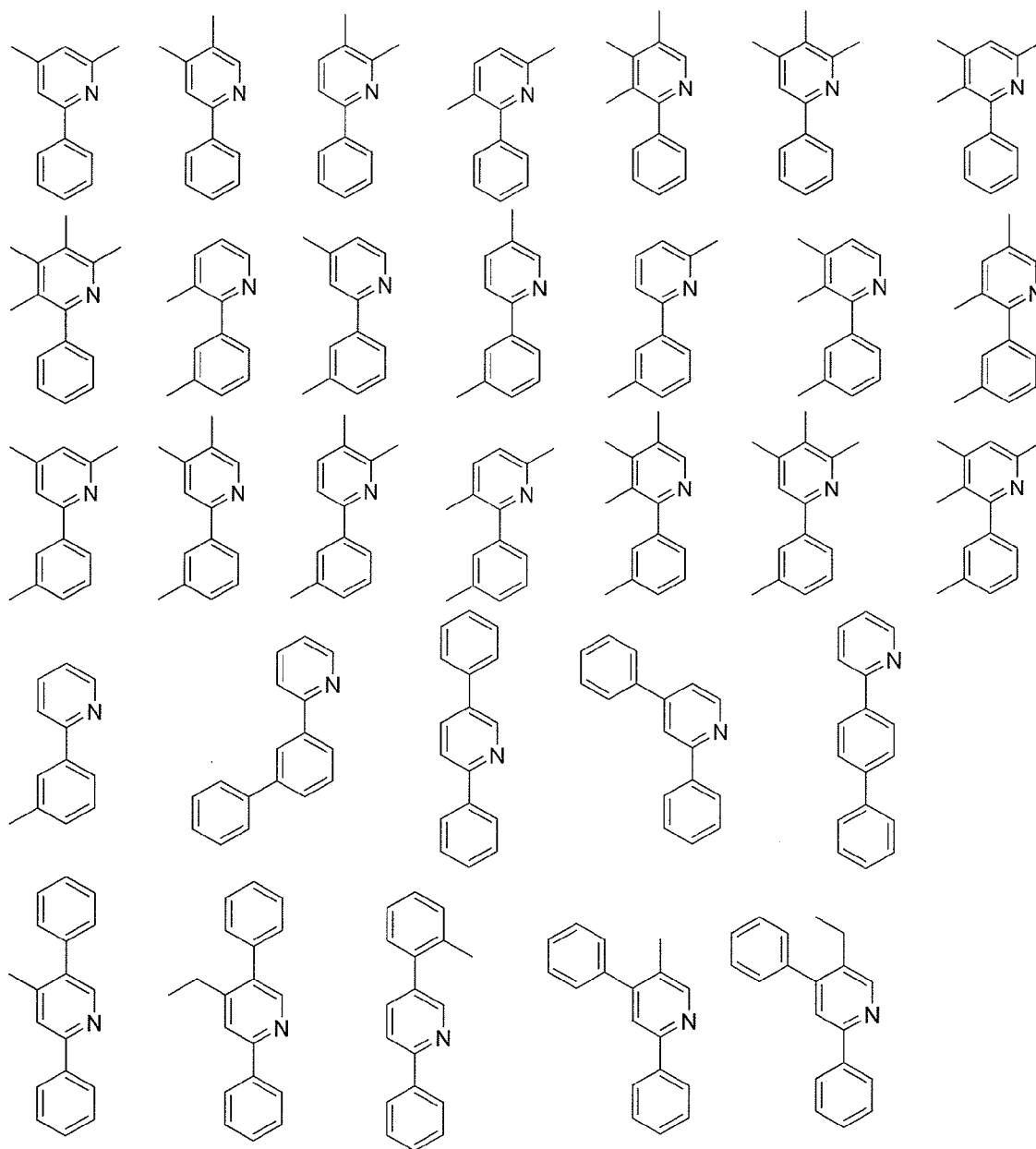




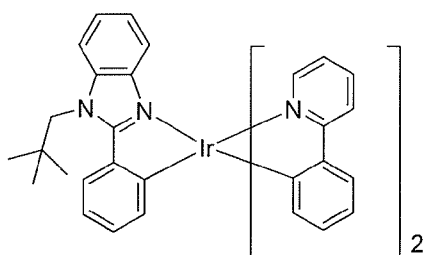
11. The compound of claim 1, wherein L2 is selected from the group consisting of:



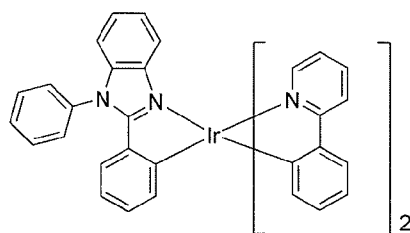
12. The compound of claim 10, wherein L2 is selected from the group consisting of:



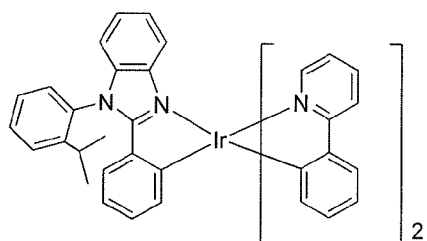
13. The compound of claim 1, wherein the compound is selected from the group consisting of:



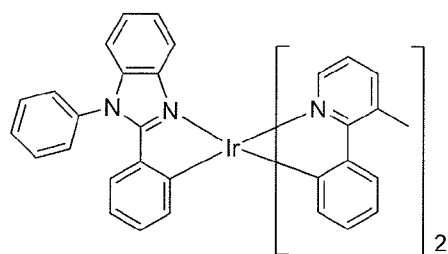
Compound 1



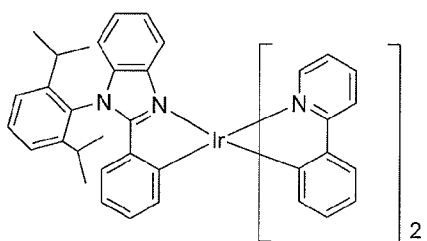
Compound 2



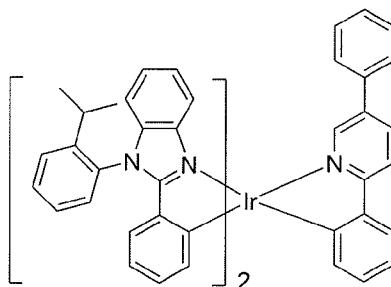
Compound 3



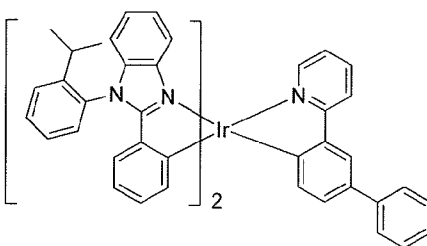
Compound 4



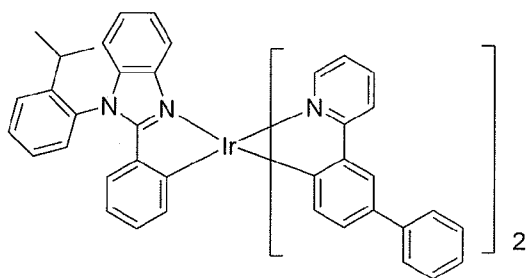
Compound 5



Compound 6

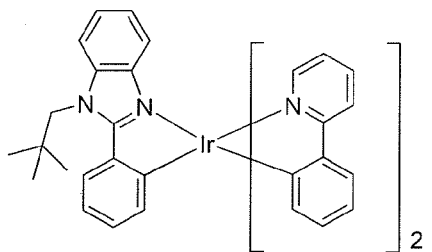


Compound 7

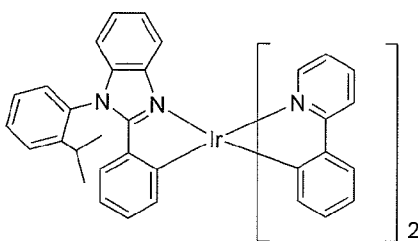


Compound 8

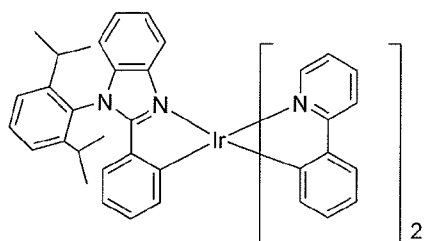
14. The compound of claim 1, wherein the compound is selected from the group consisting of:



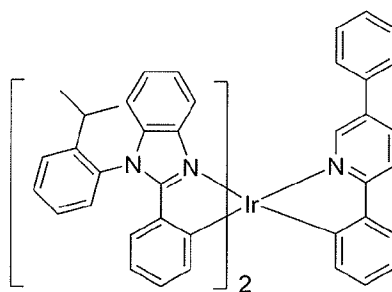
Compound 1



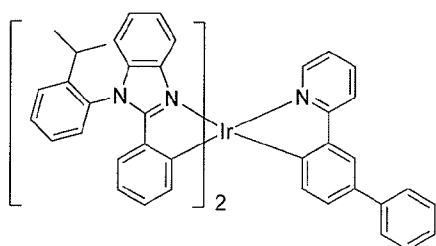
Compound 3



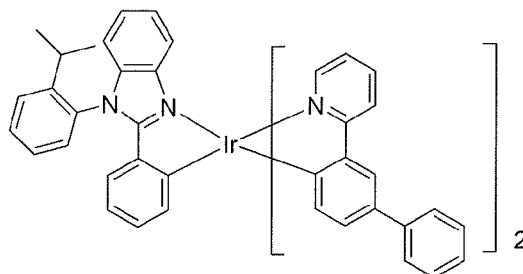
Compound 5



Compound 6

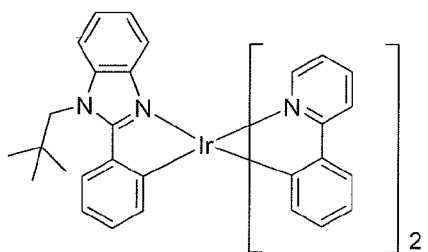


Compound 7

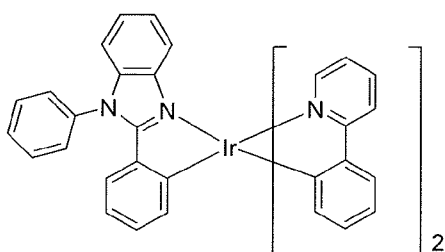


Compound 8

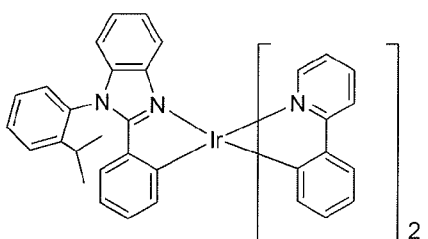
15. The compound of claim 1, wherein the compound is selected from the group consisting of:



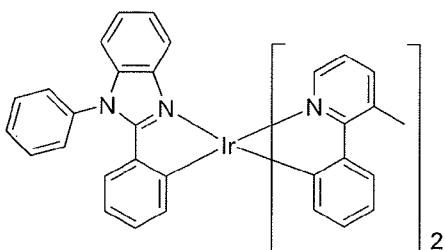
Compound 1



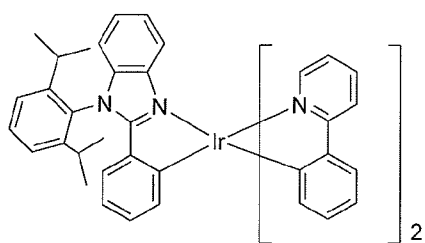
Compound 2



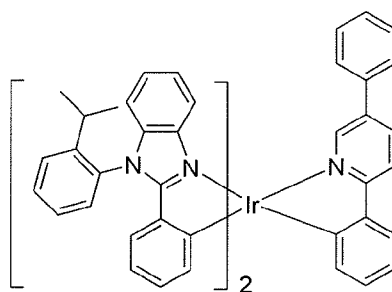
Compound 3



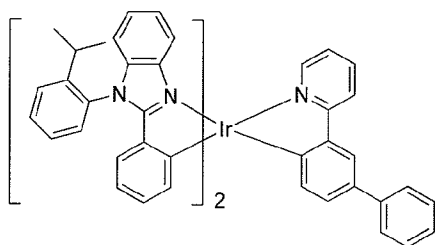
Compound 4



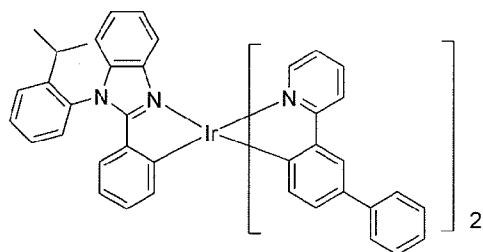
Compound 5



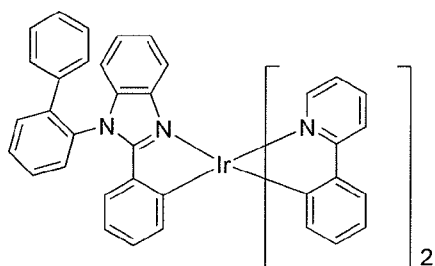
Compound 6



Compound 7

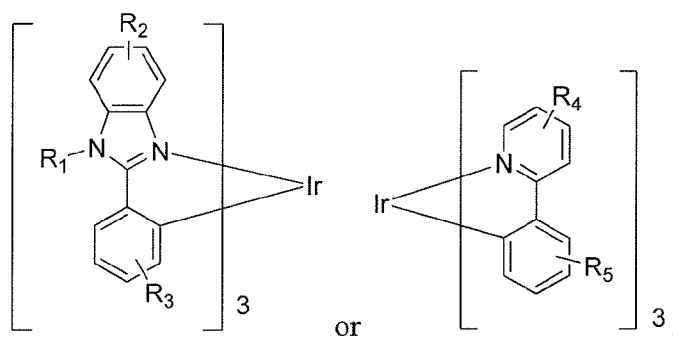


Compound 8

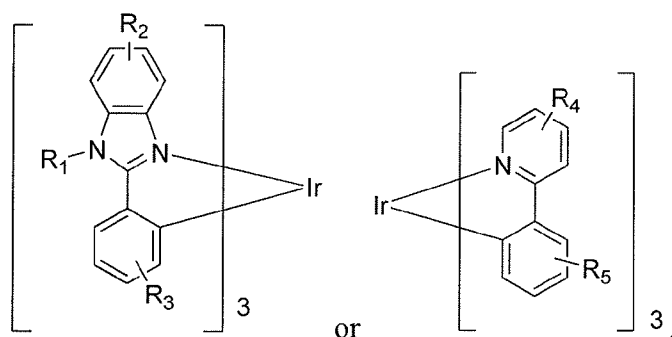


Compound 9

16. The compound of claim 1, wherein the compound has a narrower full width half maximum than either

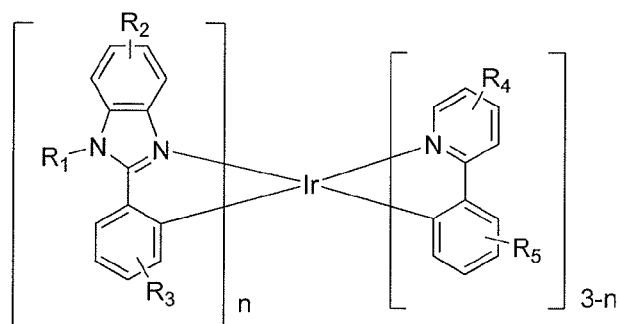


17. The compound of claim 1, wherein the compound has a lower sublimation temperature than either

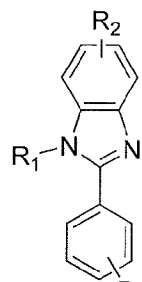


18. The compound of claim 1, wherein the compound is a green emissive dopant.

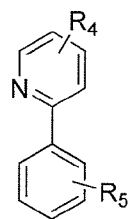
19. An organic light emitting device comprising:
 an anode;
 a cathode; and
 an organic layer, disposed between the anode and the cathode, the organic layer further comprising a heteroleptic iridium compound $\text{Ir}(\text{L1})_n(\text{L2})_{3-n}$ compound having the formula:



wherein $n = 1$ or 2 ;



wherein R_3 is L1 ;

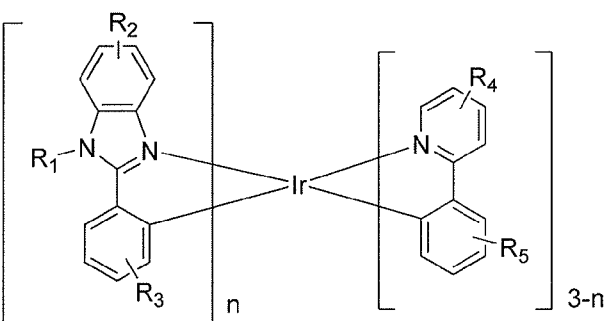


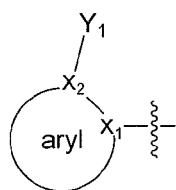
wherein R_5 is L2 ;

wherein R_1 , R_2 , R_3 , R_4 , and R_5 may represent mono, di, tri, or tetra substitutions; and

wherein R_1 , R_2 , R_3 , R_4 , and R_5 are each independently selected from the group consisting of hydrogen, alkyl, heteroalkyl, aryl, substituted aryl, heteroaryl, and substituted heteroaryl.

20. The device of claim 19, wherein the organic layer is an emissive layer

and the compound having the formula  is an emissive compound.

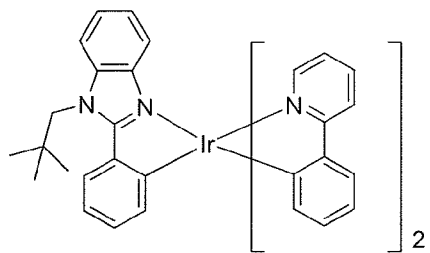
21. The device of claim 19, wherein R_1 is  ;

wherein X_1 and X_2 are independently selected from C and N;

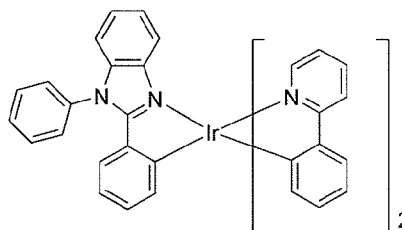
wherein Y_1 is not hydrogen; and

wherein Y_1 may be joined to other substituents on the aryl ring.

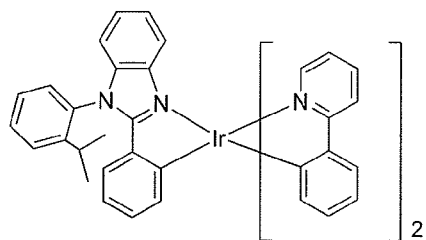
22. The device of claim 19, wherein the compound is selected from the group consisting of:



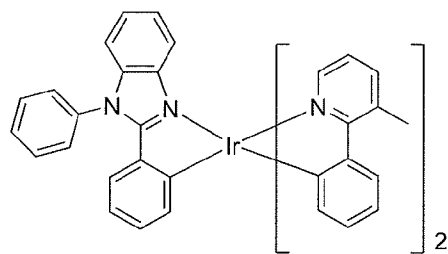
Compound 1



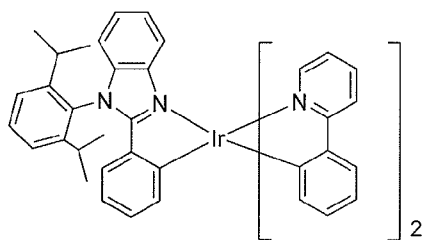
Compound 2



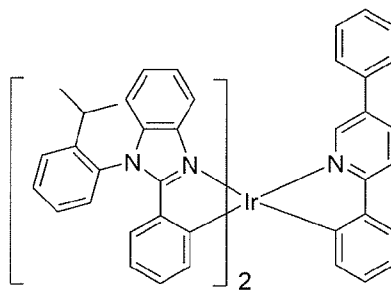
Compound 3



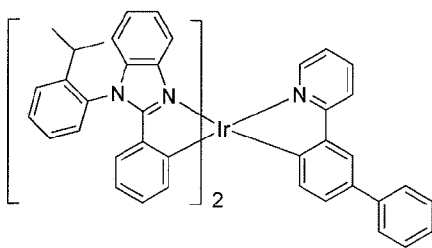
Compound 4



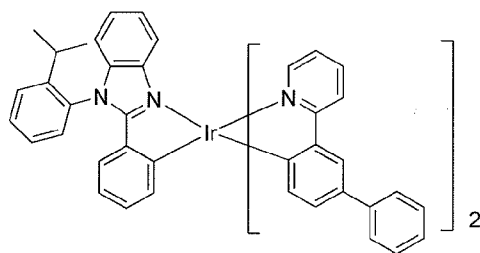
Compound 5



Compound 6

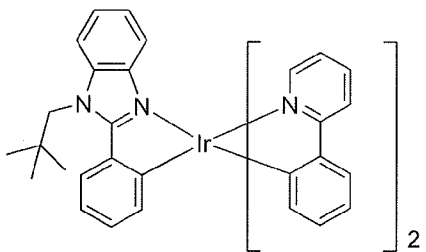


Compound 7

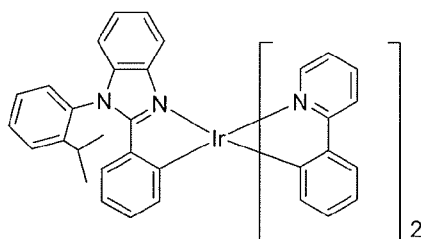


Compound 8

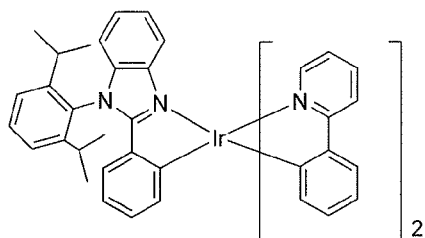
23. The device of claim 19, wherein the compound is selected from the group consisting of:



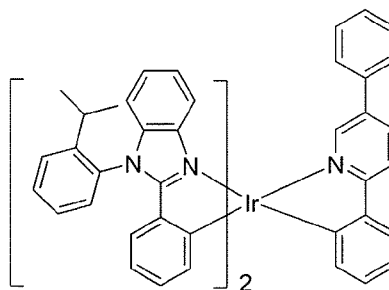
Compound 1



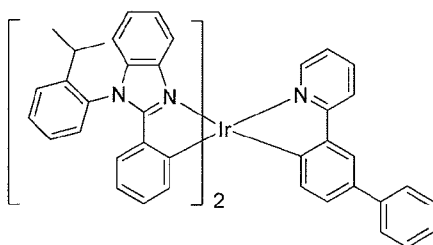
Compound 3



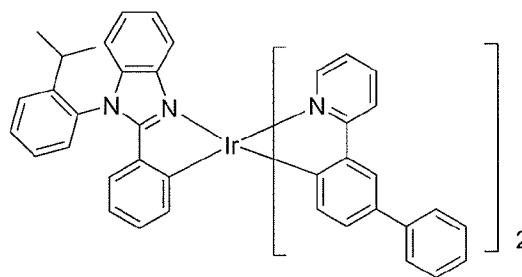
Compound 5



Compound 6

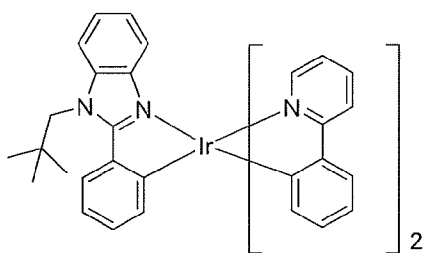


Compound 7

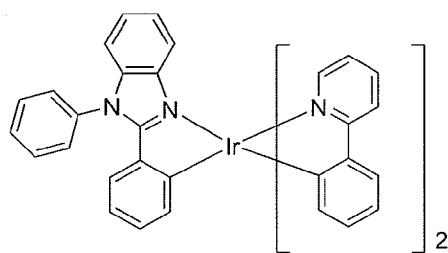


Compound 8

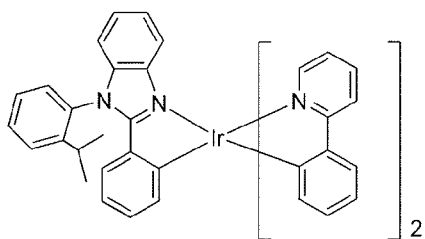
24. The device of claim 19, wherein the compound is selected from the group consisting of:



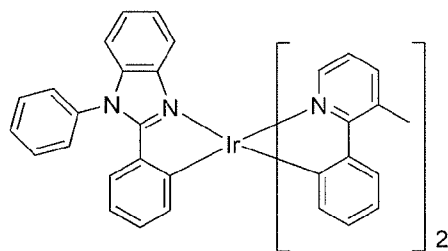
Compound 1



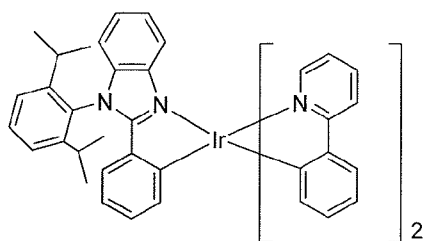
Compound 2



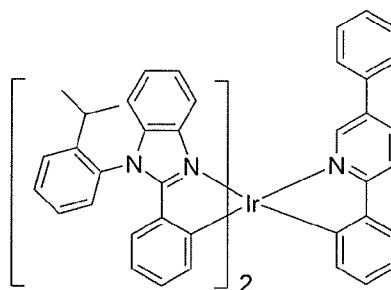
Compound 3



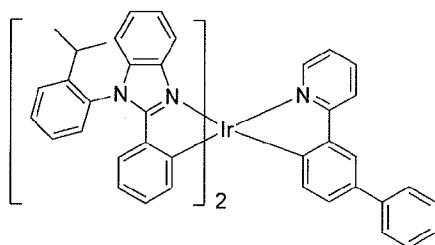
Compound 4



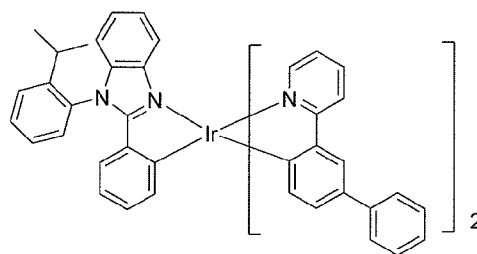
Compound 5



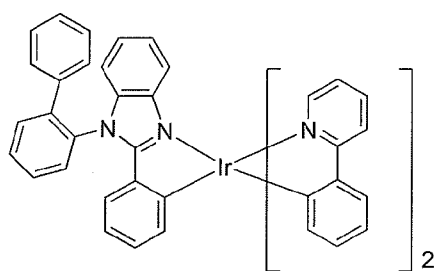
Compound 6



Compound 7



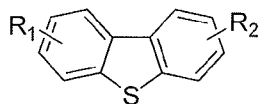
Compound 8



Compound 9

25. The device of claim 19, wherein the emissive layer further comprises a host.

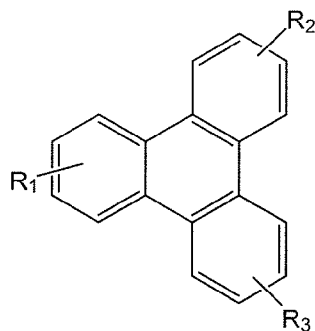
26. The device of claim 25, wherein the host has the formula:



wherein R_1 and R_2 represent, independently, mono, di, tri or tetra substitutions selected from alkyl, alkoxy, amino, alkenyl, alkynyl, arylkyl, aryl and heteroaryl, or no substitution.; and

wherein at least one of R_1 and R_2 includes a triphenylene group.

27. The device of claim 25, wherein the host has the formula:



wherein each of R_1 , R_2 , and R_3 is independently a hydrogen, a non-fused aryl group, or a non-fused heteroaryl group having one or more meta-substituents, wherein at least one of R_1 , R_2 , and R_3 is not hydrogen; and

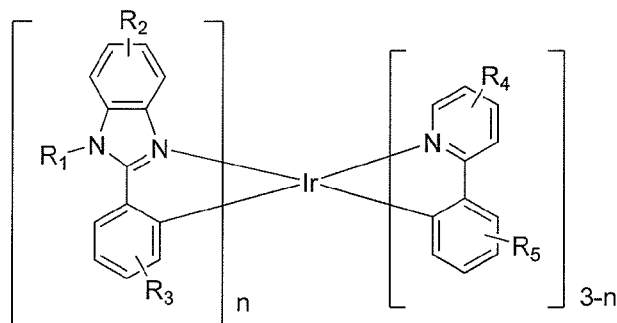
wherein each meta-substituent is a non-fused aryl or heteroaryl group optionally substituted with further substituents selected from the group consisting of non-fused aryl groups, non-fused heteroaryl groups, and alkyl groups.

28. A consumer product comprising a device, the device further comprising:

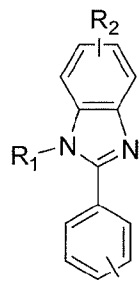
an anode;

a cathode; and

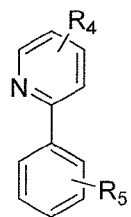
an organic layer, disposed between the anode and the cathode, the organic layer further comprising a heteroleptic iridium compound $\text{Ir}(\text{L}1)_n(\text{L}2)_{3-n}$ compound having the formula:



wherein $n = 1$ or 2 ;



wherein R_3 is L1;



wherein R_5 is L2;

wherein R_1 , R_2 , R_3 , R_4 , and R_5 may represent mono, di, tri, or tetra substitutions; and

wherein R_1 , R_2 , R_3 , R_4 , and R_5 are each independently selected from the group consisting of hydrogen, alkyl, heteroalkyl, aryl, substituted aryl, heteroaryl, and substituted heteroaryl.

1/6

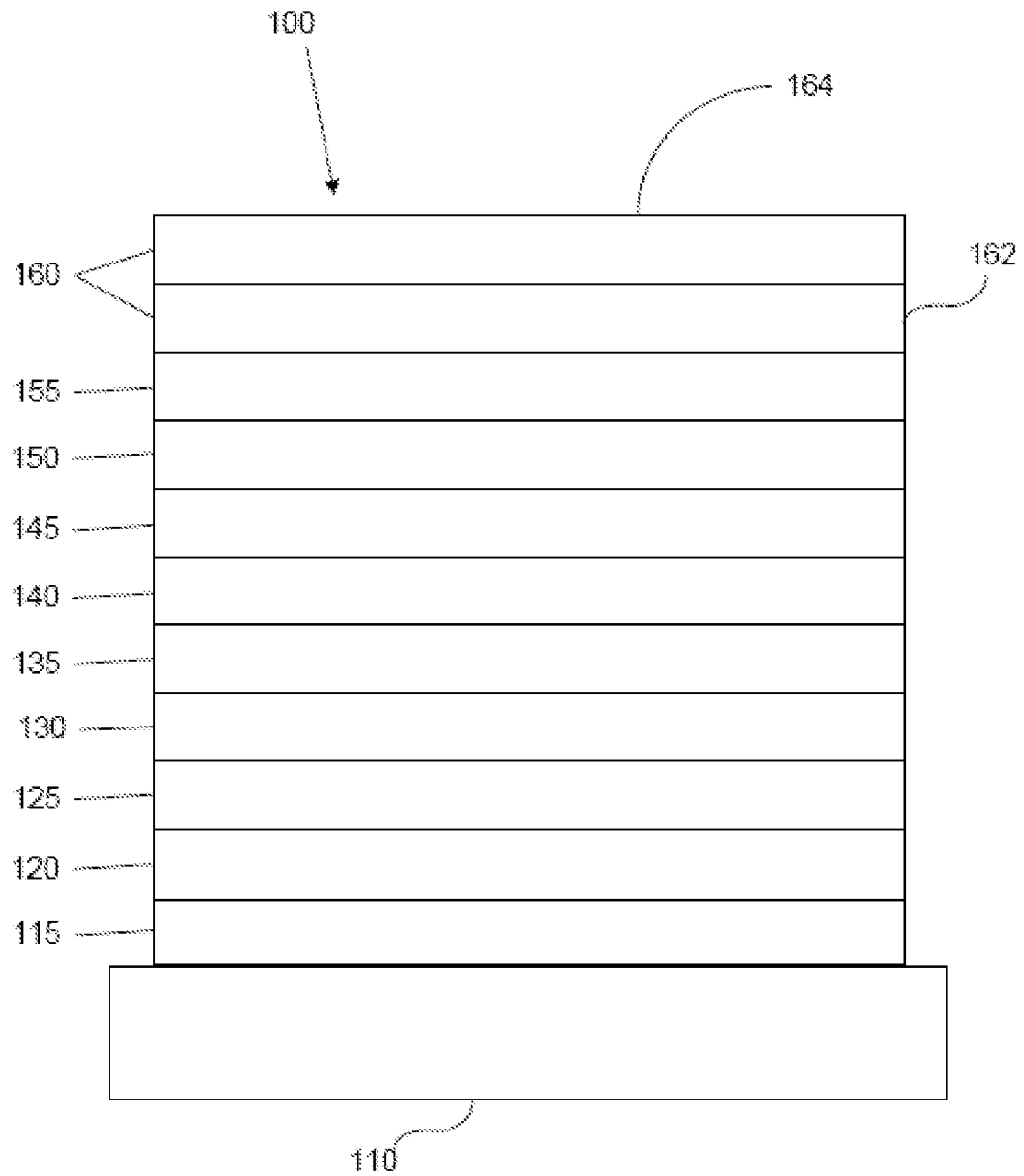


FIGURE 1

2/6

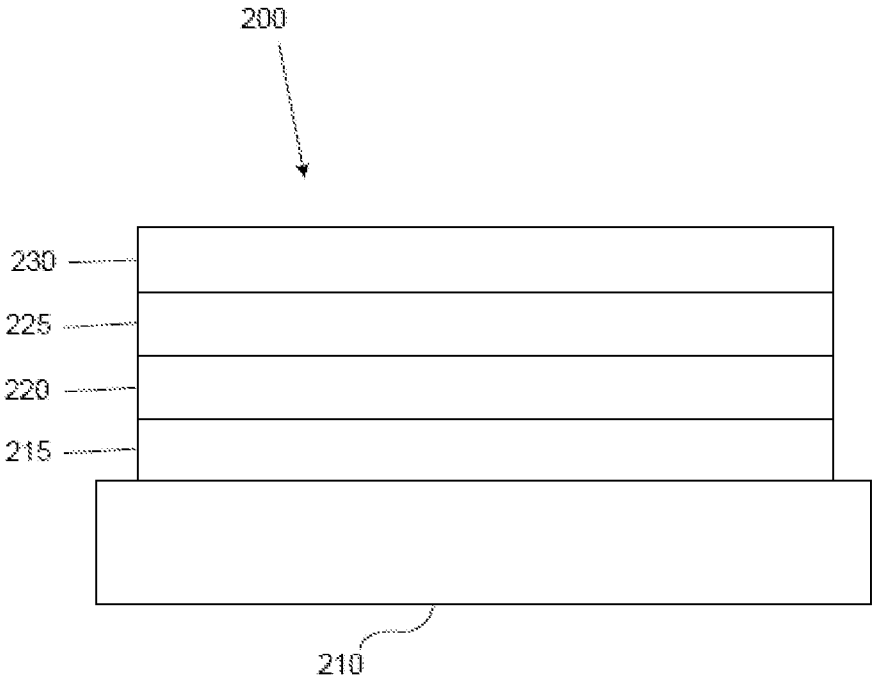


FIGURE 2

3/6

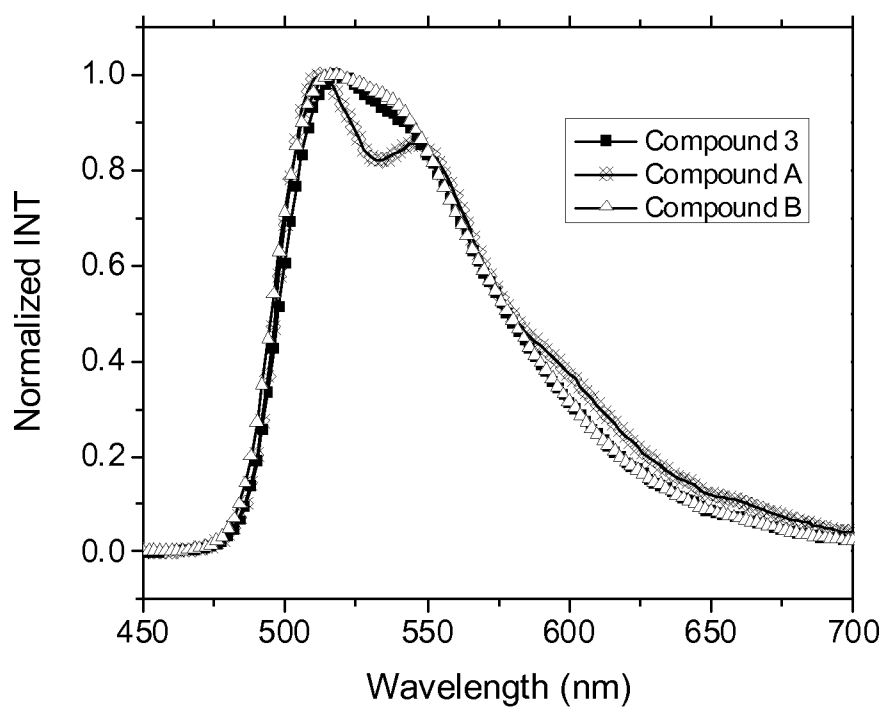


FIGURE 3

4/6

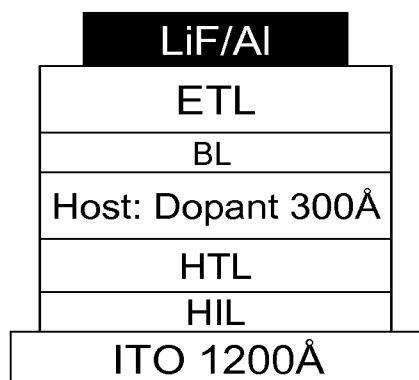
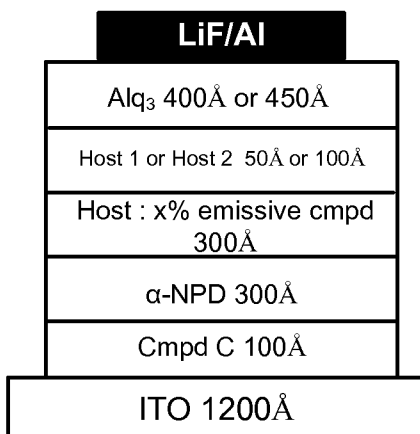


FIGURE 4

5/6

**FIGURE 5**

6/6

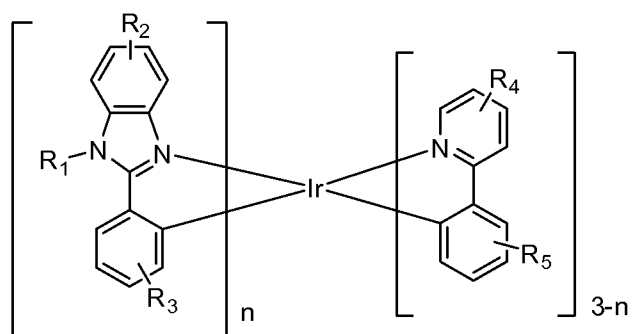


FIGURE 6

INTERNATIONAL SEARCH REPORT

International application No

PCT/US2009/063873

A. CLASSIFICATION OF SUBJECT MATTER
 INV. C09K11/06 C07D247/00

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

C09K C07D

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EP0-Internal

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	JP 2004 131464 A (MITSUBISHI CHEM CORP) 30 April 2004 (2004-04-30) Entries 420, 421, 462, 463, 1124, 1125, 1208, 1209, 1250, 1251, 1292, 1293, 1334, 1335, 1376, 1377, 1418, 1419 on pages 27-51 paragraphs [0001], [0002] figures 1-3	1-28
X,P	----- EP 2 062 959 A2 (GRACEL DISPLAY INC [KR]) 27 May 2009 (2009-05-27) claims 1-4,9	1-28
X,P	----- EP 2 066 150 A1 (GRACEL DISPLAY INC [KR]) 3 June 2009 (2009-06-03) claims 1-4,9	1-28
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☒ Further documents are listed in the continuation of Box C.

☒ See patent family annex.

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"O" document referring to an oral disclosure, use, exhibition or other means

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Date of the actual completion of the international search

1 February 2010

Date of mailing of the international search report

11/02/2010

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 Fax: (+31-70) 340-3016

Authorized officer

Saldamli, Saltuk

INTERNATIONAL SEARCH REPORT

International application No

PCT/US2009/063873

C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
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A	WO 2008/035571 A1 (KONICA MINOLTA HOLDINGS INC [JP]; SUZURI YOSHIYUKI [JP]; NAKATA AKI [J]) 27 March 2008 (2008-03-27) claim 1 compounds BD1-10, BD1-25 -----	1-28

INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No

PCT/US2009/063873

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WO 2008035571 A1	27-03-2008	NONE	